- Low Supply-Voltage Range: 1.8 V to 3.6 V
- Ultralow-Power Consumption:
  - Active Mode: 400 μA at 1 MHz, 2.2 V
  - Standby Mode: 1.3 μA
  - Off Mode (RAM Retention): 0.22 μA
- Five Power-Saving Modes
- Wake-Up From Standby Mode in Less Than 6 μs
- 16-Bit RISC Architecture, Extended Memory, 125-ns Instruction Cycle Time
- Three Channel Internal DMA
- 12-Bit A/D Converter With Internal Reference, Sample-and-Hold, and Autoscan Feature
- Three Configurable Operational Amplifiers
- Dual 12-Bit Digital-to-Analog (D/A)
   Converters With Synchronization
- 16-Bit Timer\_A With Three Capture/Compare Registers
- 16-Bit Timer\_B With Seven
   Capture/Compare-With-Shadow Registers
- On-Chip Comparator
- Supply Voltage Supervisor/Monitor With Programmable Level Detection
- Serial Communication Interface (USART1), Select Asynchronous UART or Synchronous SPI by Software

- Universal Serial Communication Interface
  - Enhanced UART Supporting Auto-Baudrate Detection
  - IrDA Encoder and Decoder
  - Synchronous SPI
  - **I2C**<sup>TM</sup>
- Serial Onboard Programming,
   Programmable Code Protection by Security
   Fuse
- Brownout Detector
- Basic Timer With Real Time Clock Feature
- Integrated LCD Driver up to 160 Segments With Regulated Charge Pump
- Family Members Include:
  - MSP430xG4616:

92KB+256B Flash or ROM Memory 4KB RAM

MSP430xG4617:

92KB+256B Flash or ROM Memory, 8KB RAM

- MSP430xG4618:

116KB+256B Flash or ROM Memory, 8KB RAM

MSP430xG4619:

120KB+256B Flash or ROM Memory, 4KB RAM

 For Complete Module Descriptions, See the MSP430x4xx Family User's Guide (literature number SLAU056)

#### description

The Texas Instruments MSP430 family of ultralow-power microcontrollers consists of several devices featuring different sets of peripherals targeted for various applications. The architecture, combined with five low-power modes, is optimized to achieve extended battery life in portable measurement applications. The device features a powerful 16-bit RISC CPU, 16-bit registers, and constant generators that contribute to maximum code efficiency. The digitally controlled oscillator (DCO) allows wake-up from low-power modes to active mode in less than 6  $\mu$ s.

The MSP430xG461x series are microcontroller configurations with two 16-bit timers, a high-performance 12-bit A/D converter, dual 12-bit D/A converters, three configurable operational amplifiers, one universal serial communication interface (USCI), one universal synchronous/asynchronous communication interface (USART), DMA, 80 I/O pins, and a liquid crystal display (LCD) driver with regulated charge pump.

Typical applications for this device include portable medical applications and e-meter applications.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications. These devices have limited built-in ESD protection.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### **AVAILABLE OPTIONS**<sup>†</sup>

	PACKAGED DEVICES <sup>‡</sup>						
T <sub>A</sub>	PLASTIC 100-PIN TQFP (PZ)	PLASTIC 113-BALL BGA (ZQW)					
	MSP430FG4616IPZ	MSP430FG4616IZQW					
	MSP430FG4617IPZ	MSP430FG4617IZQW					
	MSP430FG4618IPZ	MSP430FG4618IZQW					
4000 to 0500	MSP430FG4619IPZ	MSP430FG4619IZQW					
-40°C to 85°C	MSP430CG4616IPZ	MSP430CG4616IZQW					
	MSP430CG4617IPZ	MSP430CG4617IZQW					
	MSP430CG4618IPZ	MSP430CG4618IZQW					
	MSP430CG4619IPZ	MSP430CG4619IZQW					

<sup>&</sup>lt;sup>†</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

#### **DEVELOPMENT TOOL SUPPORT**

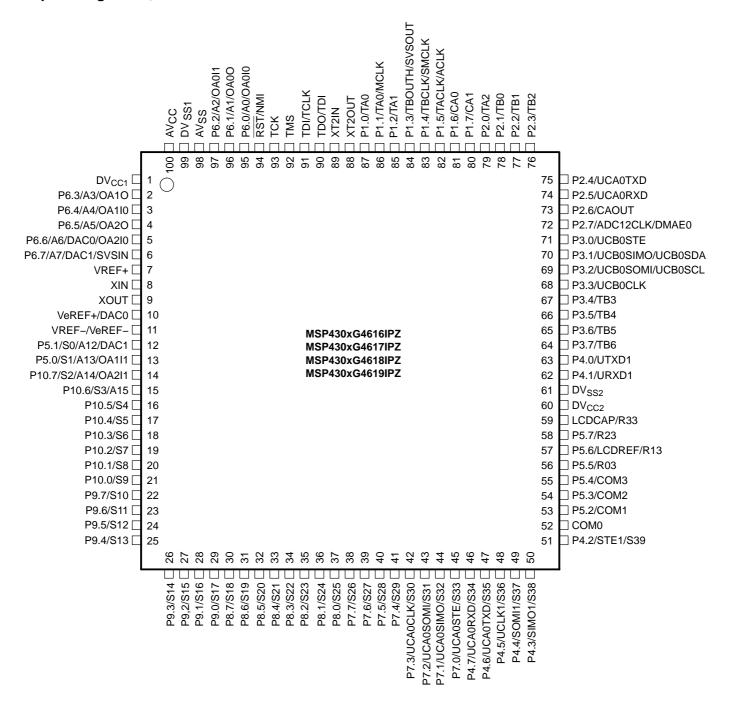
All MSP430 microcontrollers include an Embedded Emulation Module (EEM) allowing advanced debugging and programming through easy-to-use development tools. Recommended hardware options include:

- Debugging and Programming Interface
  - MSP-FET430UIF (USB)
  - MSP-FET430PIF (Parallel Port)
- Debugging and Programming Interface with Target Board
  - MSP-FET430U100 (for PZ package)
- Standalone Target Board
  - MSP-TS430PZ100 (for PZ package)
- **Production Programmer** 
  - MSP-GANG430



<sup>&</sup>lt;sup>‡</sup> Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

# pin designation, MSP430xG461xIPZ



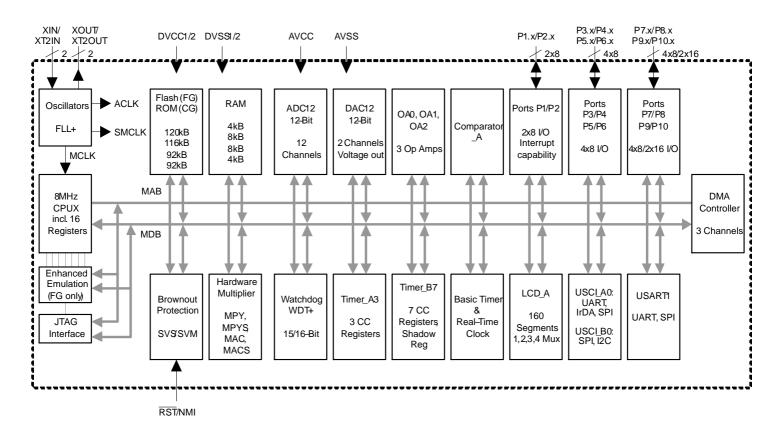


# pin designation, MSP430xG461xIZQW (top view)

	ı												
M		$\bigcirc$											
L		$\bigcirc$											
K		$\bigcirc$	$\bigcirc$									$\bigcirc$	$\bigcirc$
J		$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$
Н		$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$
G		$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$			$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$
F		$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$			$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$
E		$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$
D		$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		$\bigcirc$	$\bigcirc$
С		$\bigcirc$	$\bigcirc$	$\bigcirc$								$\bigcirc$	$\bigcirc$
В		$\bigcirc$											
Α		$\bigcirc$											

NOTE: For terminal assignments, see the MSP430xG461x Terminal Functions table.

# functional block diagram



#### **Terminal Functions**

P6.3/A3/OA1O P6.4/A4/OA1IO P6.5/A5/OA2O P6.6/A6/DAC0/OA2IO P6.7/A7/DAC1/SVSIN V <sub>REF+</sub> XIN	NO. PZ 1 2 3 4 5 6 7 8 9 10 11	NO. ZQW A1 B1 B2 C2 C1 C3 D2 D1 E1 E2	1/O	DESCRIPTION  Digital supply voltage, positive terminal General-purpose digital I/O / analog input a3—12-bit ADC / OA1 output General-purpose digital I/O / analog input a4—12-bit ADC / OA1 input multiplexer on +terminal and -terminal General-purpose digital I/O / analog input a5—12-bit ADC / OA2 output General-purpose digital I/O / analog input a6—12-bit ADC / DAC12.0 output / OA2 input multiplexer on +terminal and -terminal General-purpose digital I/O / analog input a7—12-bit ADC / DAC12.1 output / analog input to brownout, supply voltage supervisor Output of positive terminal of the reference voltage in the ADC Input port for crystal oscillator XT1. Standard or watch crystals can be connected.
P6.3/A3/OA1O P6.4/A4/OA1I0  P6.5/A5/OA2O P6.6/A6/DAC0/OA2I0  P6.7/A7/DAC1/SVSIN  V <sub>REF+</sub> XIN	2 3 4 5 6 7 8 9	B1 B2 C2 C1 C3 D2 D1 E1	1/O 1/O 1/O 1/O 1/O 1/O	General-purpose digital I/O / analog input a3—12-bit ADC / OA1 output General-purpose digital I/O / analog input a4—12-bit ADC / OA1 input multiplexer on +terminal and -terminal General-purpose digital I/O / analog input a5—12-bit ADC / OA2 output General-purpose digital I/O / analog input a6—12-bit ADC / DAC12.0 output / OA2 input multiplexer on +terminal and -terminal General-purpose digital I/O / analog input a7—12-bit ADC / DAC12.1 output / analog input to brownout, supply voltage supervisor Output of positive terminal of the reference voltage in the ADC
P6.4/A4/OA1I0  P6.5/A5/OA2O  P6.6/A6/DAC0/OA2I0  P6.7/A7/DAC1/SVSIN  V <sub>REF+</sub> XIN	3 4 5 6 7 8 9	B2 C2 C1 C3 D2 D1 E1	1/O 1/O 1/O 1/O 1/O 1/O	General-purpose digital I/O / analog input a4—12-bit ADC / OA1 input multiplexer on +terminal and -terminal  General-purpose digital I/O / analog input a5—12-bit ADC / OA2 output  General-purpose digital I/O / analog input a6—12-bit ADC / DAC12.0 output / OA2 input multiplexer on +terminal and -terminal  General-purpose digital I/O / analog input a7—12-bit ADC / DAC12.1 output / analog input to brownout, supply voltage supervisor  Output of positive terminal of the reference voltage in the ADC
P6.5/A5/OA2O P6.6/A6/DAC0/OA2I0 P6.7/A7/DAC1/SVSIN V <sub>REF+</sub> XIN	4 5 6 7 8 9	C2 C1 C3 D2 D1 E1	I/O I/O I/O O	on +terminal and -terminal  General-purpose digital I/O / analog input a5—12-bit ADC / OA2 output  General-purpose digital I/O / analog input a6—12-bit ADC / DAC12.0 output / OA2 input multiplexer on +terminal and -terminal  General-purpose digital I/O / analog input a7—12-bit ADC / DAC12.1 output / analog input to brownout, supply voltage supervisor  Output of positive terminal of the reference voltage in the ADC
P6.6/A6/DAC0/OA2I0  P6.7/A7/DAC1/SVSIN  V <sub>REF+</sub> XIN	5 6 7 8 9	C1 C3 D2 D1 E1	I/O I/O I	General-purpose digital I/O / analog input a6—12-bit ADC / DAC12.0 output / OA2 input multiplexer on +terminal and -terminal  General-purpose digital I/O / analog input a7—12-bit ADC / DAC12.1 output / analog input to brownout, supply voltage supervisor  Output of positive terminal of the reference voltage in the ADC
P6.7/A7/DAC1/SVSIN  V <sub>REF+</sub> XIN	6 7 8 9 10	C3 D2 D1 E1	I/O O I	input multiplexer on +terminal and -terminal  General-purpose digital I/O / analog input a7—12-bit ADC / DAC12.1 output / analog input to brownout, supply voltage supervisor  Output of positive terminal of the reference voltage in the ADC
V <sub>REF+</sub>	7 8 9 10	D2 D1 E1	0	analog input to brownout, supply voltage supervisor  Output of positive terminal of the reference voltage in the ADC
XIN	8 9 10	D1 E1	I	
XIN	9	E1		Input port for crystal oscillator XT1. Standard or watch crystals can be connected.
VOLIT	10		С	
XOUT		F2		Output terminal of crystal oscillator XT1
Ve <sub>REF+</sub> /DAC0	11	L_	I/O	Input for an external reference voltage to the ADC / DAC12.0 output
		E4	I	Negative terminal for the ADC reference voltage for both sources, the internal reference voltage, or an external applied reference voltage
P5.1/S0/A12/DAC1 (see Note 1)	12	F1	I/O	General-purpose digital I/O / LCD segment output 0 / analog input a12 – 12-bit ADC / DAC12.1 output
P5.0/S1/A13/OA1I1 (see Note 1)	13	F2	I/O	General-purpose digital I/O / LCD segment output 1 / analog input a13 – 12-bit ADC/OA1 input multiplexer on +terminal and -terminal
P10.7/S2/A14/OA2I1 (see Note 1)	14	E5	I/O	General-purpose digital I/O / LCD segment output 2 / analog input a14 – 12-bit ADC/OA2 input multiplexer on +terminal and -terminal
P10.6/S3/A15 (see Note 1)	15	G1	I/O	General-purpose digital I/O / LCD segment output 3 / analog input a15 – 12-bit ADC
P10.5/S4	16	G2	I/O	General-purpose digital I/O / LCD segment output 4
P10.4/S5	17	F4	I/O	General-purpose digital I/O / LCD segment output 5
P10.3/S6	18	H1	I/O	General-purpose digital I/O / LCD segment output 6
P10.2/S7	19	H2	I/O	General-purpose digital I/O / LCD segment output 7
P10.1/S8	20	F5	I/O	General-purpose digital I/O / LCD segment output 8
P10.0/S9	21	J1	I/O	General-purpose digital I/O / LCD segment output 9
P9.7/S10	22	J2	I/O	General-purpose digital I/O / LCD segment output 10
P9.6/S11	23	G4	I/O	General-purpose digital I/O / LCD segment output 11
P9.5/S12	24	K1	I/O	General-purpose digital I/O / LCD segment output 12
P9.4/S13	25	L1	I/O	General-purpose digital I/O / LCD segment output 13
P9.3/S14	26	M2	I/O	General-purpose digital I/O / LCD segment output 14
P9.2/S15	27	K2	I/O	General-purpose digital I/O / LCD segment output 15
P9.1/S16	28	L3	I/O	General-purpose digital I/O / LCD segment output 16
P9.0/S17	29	МЗ	I/O	General-purpose digital I/O / LCD segment output 17
P8.7/S18	30	H4	I/O	General-purpose digital I/O / LCD segment output 18
	31	L4	I/O	General-purpose digital I/O / LCD segment output 19
	32	M4	I/O	General-purpose digital I/O / LCD segment output 20
	33	G5	I/O	General-purpose digital I/O / LCD segment output 21
	34	L5	I/O	General-purpose digital I/O / LCD segment output 22

NOTES: 1. Segments S0 through S3 are disabled when the LCD charge pump feature is enabled (LCDCPEN = 1) and cannot be used together with the LCD charge pump. In addition, when using segments S0 through S3 with an external LCD voltage supply, V<sub>LCD</sub> ≤ AV<sub>CC</sub>.



# **Terminal Functions (Continued)**

TERMINAL						
NAME	NO. PZ	NO. ZQW	I/O	DESCRIPTION		
P8.2/S23	35	M5	I/O	General-purpose digital I/O / LCD segment output 23		
P8.1/S24	36	H5	I/O	General-purpose digital I/O / LCD segment output 24		
P8.0/S25	37	J5	1/0	General-purpose digital I/O / LCD segment output 25		
P7.7/S26	38	M6	I/O	General-purpose digital I/O / LCD segment output 26		
P7.6/S27	39	L6	I/O	General-purpose digital I/O / LCD segment output 27		
P7.5/S28	40	J6	I/O	General-purpose digital I/O / LCD segment output 28		
P7.4/S29	41	M7	I/O	General-purpose digital I/O / LCD segment output 29		
P7.3/UCA0CLK/S30	42	H6	I/O	General-purpose digital I/O / external clock input – USCI_A0/UART or SPI mode, clock output – USCI_A0/SPI mode / LCD segment 30		
P7.2/UCA0SOMI/S31	43	L7	I/O	General-purpose digital I/O / slave out/master in of USCI_A0/SPI mode / LCD segment output 31		
P7.1/UCA0SIMO/S32	44	M8	I/O	General-purpose digital I/O / slave in/master out of USCI_A0/SPI mode / LCD segment output 32		
P7.0/UCA0STE/S33	45	L8	I/O	General-purpose digital I/O / slave transmit enable—USCI_A0/SPI mode / LCD segment output 33		
P4.7/UCA0RXD/S34	46	J7	I/O	General-purpose digital I/O / receive data in – USCI_A0/UART or IrDA mode / LCD segment output 34		
P4.6/UCA0TXD/S35	47	M9	I/O	General-purpose digital I/O / transmit data out – USCI_A0/UART or IrDA mode / LCD segment output 35		
P4.5/UCLK1/S36	48	L9	1/0	General-purpose digital I/O / external clock input – USART1/UART or SPI mode, clock output – USART1/SPI MODE / LCD segment output 36		
P4.4/SOMI1/S37	49	H7	I/O	General-purpose digital I/O / slave out/master in of USART1/SPI mode / LCD segment output 37		
P4.3/SIMO1/S38	50	M10	1/0	General-purpose digital I/O / slave in/master out of USART1/SPI mode / LCD segment output 38		
P4.2/STE1/S39	51	M11	I/O	General-purpose digital I/O / slave transmit enable—USART1/SPI mode / LCD segment output 39		
COM0	52	L10	0	COM0-3 are used for LCD backplanes.		
P5.2/COM1	53	L12	1/0	General-purpose digital I/O / common output, COM0–3 are used for LCD backplanes.		
P5.3/COM2	54	J8	I/O	General-purpose digital I/O / common output, COM0–3 are used for LCD backplanes.		
P5.4/COM3	55	K12	I/O	General-purpose digital I/O / common output, COM0–3 are used for LCD backplanes.		
P5.5/R03	56	K11	I/O	General-purpose digital I/O / Input port of lowest analog LCD level (V5)		
P5.6/LCDREF/R13	57	J12	I/O	General-purpose digital I/O / External reference voltage input for regulated LCD voltage / Input port of third most positive analog LCD level (V4 or V3)		
P5.7/R23	58	J11	I/O	General-purpose digital I/O / Input port of second most positive analog LCD level (V2)		
LCDCAP/R33	59	H11	I	LCD capacitor connection / Input/output port of most positive analog LCD level (V1)		
DV <sub>CC2</sub>	60	H12		Digital supply voltage, positive terminal		
DV <sub>SS2</sub>	61	G12		Digital supply voltage, negative terminal		
P4.1/URXD1	62	G11	I/O	General-purpose digital I/O / receive data in—USART1/UART mode		
P4.0/UTXD1	63	H9	I/O	General-purpose digital I/O / transmit data out—USART1/UART mode		
P3.7/TB6	64	F12	I/O	General-purpose digital I/O / Timer_B7 CCR6. Capture: CCI6A/CCI6B input, compare: Out6 output		
P3.6/TB5	65	F11	I/O	General-purpose digital I/O / Timer_B7 CCR5. Capture: CCI5A/CCI5B input, compare: Out5 output		
P3.5/TB4	66	G9	I/O	General-purpose digital I/O / Timer_B7 CCR4. Capture: CCI4A/CCI4B input, compare: Out4 output		



# **Terminal Functions (Continued)**

TERMINAL							
NAME	NO.	NO.	I/O	DESCRIPTION			
IVANIL	PZ	ZQW					
P3.4/TB3	67	E12	I/O	General-purpose digital I/O / Timer_B7 CCR3. Capture: CCl3A/CCl3B input, compare: Output			
P3.3/UCB0CLK	68	E11	I/O	General-purpose digital I/O / external clock input—USCI_B0/UART or SPI mode, clock output—USCI_B0/SPI mode			
P3.2/UCB0SOMI/ UCB0SCL	69	F9	I/O	General-purpose digital I/O / slave out/master in of USCI_B0/SPI mode /I2C clock—USCI_B0/I2C mode			
P3.1/UCB0SIMO/ UCB0SDA	70	D12	I/O	General-purpose digital I/O / slave in/master out of USCI_B0/SPI mode, I2C data—USCI_B0/I2C mode			
P3.0/UCB0STE	71	D11	I/O	General-purpose digital I/O / slave transmit enable—USCI_B0/SPI mode			
P2.7/ADC12CLK/ DMAE0	72	E9	I/O	General-purpose digital I/O / conversion clock—12-bit ADC / DMA Channel 0 external trigger			
P2.6/CAOUT	73	C12	I/O	General-purpose digital I/O / Comparator_A output			
P2.5/UCA0RXD	74	C11	I/O	General-purpose digital I/O / receive data in—USCI_A0/UART or IrDA mode			
P2.4/UCA0TXD	75	B12	I/O	General-purpose digital I/O / transmit data out—USCI_A0/UART or IrDA mode			
P2.3/TB2	76	A11	I/O	General-purpose digital I/O / Timer_B7 CCR2. Capture: CCI2A/CCI2B input, compare: Out2 output			
P2.2/TB1	77	E8	I/O	General-purpose digital I/O / Timer_B7 CCR1. Capture: CCI1A/CCI1B input, compare: Out1 output			
P2.1/TB0	78	D8	I/O	General-purpose digital I/O / Timer_B7 CCR0. Capture: CCI0A/CCI0B input, compare: Out0 output			
P2.0/TA2	79	A10	I/O	General-purpose digital I/O / Timer_A Capture: CCl2A input, compare: Out2 output			
P1.7/CA1	80	B10	I/O	General-purpose digital I/O / Comparator_A input			
P1.6/CA0	81	A9	I/O	General-purpose digital I/O / Comparator_A input			
P1.5/TACLK/ACLK	82	В9	I/O	General-purpose digital I/O / Timer_A, clock signal TACLK input / ACLK output (divided by 1, 2, 4, or 8)			
P1.4/TBCLK/SMCLK	83	В8	I/O	General-purpose digital I/O / input clock TBCLK—Timer_B7 / submain system clock SMCLK output			
P1.3/TBOUTH/SVSOUT	84	A8	I/O	General-purpose digital I/O / switch all PWM digital output ports to high impedance—Timer_B7 TB0 to TB6 / SVS: output of SVS comparator			
P1.2/TA1	85	D7	I/O	General-purpose digital I/O / Timer_A, Capture: CCI1A input, compare: Out1 output			
P1.1/TA0/MCLK	86	E7	I/O	General-purpose digital I/O / Timer_A. Capture: CCI0B input / MCLK output.  Note: TA0 is only an input on this pin / BSL receive			
P1.0/TA0	87	A7	I/O	General-purpose digital I/O / Timer_A. Capture: CCI0A input, compare: Out0 output / BSL transmit			
XT2OUT	88	В7	0	Output terminal of crystal oscillator XT2			
XT2IN	89	В6	ı	Input port for crystal oscillator XT2. Only standard crystals can be connected.			
TDO/TDI	90	A6	I/O	Test data output port. TDO/TDI data output or programming data input terminal			
TDI/TCLK	91	D6	I	Test data input or test clock input. The device protection fuse is connected to TDI/TCLK.			
TMS	92	E6	ı	Test mode select. TMS is used as an input port for device programming and test.			
TCK	93	A5	ı	Test clock. TCK is the clock input port for device programming and test.			
RST/NMI	94	B5	- 1	Reset input or nonmaskable interrupt input port			
P6.0/A0/OA0I0	95	A4	I/O	General-purpose digital I/O / analog input a0—12-bit ADC / OA0 input multiplexer on + terminal and – terminal			
P6.1/A1/OA0O	96	D5	I/O	General-purpose digital I/O / analog input a1—12-bit ADC / OA0 output			
P6.2/A2/OA0I1	97	В4	I/O	General-purpose digital I/O / analog input a2—12-bit ADC / OA0 input multiplexer on + terminal and - terminal			



# MSP430xG461x MIXED SIGNAL MICROCONTROLLER

SLAS508I - APRIL 2006 - REVISED MARCH 2011

# **Terminal Functions (Continued)**

TERMINAL	RMINAL			TERMINAL			
NAME	NO. PZ	NO. ZQW	I/O	DESCRIPTION			
$AV_{SS}$	98	А3		Analog supply voltage, negative terminal. Supplies SVS, brownout, oscillator, comparator_A, port 1			
DV <sub>SS1</sub> (see Note 1)	99	В3		Digital supply voltage, negative terminal			
AV <sub>CC</sub>	100	A2		Analog supply voltage, positive terminal. Supplies SVS, brownout, oscillator, comparator_A, port 1; must not power up prior to $DV_{CC1}/DV_{CC2}$ .			

NOTE 1: All unassigned ball locations on the ZQW package should be electrically tied to the ground supply. The shortest ground return path to the device should be established via ball location B3.

# short-form description

#### **CPU**

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter, stack pointer, status register, and constant generator respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses, and can be handled with all instructions.

The MSP430xG461x device family utilizes the MSP430X CPU and is completely backwards compatible with the MSP430 CPU. For a complete description of the MSP430X CPU, see the MSP430x4xx Family User's Guide (SLAU056).

#### instruction set

The instruction set consists of the original 51 instructions with three formats and seven address modes and additional instructions for the expanded address range. Each instruction can operate on word and byte data. Table 1 shows examples of the three types of instruction formats; Table 2 shows the address modes.

Program Counter	PC/R0
Stack Pointer	SP/R1
Status Register	SR/CG1/R2
Constant Generator	CG2/R3
General-Purpose Register	R4
General-Purpose Register	R5
General-Purpose Register	R6
General-Purpose Register	R7
General-Purpose Register	R8
General-Purpose Register	R9
General-Purpose Register	R10
General-Purpose Register	R11
General-Purpose Register	R12
General-Purpose Register	R13
General-Purpose Register	R14
General-Purpose Register	R15

### **Table 1. Instruction Word Formats**

Dual operands, source-destination	e.g., ADD R4,R5	R4 + R5> R5		
Single operands, destination only	e.g., CALL R8	PC>(TOS), R8> PC		
Relative jump, un/conditional	e.g., JNE	Jump-on-equal bit = 0		

# **Table 2. Address Mode Descriptions**

ADDRESS MODE	DE S D SYNTAX		SYNTAX	EXAMPLE	OPERATION
Register	•	•	MOV Rs,Rd	MOV R10,R11	R10 —> R11
Indexed	•	•	MOV X(Rn),Y(Rm)	MOV 2(R5),6(R6)	M(2+R5)—> M(6+R6)
Symbolic (PC relative)	•	•	MOV EDE,TONI		M(EDE)> M(TONI)
Absolute	•	•	MOV & MEM, & TCDAT		M(MEM)> M(TCDAT)
Indirect	•		MOV @Rn,Y(Rm)	MOV @R10,Tab(R6)	M(R10) -> M(Tab+R6)
Indirect autoincrement			MOV @Rn+,Rm	MOV @R10+,R11	M(R10)> R11 R10 + 2> R10
Immediate	•		MOV #X,TONI	MOV #45,TONI	#45 —> M(TONI)

NOTE: S = source D = destination

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#### operating modes

The MSP430 has one active mode and five software-selectable low-power modes of operation. An interrupt event can wake up the device from any of the five low-power modes, service the request, and restore back to the low-power mode on return from the interrupt program.

The following six operating modes can be configured by software:

- Active mode (AM)
  - All clocks are active
- Low-power mode 0 (LPM0)
  - CPU is disabled
  - ACLK and SMCLK remain active. MCLK is disabled
  - FLL+ loop control remains active
- Low-power mode 1 (LPM1)
  - CPU is disabled
  - FLL+ loop control is disabled
  - ACLK and SMCLK remain active, MCLK is disabled
- Low-power mode 2 (LPM2)
  - CPU is disabled
  - MCLK, FLL+ loop control and DCOCLK are disabled
  - DCO's dc-generator remains enabled
  - ACLK remains active
- Low-power mode 3 (LPM3)
  - CPU is disabled
  - MCLK, FLL+ loop control, and DCOCLK are disabled
  - DCO's dc-generator is disabled
  - ACLK remains active
- Low-power mode 4 (LPM4)
  - CPU is disabled
  - ACLK is disabled
  - MCLK, FLL+ loop control, and DCOCLK are disabled
  - DCO's dc-generator is disabled
  - Crystal oscillator is stopped



#### interrupt vector addresses

The interrupt vectors and the power-up start address are located in the address range 0FFFh to 0FFC0h. The vector contains the 16-bit address of the appropriate interrupt-handler instruction sequence.

Table 3. Interrupt Sources, Flags, and Vectors of MSP430xG461x Configurations

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
Power-Up External Reset Watchdog Flash Memory	WDTIFG KEYV (see Note 1 and 5)	Reset	0FFFEh	31, highest
NMI Oscillator Fault Flash Memory Access Violation	NMIIFG (see Notes 1 and 3) OFIFG (see Notes 1 and 3) ACCVIFG (see Notes 1, 2, and 5)	(Non)maskable (Non)maskable (Non)maskable	0FFFCh	30
Timer_B7	TBCCR0 CCIFG0 (see Note 2)	Maskable	0FFFAh	29
Timer_B7	TBCCR1 CCIFG1 TBCCR6 CCIFG6, TBIFG (see Notes 1 and 2)	Maskable	0FFF8h	28
Comparator_A	CAIFG	Maskable	0FFF6h	27
Watchdog Timer+	WDTIFG	Maskable	0FFF4h	26
USCI_A0/USCI_B0 Receive	UCA0RXIFG, UCB0RXIFG (see Note 1)	Maskable	0FFF2h	25
USCI_A0/USCI_B0 Transmit	UCA0TXIFG, UCB0TXIFG (see Note 1)	Maskable	0FFF0h	24
ADC12	ADC12IFG (see Notes 1 and 2)	Maskable	0FFEEh	23
Timer_A3	TACCR0 CCIFG0 (see Note 2)	Maskable	0FFECh	22
Timer_A3	TACCR1 CCIFG1 and TACCR2 CCIFG2, TAIFG (see Notes 1 and 2)	Maskable	0FFEAh	21
I/O Port P1 (Eight Flags)	P1IFG.0 to P1IFG.7 (see Notes 1 and 2)	Maskable	0FFE8h	20
USART1 Receive	URXIFG1	Maskable	0FFE6h	19
USART1 Transmit	UTXIFG1	Maskable	0FFE4h	18
I/O Port P2 (Eight Flags)	P2IFG.0 to P2IFG.7 (see Notes 1 and 2)	Maskable	0FFE2h	17
Basic Timer1/RTC	BTIFG	Maskable	0FFE0h	16
DMA	DMA0IFG, DMA1IFG, DMA2IFG (see Notes 1 and 2)	Maskable	0FFDEh	15
DAC12	DAC12.0IFG, DAC12.1IFG (see Notes 1 and 2)	Maskable	0FFDCh	14
			0FFDAh	13
Reserved	Reserved (see Note 4)			
			0FFC0h	0, lowest

#### NOTES: 1. Multiple source flags

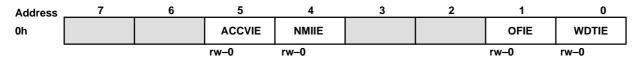
- 2. Interrupt flags are located in the module.
- 3. A reset is generated if the CPU tries to fetch instructions from within the module register memory address range (0h to 01FFh). (Non)maskable: the individual interrupt-enable bit can disable an interrupt event, but the general-interrupt enable cannot disable it.
- 4. The interrupt vectors at addresses 0FFDAh to 0FFC0h are not used in this device and can be used for regular program code if necessary.
- 5. Access and key violations, KEYV and ACCVIFG, only applicable to F devices.



# special function registers (SFRs)

The MSP430 SFRs are located in the lowest address space and are organized as byte mode registers. SFRs should be accessed with byte instructions.

### interrupt enable 1 and 2



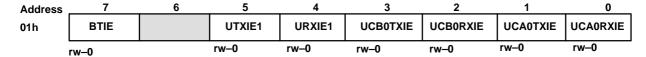
WDTIE Watchdog-timer interrupt enable. Inactive if watchdog mode is selected.

Active if watchdog timer is configured as a general-purpose timer.

OFIE Oscillator-fault-interrupt enable

NMIIE Nonmaskable-interrupt enable

ACCVIE Flash access violation interrupt enable



UCA0RXIE USCI\_A0 receive-interrupt enable
UCA0TXIE USCI\_A0 transmit-interrupt enable
UCB0RXIE USCI\_B0 receive-interrupt enable
UCB0TXIE USCI\_B0 transmit-interrupt enable

URXIE1 USART1 UART and SPI receive-interrupt enable
UTXIE1 USART1 UART and SPI transmit-interrupt enable

BTIE Basic timer interrupt enable

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# interrupt flag register 1 and 2

Address	7	6	5	4	3	2	1	0
02h				NMIIFG			OFIFG	WDTIFG
				rw–0			rw–1	rw-(0)

WDTIFG: Set on watchdog timer overflow (in watchdog mode) or security key violation

Reset on V<sub>CC</sub> power-on or a reset condition at the RST/NMI pin in reset mode

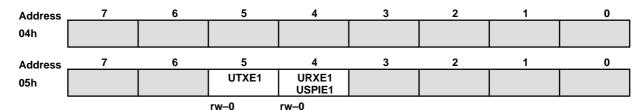
OFIFG: Flag set on oscillator fault NMIIFG: Set via RST/NMI pin

Address	7	6	5	4	3	2	1	0
03h	BTIFG		UTXIFG1	URXIFG1	UCB0TXIFG	UCB0RXIFG	UCA0TXIFG	UCA0RXIFG
	rw_0		rw_1	rw_0	rw-0	rw-0	rw-0	rw–0

UCA0RXIFG USCI\_A0 receive-interrupt flag
UCA0TXIFG USCI\_A0 transmit-interrupt flag
UCB0RXIFG USCI\_B0 receive-interrupt flag
UCB0TXIFG USCI\_B0 transmit-interrupt flag
URXIFG0: USART1: UART and SPI receive flag
UTXIFG0: USART1: UART and SPI transmit flag

BTIFG: Basic timer flag

# module enable registers 1 and 2



URXE1: USART1: UART mode receive enable
UTXE1: USART1: UART mode transmit enable

USPIE1: USART1: SPI mode transmit and receive enable

**Legend** rw: Bit can be read and written.

rw-0,1: Bit can be read and written. It is Reset or Set by PUC.rw-(0,1): Bit can be read and written. It is Reset or Set by POR.

SFR bit is not present in device

# memory organization

		MSP430FG4616	MSP430FG4617	MSP430FG4618	MSP430FG4619
Memory Main: interrupt vector Main: code memory	Size Flash Flash	92KB 0FFFFh – 0FFC0h 018FFFh – 002100h	92KB 0FFFFh – 0FFC0h 019FFFh – 003100h	116KB 0FFFFh – 0FFC0h 01FFFFh – 003100h	120KB 0FFFFh – 0FFC0h 01FFFFh – 002100h
RAM (Total)	Size	4KB 020FFh – 01100h	8KB 030FFh – 01100h	8KB 030FFh – 01100h	4KB 020FFh – 01100h
Extended	Size	2KB 020FFh – 01900h	6KB 030FFh – 01900h	6KB 030FFh – 01900h	2KB 020FFh – 01900h
Mirrored	Size	2KB 018FFh – 01100h	2KB 018FFh – 01100h	2KB 018FFh – 01100h	2KB 018FFh – 01100h
Information memory	Size Flash	256 Byte 010FFh – 01000h	256 Byte 010FFh – 01000h	256 Byte 010FFh – 01000h	256 Byte 010FFh – 01000h
Boot memory	Size ROM	1KB 0FFFh – 0C00h	1KB 0FFFh – 0C00h	1KB 0FFFh – 0C00h	1KB 0FFFh – 0C00h
RAM (mirrored at 018FFh – 01100h)	Size	2KB 09FFh – 0200h	2KB 09FFh – 0200h	2KB 09FFh – 0200h	2KB 09FFh – 0200h
Peripherals	16 bit 8 bit 8-bit SFR	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h

		MSP430CG4616	MSP430CG4617	MSP430CG4618	MSP430CG4619
Memory Main: interrupt vector Main: code memory	Size ROM ROM	92KB 0FFFFh – 0FFC0h 018FFFh – 002100h	92KB 0FFFFh – 0FFC0h 019FFFh – 003100h	116KB 0FFFFh – 0FFC0h 01FFFFh – 003100h	120KB 0FFFFh – 0FFC0h 01FFFFh – 002100h
RAM (Total)	Size	4KB 020FFh – 01100h	8KB 030FFh – 01100h	8KB 030FFh – 01100h	4KB 020FFh – 01100h
Extended	Size	2KB 020FFh – 01900h	6KB 030FFh – 01900h	6KB 030FFh – 01900h	2KB 020FFh – 01900h
Mirrored	Size	2KB 018FFh – 01100h	2KB 018FFh – 01100h	2KB 018FFh – 01100h	2KB 018FFh – 01100h
Information memory	Size ROM	256 Byte 010FFh – 01000h	256 Byte 010FFh – 01000h	256 Byte 010FFh – 01000h	256 Byte 010FFh – 01000h
Boot memory (Optional on CG)	Size ROM	1KB 0FFFh – 0C00h	1KB 0FFFh – 0C00h	1KB 0FFFh – 0C00h	1KB 0FFFh – 0C00h
RAM (mirrored at 018FFh – 01100h)	Size	2KB 09FFh – 0200h	2KB 09FFh – 0200h	2KB 09FFh – 0200h	2KB 09FFh – 0200h
Peripherals	16 bit 8 bit 8-bit SFR	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h

# bootstrap loader (BSL)

The MSP430 BSL enables users to program the flash memory or RAM using a UART serial interface. Access to the MSP430 memory via the BSL is protected by user-defined password. A bootstrap loader security key is provided at address 0FFBEh to disable the BSL completely or to disable the erasure of the flash if an invalid password is supplied. The BSL is optional for ROM-based devices. For complete description of the features of the BSL and its implementation, see the application report *Features of the MSP430 Bootstrap Loader*, literature number SLAA089.

BSLKEY	DESCRIPTION
00000h	Erasure of flash disabled if an invalid password is supplied
0AA55h	BSL disabled
any other value	BSL enabled

BSL FUNCTION	PZ/ZQW PACKAGE PINS
Data Transmit	87/A7 – P1.0
Data Receive	86/E7 – P1.1

# flash memory

The flash memory can be programmed via the JTAG port, the bootstrap loader, or in system by the CPU. The CPU can perform single-byte and single-word writes to the flash memory. Features of the flash memory include:

- Flash memory has n segments of main memory and two segments of information memory (A and B) of 128 bytes each. Each segment in main memory is 512 bytes in size.
- Segments 0 to n may be erased in one step, or each segment may be individually erased.
- Segments A and B can be erased individually, or as a group with segments 0 to n.
   Segments A and B are also called information memory.
- New devices may have some bytes programmed in the information memory (needed for test during manufacturing). The user should perform an erase of the information memory prior to the first use.

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### peripherals

Peripherals are connected to the CPU through data, address, and control buses and can be handled using all instructions. For complete module descriptions, see the MSP430x4xx Family User's Guide (SLAU056).

#### **DMA** controller

The DMA controller allows movement of data from one memory address to another without CPU intervention. For example, the DMA controller can be used to move data from the ADC12 conversion memory to RAM. Using the DMA controller can increase the throughput of peripheral modules. The DMA controller reduces system power consumption by allowing the CPU to remain in sleep mode without having to awaken to move data to or from a peripheral.

#### oscillator and system clock

The clock system in the MSP430xG461x family of devices is supported by the FLL+ module, which includes support for a 32768-Hz watch crystal oscillator, an internal digitally controlled oscillator (DCO), and a high-frequency crystal oscillator. The FLL+ clock module is designed to meet the requirements of both low system cost and low power consumption. The FLL+ features digital frequency locked loop (FLL) hardware that, in conjunction with a digital modulator, stabilizes the DCO frequency to a programmable multiple of the watch crystal frequency. The internal DCO provides a fast turn-on clock source and stabilizes in less than 6 μs. The FLL+ module provides the following clock signals:

- Auxiliary clock (ACLK), sourced from a 32768-Hz watch crystal or a high frequency crystal
- Main clock (MCLK), the system clock used by the CPU
- Sub-Main clock (SMCLK), the subsystem clock used by the peripheral modules
- ACLK/n, the buffered output of ACLK, ACLK/2, ACLK/4, or ACLK/8

### brownout, supply voltage supervisor

The brownout circuit is implemented to provide the proper internal reset signal to the device during power-on and power-off. The supply voltage supervisor (SVS) circuitry detects if the supply voltage drops below a user selectable level and supports both supply voltage supervision (the device is automatically reset) and supply voltage monitoring (SVM, the device is not automatically reset).

The CPU begins code execution after the brownout circuit releases the device reset. However,  $V_{CC}$  may not have ramped to  $V_{CC(min)}$  at that time. The user must insure the default FLL+ settings are not changed until  $V_{CC}$  reaches  $V_{CC(min)}$ . If desired, the SVS circuit can be used to determine when  $V_{CC}$  reaches  $V_{CC(min)}$ .

#### digital I/O

There are ten 8-bit I/O ports implemented—ports P1 through P10:

- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt conditions is possible.
- Edge-selectable interrupt input capability for all the eight bits of ports P1 and P2.
- Read/write access to port-control registers is supported by all instructions.
- Ports P7/P8 and P9/P10 can be accessed word-wise as ports PA and PB respectively.

#### **Basic Timer1 and Real-Time Clock**

The Basic Timer1 has two independent 8-bit timers that can be cascaded to form a 16-bit timer/counter. Both timers can be read and written by software. Basic Timer1 is extended to provide an integrated real-time clock (RTC). An internal calendar compensates for months with less than 31 days and includes leap-year correction.



# LCD\_A drive with regulated charge pump

The LCD\_A driver generates the segment and common signals required to drive an LCD display. The LCD\_A controller has dedicated data memory to hold segment drive information. Common and segment signals are generated as defined by the mode. Static, 2-MUX, 3-MUX, and 4-MUX LCDs are supported by this peripheral. The module can provide a LCD voltage independent of the supply voltage with its integrated charge pump. Furthermore it is possible to control the level of the LCD voltage and, thus, contrast by software.

# watchdog timer (WDT+)

The primary function of the WDT+ module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the module can be configured as an interval timer and can generate interrupts at selected time intervals.

#### universal serial communication interface (USCI)

The USCI modules are used for serial data communication. The USCI module supports synchronous communication protocols like SPI (3 or 4 pin), I2C and asynchronous communication protocols like UART, enhanced UART with automatic baudrate detection, and IrDA.

The USCI A0 module provides support for SPI (3 or 4 pin), UART, enhanced UART and IrDA.

The USCI\_B0 module provides support for SPI (3 or 4 pin) and I2C.

#### **USART1**

The hardware universal synchronous/asynchronous receive transmit (USART) peripheral module is used for serial data communication. The USART supports synchronous SPI (3 or 4 pin) and asynchronous UART communication protocols, using double-buffered transmit and receive channels.

#### hardware multiplier

The multiplication operation is supported by a dedicated peripheral module. The module performs  $16 \times 16$ ,  $16 \times 8$ ,  $8 \times 16$ , and  $8 \times 8$  bit operations. The module is capable of supporting signed and unsigned multiplication, as well as signed and unsigned multiply and accumulate operations. The result of an operation can be accessed immediately after the operands have been loaded into the peripheral registers. No additional clock cycles are required.



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# Timer\_A3

Timer\_A3 is a 16-bit timer/counter with three capture/compare registers. Timer\_A3 can support multiple capture/compares, PWM outputs, and interval timing. Timer\_A3 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

	Timer_A3 Signal Connections					
Input Pin Number	Device Input	Module Input	Module	Module Output	Output Pin Number	
PZ/ZQW	Signal	Name	Block	Signal	PZ/ZQW	
82/B9 - P1.5	TACLK	TACLK				
	ACLK	ACLK	1 _			
	SMCLK	SMCLK	Timer	NA		
82/B9 - P1.5	TACLK	INCLK				
87/A7 - P1.0	TA0	CCI0A			87/A7 - P1.0	
86/E7 - P1.1	TA0	CCI0B	7			
	DV <sub>SS</sub>	GND	CCR0	TA0		
	DV <sub>CC</sub>	V <sub>CC</sub>				
85/D7 - P1.2	TA1	CCI1A			85/D7 - P1.2	
	CAOUT (internal)	CCI1B	]	T. 4	ADC12 (internal)	
	DV <sub>SS</sub>	GND	CCR1	TA1		
	DV <sub>CC</sub>	V <sub>CC</sub>				
79/A10 - P2.0	TA2	CCI2A			79/A10 - P2.0	
	ACLK (internal)	CCI2B	0000			
	DV <sub>SS</sub>	GND	CCR2	TA2		
	DV <sub>CC</sub>	V <sub>CC</sub>	7			

# Timer\_B7

Timer\_B7 is a 16-bit timer/counter with seven capture/compare registers. Timer\_B7 can support multiple capture/compares, PWM outputs, and interval timing. Timer\_B7 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

		Timer_B7 Signal Co	nnections		
Input Pin Number	Device Input	Module Input	Module	Module Output	Output Pin Numbe
PZ/ZQW	Signal	Name	Block	Signal	PZ/ZQW
83/B8 - P1.4	TBCLK	TBCLK			
	ACLK	ACLK	1 _	l [	
	SMCLK	SMCLK	Timer	NA	
83/B8 - P1.4	TBCLK	INCLK			
78/D8 - P2.1	TB0	CCI0A			78/D8 - P2.1
78/D8 - P2.1	TB0	CCI0B	1	<u></u> _	ADC12 (internal)
	DV <sub>SS</sub>	GND	CCR0	TB0	
	DV <sub>CC</sub>	V <sub>CC</sub>			
77/E8 - P2.2	TB1	CCI1A			77/E8 - P2.2
77/E8 - P2.2	TB1	CCI1B		F	ADC12 (internal)
	DV <sub>SS</sub>	GND	CCR1	TB1	
	DV <sub>CC</sub>	V <sub>CC</sub>	1		
76/A11 - P2.3	TB2	CCI2A		TB2	76/A11 - P2.3
76/A11 - P2.3	TB2	CCI2B	1		
	DV <sub>SS</sub>	GND	CCR2		
	DV <sub>CC</sub>	V <sub>CC</sub>	1		
67/E12 - P3.4	TB3	CCI3A			67/E12 - P3.4
67/E12 - P3.4	TB3	CCI3B	1		
	DV <sub>SS</sub>	GND	CCR3	TB3	
	DV <sub>CC</sub>	V <sub>CC</sub>	1		
66/G9 - P3.5	TB4	CCI4A			66/G9 - P3.5
66/G9 - P3.5	TB4	CCI4B	1		
	DV <sub>SS</sub>	GND	CCR4	TB4	
	DV <sub>CC</sub>	V <sub>CC</sub>			
65/F11 - P3.6	TB5	CCI5A			65/F11 - P3.6
65/F11 - P3.6	TB5	CCI5B	1		
	DV <sub>SS</sub>	GND	CCR5	TB5	
	DV <sub>CC</sub>	V <sub>CC</sub>			
64/F12 - P3.7	TB6	CCI6A			64/F12 - P3.7
	ACLK (internal)	CCI6B	1		
	DV <sub>SS</sub>	GND	CCR6	TB6	
	DV <sub>CC</sub>	V <sub>CC</sub>	1		

# Comparator\_A

The primary function of the comparator\_A module is to support precision slope analog-to-digital conversions, battery-voltage supervision, and monitoring of external analog signals.

#### ADC12

The ADC12 module supports fast, 12-bit analog-to-digital conversions. The module implements a 12-bit SAR core, sample select control, reference generator and a 16 word conversion-and-control buffer. The conversion-and-control buffer allows up to 16 independent ADC samples to be converted and stored without any CPU intervention.

#### DAC12

The DAC12 module is a 12-bit, R-ladder, voltage output DAC. The DAC12 may be used in 8- or 12-bit mode, and may be used in conjunction with the DMA controller. When multiple DAC12 modules are present, they may be grouped together for synchronous operation.

#### OA

The MSP430xG461x has three configurable low-current general-purpose operational amplifiers. Each OA input and output terminal is software-selectable and offer a flexible choice of connections for various applications. The OA op amps primarily support front-end analog signal conditioning prior to analog-to-digital conversion.

	OA Signal Connections							
Input Pin Number	Device Input	Module Input Name	Module Block	Module Output	Device Output	Output Pin Number		
PZ	Signal	Name	BIOCK	Signal	Signal	PZ		
95 - P6.0	OA010	OA010			OA0O	96 - P6.1		
97 - P6.2	OA0I1	OA0I1	1		OA0O	ADC12 (internal)		
	DAC12_0OUT (internal)	DAC12_0OUT	OA0	OA0OUT				
	DAC12_1OUT (internal)	DAC12_1OUT						
3 - P6.4	OA1I0	OA1I0			OA1O	2 - P6.3		
13 - P5.0	OA1I1	OA1I1	1		OA1O	13- P5.0		
	DAC12_0OUT (internal)	DAC12_0OUT	OA1	OA1OUT	OA1O	ADC12 (internal)		
	DAC12_1OUT (internal)	DAC12_1OUT						
5 - P6.6	OA2I0	OA2I0			OA2O	4 - P6.5		
14 - P10.7	OA2I1	OA2I1	1		OA2O	14 - P10.7		
	DAC12_0OUT (internal)	DAC12_0OUT	OA2	OA2OUT	OA2O	ADC12 (internal)		
	DAC12_1OUT (internal)	DAC12_1OUT						



# peripheral file map

	PERIPHERALS WITH WORD ACCESS	i	
Watchdog+	Watchdog timer control	WDTCTL	0120h
Timer_B7	Capture/compare register 6	TBCCR6	019Eh
	Capture/compare register 5	TBCCR5	019Ch
	Capture/compare register 4	TBCCR4	019Ah
	Capture/compare register 3	TBCCR3	0198h
	Capture/compare register 2	TBCCR2	0196h
	Capture/compare register 1	TBCCR1	0194h
	Capture/compare register 0	TBCCR0	0192h
	Timer_B register	TBR	0190h
	Capture/compare control 6	TBCCTL6	018Eh
	Capture/compare control 5	TBCCTL5	018Ch
	Capture/compare control 4	TBCCTL4	018Ah
	Capture/compare control 3	TBCCTL3	0188h
	Capture/compare control 2	TBCCTL2	0186h
	Capture/compare control 1	TBCCTL1	0184h
	Capture/compare control 0	TBCCTL0	0182h
	Timer_B control	TBCTL	0180h
	Timer_B interrupt vector	TBIV	011Eh
Timer_A3	Capture/compare register 2	TACCR2	0176h
	Capture/compare register 1	TACCR1	0174h
	Capture/compare register 0	TACCR0	0172h
	Timer_A register	TAR	0170h
	Capture/compare control 2	TACCTL2	0166h
	Capture/compare control 1	TACCTL1	0164h
	Capture/compare control 0	TACCTL0	0162h
	Timer_A control	TACTL	0160h
	Timer_A interrupt vector	TAIV	012Eh
Hardware	Sum extend	SUMEXT	013Eh
Multiplier	Result high word	RESHI	013Ch
	Result low word	RESLO	013Ah
	Second operand	OP2	0138h
	Multiply signed + accumulate/operand1	MACS	0136h
	Multiply + accumulate/operand1	MAC	0134h
	Multiply signed/operand1	MPYS	0132h
	Multiply unsigned/operand1	MPY	0130h
Flash	Flash control 3	FCTL3	012Ch
(FG devices only)	Flash control 2	FCTL2	012Ah
	Flash control 1	FCTL1	0128h

	<u> </u>		
	PERIPHERALS WITH WORD ACCESS (CONT	INUED)	
DMA	DMA module control 0	DMACTL0	0122h
	DMA module control 1	DMACTL1	0124h
	DMA interrupt vector	DMAIV	0126h
DMA Channel 0	DMA channel 0 control	DMA0CTL	01D0h
	DMA channel 0 source address	DMA0SA	01D2h
	DMA channel 0 destination address	DMA0DA	01D6h
	DMA channel 0 transfer size	DMA0SZ	01DAh
DMA Channel 1	DMA channel 1 control	DMA1CTL	01DCh
	DMA channel 1 source address	DMA1SA	01DEh
	DMA channel 1 destination address	DMA1DA	01E2h
	DMA channel 1 transfer size	DMA1SZ	01E6h
DMA Channel 2	DMA channel 2 control	DMA2CTL	01E8h
	DMA channel 2 source address	DMA2SA	01EAh
	DMA channel 2 destination address	DMA2DA	01EEh
	DMA channel 2 transfer size	DMA2SZ	01F2h

	PERIPHERALS WITH WORD ACCESS (CONTIN	NUED)	
ADC12	Conversion memory 15	ADC12MEM15	015Eh
See also Peripherals	Conversion memory 14	ADC12MEM14	015Ch
With Byte Access	Conversion memory 13	ADC12MEM13	015Ah
	Conversion memory 12	ADC12MEM12	0158h
	Conversion memory 11	ADC12MEM11	0156h
	Conversion memory 10	ADC12MEM10	0154h
	Conversion memory 9	ADC12MEM9	0152h
	Conversion memory 8	ADC12MEM8	0150h
	Conversion memory 7	ADC12MEM7	014Eh
	Conversion memory 6	ADC12MEM6	014Ch
	Conversion memory 5	ADC12MEM5	014Ah
	Conversion memory 4	ADC12MEM4	0148h
	Conversion memory 3	ADC12MEM3	0146h
	Conversion memory 2	ADC12MEM2	0144h
	Conversion memory 1	ADC12MEM1	0142h
	Conversion memory 0	ADC12MEM0	0140h
	Interrupt-vector-word register	ADC12IV	01A8h
	Inerrupt-enable register	ADC12IE	01A6h
	Inerrupt-flag register	ADC12IFG	01A4h
	Control register 1	ADC12CTL1	01A2h
	Control register 0	ADC12CTL0	01A0h
DAC12	DAC12_1 data	DAC12_1DAT	01CAh
	DAC12_1 control	DAC12_1CTL	01C2h
	DAC12_0 data	DAC12_0DAT	01C8h
	DAC12_0 control	DAC12_0CTL	01C0h
Port PA	Port PA selection	PASEL	03Eh
	Port PA direction	PADIR	03Ch
	Port PA output	PAOUT	03Ah
	Port PA input	PAIN	038h
Port PB	Port PB selection	PBSEL	00Eh
	Port PB direction	PBDIR	00Ch
	Port PB output	PBOUT	00Ah
	Port PB input	PBIN	008h

PERIPHERALS WITH BYTE ACCESS						
OA2	Operational Amplifier 2 control register 1	OA2CTL1	0C5h			
	Operational Amplifier 2 control register 0	OA2CTL0	0C4h			
OA1	Operational Amplifier 1 control register 1	OA1CTL1	0C3h			
	Operational Amplifier 1 control register 0	OA1CTL0	0C2h			
OA0	Operational Amplifier 0 control register 1	OA0CTL1	0C1h			
	Operational Amplifier 0 control register 0	OA0CTL0	0C0h			
LCD_A	LCD Voltage Control 1	LCDAVCTL1	0AFh			
	LCD Voltage Control 0	LCDAVCTL0	0AEh			
	LCD Voltage Port Control 1	LCDAPCTL1	0ADh			
	LCD Voltage Port Control 0	LCDAPCTL0	0ACh			
	LCD memory 20	LCDM20	0A4h			
	:	:	:			
	LCD memory 16	LCDM16	0A0h			
	LCD memory 15	LCDM15	09Fh			
	:	:	:			
	LCD memory 1	LCDM1	091h			
150/0	LCD control and mode	LCDCTL	090h			
ADC12 (Memory control	ADC memory-control register 15	ADC12MCTL15	08Fh			
registers require byte	ADC memory-control register 14	ADC12MCTL14	08Eh			
access)	ADC memory-control register 13	ADC12MCTL13	08Dh			
	ADC memory-control register 12	ADC12MCTL12	08Ch			
	ADC memory-control register 11	ADC12MCTL11	08Bh			
	ADC memory-control register 10	ADC12MCTL10	08Ah			
	ADC memory-control register 9	ADC12MCTL9	089h			
	ADC memory-control register 8	ADC12MCTL8	088h			
	ADC memory-control register 7	ADC12MCTL7	087h			
	ADC memory-control register 6	ADC12MCTL6	086h			
	ADC memory-control register 5	ADC12MCTL5	085h			
	ADC memory-control register 4	ADC12MCTL4	084h			
	ADC memory-control register 3	ADC12MCTL3	083h			
	ADC memory-control register 2	ADC12MCTL2	082h			
	ADC memory-control register 1	ADC12MCTL1	081h			
	ADC memory-control register 0	ADC12MCTL0	080h			
USART1	Transmit buffer	U1TXBUF	07Fh			
	Receive buffer	U1RXBUF	07Eh			
	Baud rate	U1BR1	07Dh			
	Baud rate	U1BR0	07Ch			
	Modulation control	U1MCTL	07Bh			
	Receive control	U1RCTL	07Ah			
	Transmit control	U1TCTL	079h			
	USART control	U1CTL	078h			



	PERIPHERALS WITH BYTE ACCESS (CONTIN	UED)	
USCI	USCI I2C Slave Address	UCBI2CSA	011Ah
	USCI I2C Own Address	UCBI2COA	0118h
	USCI Synchronous Transmit Buffer	UCBTXBUF	06Fh
	USCI Synchronous Receive Buffer	UCBRXBUF	06Eh
	USCI Synchronous Status	UCBSTAT	06Dh
	USCI I2C Interrupt Enable	UCBI2CIE	06Ch
	USCI Synchronous Bit Rate 1	UCBBR1	06Bh
	USCI Synchronous Bit Rate 0	UCBBR0	06Ah
	USCI Synchronous Control 1	UCBCTL1	069h
	USCI Synchronous Control 0	UCBCTL0	068h
	USCI Transmit Buffer	UCATXBUF	067h
	USCI Receive Buffer	UCARXBUF	066h
	USCI Status	UCASTAT	065h
	USCI Modulation Control	UCAMCTL	064h
	USCI Baud Rate 1	UCABR1	063h
	USCI Baud Rate 0	UCABR0	062h
	USCI Control 1	UCACTL1	061h
	USCI Control 0	UCACTL0	060h
	USCI IrDA Receive Control	UCAIRRCTL	05Fh
	USCI IrDA Transmit Control	UCAIRTCTL	05Eh
	USCI LIN Control	UCAABCTL	05Dh
Comparator_A	Comparator_A port disable	CAPD	05Bh
	Comparator_A control 2	CACTL2	05Ah
	Comparator_A control 1	CACTL1	059h
BrownOUT, SVS	SVS control register (Reset by brownout signal)	SVSCTL	056h
FLL+Clock	FLL+ Control 1	FLL_CTL1	054h
	FLL+ Control 0	FLL_CTL0	053h
	System clock frequency control	SCFQCTL	052h
	System clock frequency integrator	SCFI1	051h
	System clock frequency integrator	SCFI0	050h
RTC (Basic Timer 1)	Real Time Clock Year High Byte	RTCYEARH	04Fh
	Real Time Clock Year Low Byte	RTCYEARL	04Eh
	Real Time Clock Month	RTCMON	04Dh
	Real Time Clock Day of Month	RTCDAY	04Ch
	Basic Timer1 Counter 2	BTCNT2	047h
	Basic Timer1 Counter 1	BTCNT1	046h
	Real Time Counter 4	RTCNT4	045h
	(Real Time Clock Day of Week)	(RTCDOW)	
	Real Time Counter 3	RTCNT3	044h
	(Real Time Clock Hour)	(RTCHOUR)	
	Real Time Counter 2	RTCNT2	043h
	(Real Time Clock Minute)	(RTCMIN)	
	Real Time Counter 1	RTCNT1	042h
	(Real Time Clock Second)	(RTCSEC)	
	Real Time Clock Control	RTCCTL	041h
	Basic Timer1 Control	BTCTL	040h



	PERIPHERALS WITH BYTE ACCESS	(CONTINUED)	
Port P10	Port P10 selection	P10SEL	00Fh
	Port P10 direction	P10DIR	00Dh
	Port P10 output	P10OUT	00Bh
	Port P10 input	P10IN	009h
Port P9	Port P9 selection	P9SEL	00Eh
	Port P9 direction	P9DIR	00Ch
	Port P9 output	P9OUT	00Ah
	Port P9 input	P9IN	008h
Port P8	Port P8 selection	P8SEL	03Fh
	Port P8 direction	P8DIR	03Dh
	Port P8 output	P8OUT	03Bh
	Port P8 input	P8IN	039h
Port P7	Port P7 selection	P7SEL	03Eh
	Port P7 direction	P7DIR	03Ch
	Port P7 output	P7OUT	03Ah
	Port P7 input	P7IN	038h
Port P6	Port P6 selection	P6SEL	037h
	Port P6 direction	P6DIR	036h
	Port P6 output	P6OUT	035h
	Port P6 input	P6IN	034h
Port P5	Port P5 selection	P5SEL	033h
	Port P5 direction	P5DIR	032h
	Port P5 output	P5OUT	031h
	Port P5 input	P5IN	030h
Port P4	Port P4 selection	P4SEL	01Fh
	Port P4 direction	P4DIR	01Eh
	Port P4 output	P4OUT	01Dh
	Port P4 input	P4IN	01Ch
Port P3	Port P3 selection	P3SEL	01Bh
	Port P3 direction	P3DIR	01Ah
	Port P3 output	P3OUT	019h
	Port P3 input	P3IN	018h
Port P2	Port P2 selection	P2SEL	02Eh
	Port P2 interrupt enable	P2IE	02Dh
	Port P2 interrupt-edge select	P2IES	02Ch
	Port P2 interrupt flag	P2IFG	02Bh
	Port P2 direction	P2DIR	02Ah
	Port P2 output	P2OUT	029h
	Port P2 input	P2IN	028h
Port P1	Port P1 selection	P1SEL	026h
	Port P1 interrupt enable	P1IE	025h
	Port P1 interrupt-edge select	P1IES	024h
	Port P1 interrupt flag	P1IFG	023h
	Port P1 direction	P1DIR	022h
	Port P1 output	P1OUT	021h
	Port P1 input	P1IN	020h



# MSP430xG461x MIXED SIGNAL MICROCONTROLLER

SLAS508I - APRIL 2006 - REVISED MARCH 2011

PERIPHERALS WITH BYTE ACCESS (CONTINUED)					
Special functions	SFR module enable 2	ME2	005h		
	SFR module enable 1	ME1	004h		
	SFR interrupt flag 2	IFG2	003h		
	SFR interrupt flag 1	IFG1	002h		
	SFR interrupt enable 2	IE2	001h		
	SFR interrupt enable 1	IE1	000h		

# absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Voltage range applied at V <sub>CC</sub> to V	SS	
Voltage range applied to any pin (	see Note)	$\dots$ -0.3 V to V <sub>CC</sub> + 0.3 V
Diode current at any device termin	nal	±2 mA
Storage temperature range, T <sub>sta</sub> :	Unprogrammed device	–55°C to 150°C
- · · · · · · · · · · · · · · · · · · ·		40°C to 85°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions

			MIN	NOM	MAX	UNITS
Supply voltage during program exect $V_{CC}$ (AV <sub>CC</sub> = DV <sub>CC1/2</sub> = V <sub>CC</sub> )	Supply voltage during program execution (see Note 1), $V_{CC}$ (AV <sub>CC</sub> = DV <sub>CC1/2</sub> = V <sub>CC</sub> )		1.8		3.6	V
Supply voltage during flash memory programming (see Note 1), V <sub>CC</sub> (AV <sub>CC</sub> = DV <sub>CC1/2</sub> = V <sub>CC</sub> )		MSP430FG461x	2.7		3.6	V
Supply voltage during program exect SVS enabled and PORON = 1 (see N $V_{CC}$ (AV $_{CC}$ = DV $_{CC1/2}$ = $V_{CC}$ )		MSP430xG461x	2		3.6	V
Supply voltage (see Note 1), V <sub>SS</sub> (AV <sub>SS</sub> = DV <sub>SS1/2</sub> = V <sub>SS</sub> )			0		0	V
Operating free-air temperature range	, T <sub>A</sub>	MSP430xG461x	-40		85	°C
	LF selected, XTS_FLL = 0	Watch crystal		32.768		
LFXT1 crystal frequency, f <sub>(LFXT1)</sub> (see Note 2)	XT1 selected, XTS_FLL = 1	Ceramic resonator	450		8000	kHz
(366 14016 2)	XT1 selected, XTS_FLL = 1	Crystal	1000		8000	
VT0		Ceramic resonator	450		8000	1.11=
XT2 crystal frequency, f <sub>(XT2)</sub>		Crystal	1000		8000	kHz
Processor frequency (signal MCLK), f <sub>(System)</sub>		V <sub>CC</sub> = 1.8 V	DC		3.0	
		V <sub>CC</sub> = 2.0 V	DC	_	4.6	MHz
		V <sub>CC</sub> = 3.6 V	DC		8.0	

- NOTES: 1. It is recommended to power AV<sub>CC</sub> and DV<sub>CC</sub> from the same source. A maximum difference of 0.3 V between AV<sub>CC</sub> and DV<sub>CC</sub> can be tolerated during power up and operation.
  - The minimum operating supply voltage is defined according to the trip point where POR is going active by decreasing the supply voltage. POR is going inactive when the supply voltage is raised above the minimum supply voltage plus the hysteresis of the SVS circuitry.
  - 3. In LF mode, the LFXT1 oscillator requires a watch crystal. In XT1 mode, LFXT1 accepts a ceramic resonator or a crystal.

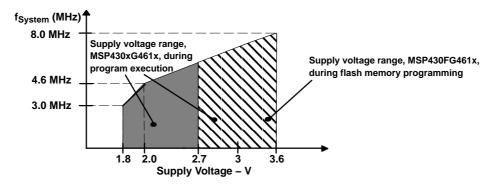


Figure 1. Frequency vs Supply Voltage, Typical Characteristic



NOTE: All voltages referenced to V<sub>SS</sub>. The JTAG fuse-blow voltage, V<sub>FB</sub>, is allowed to exceed the absolute maximum rating. The voltage is applied to the TDI/TCLK pin when blowing the JTAG fuse.

# electrical characteristics over recommended operating free-air temperature (unless otherwise noted)

# supply current into AV<sub>CC</sub> + DV<sub>CC</sub> excluding external current

	PARAMETER		TEST COND	OITIONS	MIN TYP	MAX	UNIT
	Active mode (see Note 1 and Note 4)			V <sub>CC</sub> = 2.2 V	280	370	
	$f_{(MCLK)} = f_{(SMCLK)} = 1 \text{ MHz},$ $f_{(ACLK)} = 32,768 \text{ Hz}$	CG461x	$T_A = -40$ °C to 85°C	V <sub>CC</sub> = 3 V	470	580	μΑ
I <sub>(AM)</sub>	XTS=0, SELM=(0,1)			V <sub>CC</sub> = 2.2 V	400	480	
	(FG461x: Program executes from flash)	FG461x	$T_A = -40^{\circ}C$ to $85^{\circ}C$	V <sub>CC</sub> = 3 V	600	740	μΑ
_	Low-power mode (LPM0)	xG461x		V <sub>CC</sub> = 2.2 V	45	70	_
(LPM0)	(see Note 1 and Note 4)		$T_A = -40^{\circ}C$ to $85^{\circ}C$	V <sub>CC</sub> = 3 V	75	110	μΑ
I <sub>(LPM2)</sub>	Low-power mode (LPM2), $f_{(MCLK)} = f_{(SMCLK)} = 0 \text{ MHz},$		$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$	V <sub>CC</sub> = 2.2 V	11	20	μА
·(LFIVIZ)	f <sub>(ACLK)</sub> = 32,768 Hz, SCG0 = 0 (see No Note 4)	te 2 and		$V_{CC} = 3 V$	17	24	, p
			T <sub>A</sub> = −40°C		1.3	4.0	
	Low-power mode (LPM3) $f_{(MCLK)} = f_{(SMCLK)} = 0 \text{ MHz},$		T <sub>A</sub> = 25°C	٦,, ۵,,,	1.3	4.0	
	$f_{(ACLK)} = 32,768 \text{ Hz}, SCG0 = 1$		T <sub>A</sub> = 60°C	$V_{CC} = 2.2 \text{ V}$	2.22	6.5	
	Basic Timer1 enabled, ACLK selected LCD_A enabled, LCDCPEN = 0;		$T_A = 85^{\circ}C$		6.5	15.0	
I <sub>(LPM3)</sub>	(static mode; f <sub>LCD</sub> = f <sub>(ACLK)</sub> /32) (see Note 2 and Note 3 and Note 4)		$T_A = -40^{\circ}C$		1.9	5.0	μΑ
			T <sub>A</sub> = 25°C	V <sub>CC</sub> = 3 V	1.9	5.0	
			$T_A = 60^{\circ}C$	1,00-2,	2.5	7.5	
		T <sub>A</sub> = 85°C		7.5	18.0		
	Lawrence and (LDMC)		T <sub>A</sub> = −40°C		1.5	5.5	
	Low-power mode (LPM3) $f_{(MCLK)} = f_{(SMCLK)} = 0 \text{ MHz},$		T <sub>A</sub> = 25°C	V <sub>CC</sub> = 2.2 V	1.5	5.5	
	$f_{(ACLK)} = 32,768 \text{ Hz}, SCG0 = 1$		T <sub>A</sub> = 60°C		2.8	7.0	
	Basic Timer1 enabled, ACLK selected		T <sub>A</sub> = 85°C	1	7.2	17.0	1 .
(LPM3)	LCD_A enabled, LCDCPEN = 0; $(4-\text{mux mode}; f_{\text{LCD}} = f_{\text{(ACLK)}}/32)$		$T_A = -40^{\circ}C$		2.5	6.5	μΑ
	(see Note 2 and Note 3 and Note 4)		T <sub>A</sub> = 25°C	T.,	2.5	6.5	
			T <sub>A</sub> = 60°C	$V_{CC} = 3 V$	3.2	8.0	
			T <sub>A</sub> = 85°C		8.5	20.0	
			T <sub>A</sub> = −40°C		0.13	1.0	
			T <sub>A</sub> = 25°C	7	0.22	1.0	
	Low-power mode (LPM4)		T <sub>A</sub> = 60°C	$V_{CC} = 2.2 \text{ V}$	0.9	2.5	
	$f_{\text{(MCLK)}} = 0 \text{ MHz}, f_{\text{(SMCLK)}} = 0 \text{ MHz},$		T <sub>A</sub> = 85°C	7	4.3	12.5	] .
I <sub>(LPM4)</sub>	$f_{(ACLK)} = 0 \text{ Hz}, SCG0 = 1$		$T_A = -40^{\circ}C$		0.13	1.6	μΑ
	(see Note 2 and Note 4)		T <sub>A</sub> = 25°C	٦.,	0.3	1.6	
			T <sub>A</sub> = 60°C	$V_{CC} = 3 V$	1.1	3.0	
			T <sub>A</sub> = 85°C		5.0	15.0	

NOTES: 1. Timer\_B is clocked by  $f_{(DCOCLK)} = f_{(DCO)} = 1$  MHz. All inputs are tied to 0 V or to  $V_{CC}$ . Outputs do not source or sink any current.

- 2. All inputs are tied to 0 V or to  $V_{CC}$ . Outputs do not source or sink any current.
- 3. The LPM3 currents are characterized with a Micro Crystal CC4V-T1A (9 pF) crystal and OSCCAPx = 1h.
- 4. Current for brownout included.

Current consumption of active mode versus system frequency, F version:

$$I_{(AM)} = I_{(AM)} [1 \text{ MHz}] \times f_{(System)} [MHz]$$

Current consumption of active mode versus supply voltage, F version:

$$I_{(AM)} = I_{(AM)[3\ V]} + 200\ \mu\text{A/V} \times (V_{CC} - 3\ V)$$



# electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

# Schmitt-trigger inputs – Ports P1 to P10, RST/NMI, JTAG (TCK, TMS, TDI/TCLK, TDO/TDI)

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
,,	Decision are in a law at three held welfer as	V <sub>CC</sub> = 2.2 V	1.1	1.55	V
VIT+	V <sub>IT+</sub> Positive-going input threshold voltage	V <sub>CC</sub> = 3 V	1.5	1.98	V
	No notive as in a input three held voltage	V <sub>CC</sub> = 2.2 V	0.4	0.9	V
VIT-	V <sub>IT</sub> . Negative-going input threshold voltage	V <sub>CC</sub> = 3 V	0.9	1.3	V
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Input valtage bystereoic (V V V	V <sub>CC</sub> = 2.2 V	0.3	1.1	V
Vhys	V <sub>hys</sub> Input voltage hysteresis (V <sub>IT+</sub> – V <sub>IT-</sub> )	V <sub>CC</sub> = 3 V	0.5	1	] v

#### inputs Px.x, TAx, TBx

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT	
	External interrupt timing	Port P1, P2: P1.x to P2.x, external trigger signal		62			20	
t <sub>(int)</sub>	External interrupt timing	for the interrupt flag, (see Note 1)	3 V	50			ns	
	Timer_A, Timer_B capture TA0, TA1, TA2		2.2 V	62				
<sup>l</sup> (cap)	t(cap) timing	TB0, TB1, TB2, TB3, TB4, TB5, TB6	3 V	50			ns	
f <sub>(TAext)</sub>	Timer_A, Timer_B clock	TACLK TROLK INCLKS to a few	2.2 V			8	MHz	
f <sub>(TBext)</sub>	frequency externally applied to pin	TACLK, TBCLK, INCLK: $t_{(H)} = t_{(L)}$	3 V			10	IVITIZ	
f <sub>(TAint)</sub>	Timer_A, Timer_B clock	SMCLK or ACLK signal calcuted	2.2 V			8	MHz	
f <sub>(TBint)</sub>	frequency	SMCLK or ACLK signal selected	3 V			10	IVII <sup>-1</sup> Z	

NOTES: 1. The external signal sets the interrupt flag every time the minimum  $t_{(int)}$  parameters are met. It may be set even with trigger signals shorter than  $t_{(int)}$ .

# leakage current - Ports P1 to P10 (see Note 1)

	PARAMETER		TEST CONDITION	S	MIN	TYP	MAX	UNIT
I <sub>lkg(Px.y)</sub>	Leakage current	Port Px	$V_{(Px,y)}$ (see Note 2) (1 \le x \le 10, 0 \le y \le 7)	V <sub>CC</sub> = 2.2 V/3 V			±50	nA

NOTES: 1. The leakage current is measured with V<sub>SS</sub> or V<sub>CC</sub> applied to the corresponding pin(s), unless otherwise noted.

2. The port pin must be selected as input.

# electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

# outputs - Ports P1 to P10

	PARAMETER	TEST	CONDITIONS		MIN	TYP N	IAX	UNIT
		$I_{OH(max)} = -1.5 \text{ mA},$	$V_{CC} = 2.2 \text{ V},$	See Note 1	V <sub>CC</sub> -0.25	,	$V_{CC}$	
I Value Hinn-level output voitage	$I_{OH(max)} = -6 \text{ mA},$	$V_{CC} = 2.2 \text{ V},$	See Note 2	V <sub>CC</sub> -0.6	,	$V_{CC}$	V	
	$I_{OH(max)} = -1.5 \text{ mA},$	$V_{CC} = 3 V$ ,	See Note 1	V <sub>CC</sub> -0.25	,	$V_{CC}$	V	
		$I_{OH(max)} = -6 \text{ mA},$	$V_{CC} = 3 V$ ,	See Note 2	V <sub>CC</sub> -0.6	,	V <sub>CC</sub>	
		$I_{OL(max)} = 1.5 \text{ mA},$	$V_{CC} = 2.2 \text{ V},$	See Note 1	$V_{SS}$	V <sub>SS</sub> +0	0.25	
V	Low-level output voltage	$I_{OL(max)} = 6 \text{ mA},$	$V_{CC} = 2.2 \text{ V},$	See Note 2	$V_{SS}$	V <sub>SS</sub> -	+0.6	V
V <sub>OL</sub> Low-level output voltage	$I_{OL(max)} = 1.5 \text{ mA},$	$V_{CC} = 3 V$ ,	See Note 1	$V_{SS}$	V <sub>SS</sub> +0	0.25	V	
		$I_{OL(max)} = 6 \text{ mA},$	$V_{CC} = 3 V$ ,	See Note 2	$V_{SS}$	V <sub>SS</sub> -	+0.6	

NOTES: 1. The maximum total current,  $I_{OH(max)}$  and  $I_{OL(max)}$ , for all outputs combined, should not exceed  $\pm 12$  mA to satisfy the maximum specified voltage drop.

2. The maximum total current, I<sub>OH(max)</sub> and I<sub>OL(max)</sub>, for all outputs combined, should not exceed ±48 mA to satisfy the maximum specified voltage drop.

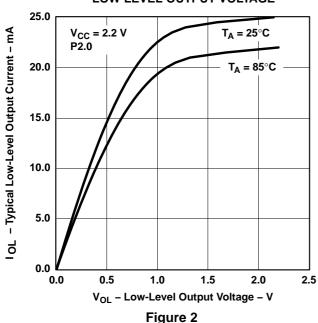
#### output frequency

	PARAMETER	TEST	TEST CONDITIONS		TYP	MAX	UNIT
,	$(1 \le x \le 10, \ 0 \le y \le 7)$	$C_L = 20 \text{ pF},$	V <sub>CC</sub> = 2.2 V	DC		10	MHz
f <sub>(Px.y)</sub>		$I_L = \pm 1.5 \text{ mA}$	V <sub>CC</sub> = 3 V	DC		12	MHz
f <sub>(MCLK)</sub>	P1.1/TA0/MCLK,		V 00V			40	NAL 1-
f <sub>(SMCLK)</sub>	P1.4/TBCLK/SMCLK,	C <sub>L</sub> = 20 pF	$V_{CC} = 2.2 \text{ V}$			10	MHz
f <sub>(ACLK)</sub>	P1.5/TACLK/ACLK		V <sub>CC</sub> = 3 V	DC		12	MHz
		P1.5/TACLK/ACLK, C <sub>L</sub> = 20 pF V <sub>CC</sub> = 2.2 V / 3 V	$f_{(ACLK)} = f_{(LFXT1)} = f_{(XT1)}$	40%		60%	
			$f_{(ACLK)} = f_{(LFXT1)} = f_{(LF)}$	30%		70%	
			$f_{(ACLK)} = f_{(LFXT1)}$		50%		
		P1.1/TA0/MCLK,	$f_{(MCLK)} = f_{(XT1)}$	40%		60%	
t <sub>(Xdc)</sub>	Duty cycle of output frequency	$C_L = 20 \text{ pF},$ $V_{CC} = 2.2 \text{ V} / 3 \text{ V}$	$f_{(MCLK)} = f_{(DCOCLK)}$	50%– 15 ns	50%	50%+ 15 ns	
		P1.4/TBCLK/SMCLK,	$f_{(SMCLK)} = f_{(XT2)}$	40%		60%	
		$C_L = 20 \text{ pF},$ $V_{CC} = 2.2 \text{ V} / 3 \text{ V}$	$f_{(SMCLK)} = f_{(DCOCLK)}$	50%– 15 ns	50%	50%+ 15 ns	

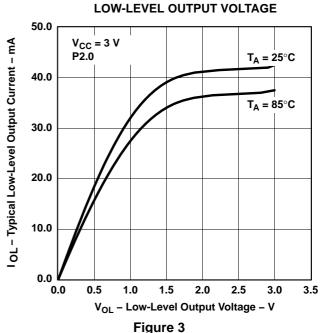
electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

typical characteristics - outputs

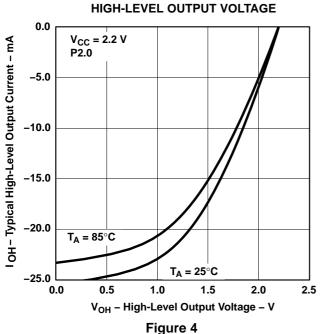
# TYPICAL LOW-LEVEL OUTPUT CURRENT vs LOW-LEVEL OUTPUT VOLTAGE



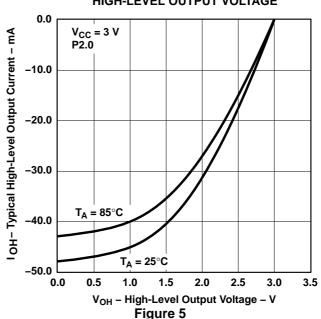
# TYPICAL LOW-LEVEL OUTPUT CURRENT VS



# TYPICAL HIGH-LEVEL OUTPUT CURRENT vs



# TYPICAL HIGH-LEVEL OUTPUT CURRENT vs HIGH-LEVEL OUTPUT VOLTAGE





# MSP430xG461x MIXED SIGNAL MICROCONTROLLER

SLAS508I - APRIL 2006 - REVISED MARCH 2011

# electrical characteristics over recommended operating free-air temperature (unless otherwise noted)

# wake-up LPM3

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
		f = 1 MHz				6	
t <sub>d(LPM3)</sub>	Delay time	f = 2 MHz	V <sub>CC</sub> = 2.2 V/3 V			6	μs
		f = 3 MHz				6	

# **RAM**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VRAMh	CPU halted (see Note 1)	1.6	•	•	V

NOTE 1: This parameter defines the minimum supply voltage when the data in program memory RAM remain unchanged. No program execution should take place during this supply voltage condition.

# electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

#### LCD\_A

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
V <sub>CC(LCD)</sub>	Supply voltage (see Note 2)	Charge pump enabled (LCDCPEN = 1; VLCDx > 0000)		2.2		3.6	V
I <sub>CC(LCD)</sub>	Supply current (see Note 2)	$\begin{split} &V_{LCD(typ)}\text{=3 V; LCDCPEN = 1,}\\ &VLCDx\text{= 1000; all segments on,}\\ &f_{LCD}\text{=}f_{ACLK}/32,\\ &\text{no LCD connected (see Note 4)}\\ &T_{A}=25^{\circ}\text{C} \end{split}$	2.2 V		3		μΑ
C <sub>LCD</sub>	Capacitor on LCDCAP (see Note 1 and Note 3)	Charge pump enabled (LCDCPEN = 1; VLCDx > 0000)		4.7			μF
f <sub>LCD</sub>	LCD frequency					1.1	kHz
V <sub>LCD</sub>	LCD voltage (see Note 3)	VLCDx = 0000			$V_{CC}$		V
		VLCDx = 0001			2.60		
		VLCDx = 0010			2.66		
		VLCDx = 0011			2.72		
		VLCDx = 0100			2.78		
		VLCDx = 0101			2.84		
		VLCDx = 0110			2.90		
		VLCDx = 0111			2.96		
		VLCDx = 1000			3.02		
		VLCDx = 1001			3.08		
		VLCDx = 1010			3.14		
		VLCDx = 1011			3.20		
		VLCDx = 1100			3.26		
		VLCDx = 1101			3.32		
		VLCDx = 1110			3.38		
		VLCDx = 1111			3.44	3.60	
R <sub>LCD</sub>	LCD driver output impedance	$V_{LCD}$ =3 V; CPEN = 1; VLCDx = 1000, $I_{LOAD}$ = $\pm$ 10 μA	2.2 V			10	kΩ

NOTES: 1. Enabling the internal charge pump with an external capacitor smaller than the minimum specified might damage the device.

4. Connecting an actual display will increase the current consumption depending on the size of the LCD.



<sup>2.</sup> Refer to the supply current specifications I<sub>(LPM3)</sub> for additional current specifications with the LCD\_A module active.

Segments S0 through S3 are disabled when the LCD charge pump feature is enabled (LCDCPEN = 1) and cannot be used together
with the LCD charge pump. In addition, when using segments S0 through S3 with an external LCD voltage supply, V<sub>LCD</sub> ≤ AV<sub>CC</sub>.

# electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

## Comparator\_A (see Note 1)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
		CAON 4 CARCEL O CAREE O	V <sub>CC</sub> = 2.2 V		25	40	
I(CC)		CAON=1, CARSEL=0, CAREF=0	V <sub>CC</sub> = 3 V		45	60	μΑ
		CAON=1, CARSEL=0, CAREF=1/2/3,	V <sub>CC</sub> = 2.2 V		30	50	
I(Refladder/R	tefDiode)	No load at P1.6/CA0 and P1.7/CA1	V <sub>CC</sub> = 3 V		45	71	μΑ
V <sub>(Ref025)</sub>	Voltage @ 0.25 V <sub>CC</sub> node	PCA0=1, CARSEL=1, CAREF=1, No load at P1.6/CA0 and P1.7/CA1	V <sub>CC</sub> = 2.2 V / 3 V	0.23	0.24	0.25	
V <sub>(Ref050)</sub>	Voltage @ 0.5 V <sub>CC</sub> node	PCA0=1, CARSEL=1, CAREF=2, No load at P1.6/CA0 and P1.7/CA1	V <sub>CC</sub> = 2.2V / 3 V	0.47	0.48	0.5	
		PCA0=1, CARSEL=1, CAREF=3,	V <sub>CC</sub> = 2.2 V	390	480	540	
V <sub>(RefVT)</sub>		No load at P1.6/CA0 and P1.7/CA1; $T_A = 85^{\circ}C$	V <sub>CC</sub> = 3 V	400	490	550	mV
V <sub>IC</sub>	Common-mode input voltage range	CAON=1	V <sub>CC</sub> = 2.2 V / 3 V	0		V <sub>CC</sub> -1	٧
$V_p - V_S$	Offset voltage	See Note 2	VCC = 2.2 V / 3 V	-30		30	mV
$V_{hys}$	Input hysteresis	CAON = 1	$V_{CC} = 2.2 \text{ V} / 3 \text{ V}$	0	0.7	1.4	mV
		T <sub>A</sub> = 25°C,	V <sub>CC</sub> = 2.2 V	160	210	300	
		Overdrive 10 mV, without filter: CAF = 0	V <sub>CC</sub> = 3 V	80	150	240	ns
t(response LF	⊣)	T <sub>A</sub> = 25°C	V <sub>CC</sub> = 2.2 V	1.4	1.9	3.4	
		Overdrive 10 mV, with filter: CAF = 1	V <sub>CC</sub> = 3 V	0.9	1.5	2.6	μs
		T <sub>A</sub> = 25°C	$V_{CC} = 2.2 \text{ V}$	130	210	300	
		Overdrive 10 mV, without filter: CAF = 0	V <sub>CC</sub> = 3 V	80	150	240	ns
t(response HI	L)	T <sub>A</sub> = 25°C,	V <sub>CC</sub> = 2.2 V	1.4	1.9	3.4	
		Overdrive 10 mV, with filter: CAF = 1	V <sub>CC</sub> = 3 V	0.9	1.5	2.6	μS

NOTES: 1. The leakage current for the Comparator\_A terminals is identical to I<sub>lkg(Px.x)</sub> specification.

<sup>2.</sup> The input offset voltage can be cancelled by using the CAEX bit to invert the Comparator\_A inputs on successive measurements. The two successive measurements are then summed together.

# typical characteristics

# **REFERENCE VOLTAGE** FREE-AIR TEMPERATURE **Typical**

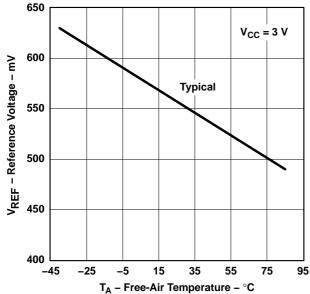


Figure 6. V<sub>(RefVT)</sub> vs Temperature

# **REFERENCE VOLTAGE** FREE-AIR TEMPERATURE

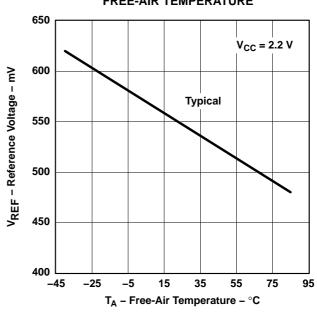


Figure 7. V<sub>(RefVT)</sub> vs Temperature

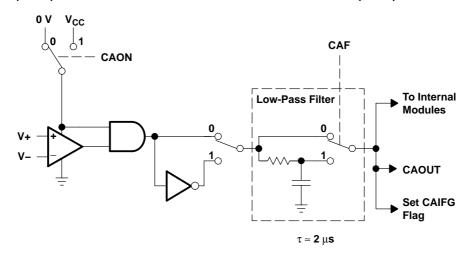


Figure 8. Block Diagram of Comparator\_A Module

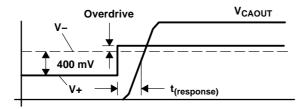


Figure 9. Overdrive Definition



#### POR/brownout reset (BOR) (see Note 1)

PAI	RAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>d(BOR)</sub>					2000	μs
V <sub>CC(start)</sub>		dV <sub>CC</sub> /dt ≤ 3 V/s (see Figure 10)		$0.7 \times V_{(B\_IT-)}$		V
V <sub>(B_IT-)</sub>	Brownout	dV <sub>CC</sub> /dt ≤ 3 V/s (see Figure 10 through Figure 12)			1.79	V
V <sub>hys(B_IT-)</sub>	(see Notes 2 and 3)	dV <sub>CC</sub> /dt ≤ 3 V/s (see Figure 10)	70	130	210	mV
t <sub>(reset)</sub>		Pulse length needed at $\overline{RST}/NMI$ pin to accepted reset internally, $V_{CC}$ = 2.2 V/3 V	2			μs

- NOTES: 1. The current consumption of the brownout module is already included in the I<sub>CC</sub> current consumption data.
  - 2. The voltage level  $V_{(B\_IT-)} + V_{hys(B\_IT-)}$  is  $\leq 1.89V$ .
  - 3. During power up, the CPU begins code execution following a period of t<sub>d(BOR)</sub> after V<sub>CC</sub> = V<sub>(B\_IT-)</sub> + V<sub>hys(B\_IT-)</sub>. The default FLL+ settings must not be changed until V<sub>CC</sub> ≥ V<sub>CC(min)</sub>, where V<sub>CC(min)</sub> is the minimum supply voltage for the desired operating frequency. See the *MSP430x4xx Family User's Guide* for more information on the brownout/SVS circuit.

#### typical characteristics

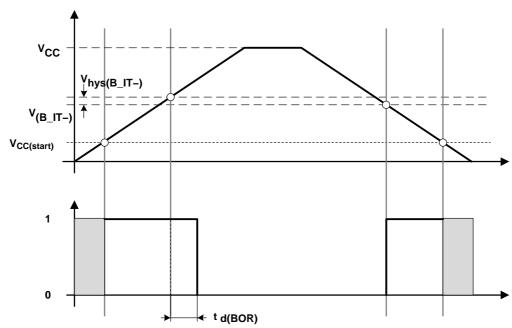


Figure 10. POR/Brownout Reset (BOR) vs Supply Voltage

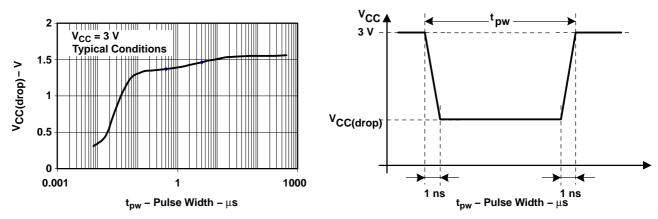


Figure 11. V<sub>CC(drop)</sub> Level With a Square Voltage Drop to Generate a POR/Brownout Signal



# typical characteristics (continued)

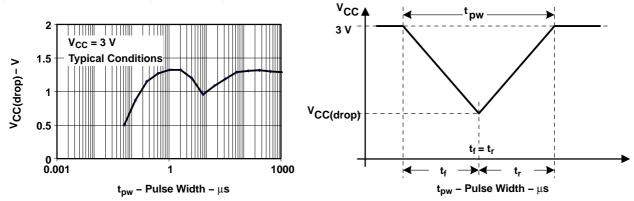


Figure 12. V<sub>CC(drop)</sub> Level With a Triangle Voltage Drop to Generate a POR/Brownout Signal

# electrical characteristics over recommended operating free-air temperature (unless otherwise noted)

## SVS (supply voltage supervisor/monitor) (see Note 1)

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
	dV <sub>CC</sub> /dt > 30 V/ms (see Figure 13)		5		150	
t(SVSR)	dV <sub>CC</sub> /dt ≤ 30 V/ms			150 2000 150 300 12 1.55 1.7 120 155 -) V(\$SVS_IT-) x 0.016  20 1.9 2.05 2.1 2.23 2.2 2.35 2.3 2.46 2.4 2.58 2.5 2.69 2.65 2.84 2.8 2.97 2.9 3.10 3.05 3.26 3.2 3.39 3.35 3.58† 3.5 3.73† 3.7† 3.96† 1.2 1.3	μs	
t <sub>d(SVSon)</sub>	SVS on, switch from VLD = 0 to VLD $\neq$ 0, V <sub>CC</sub> = 3 V			150	300	μs
t <sub>settle</sub>	VLD ≠ 0 <sup>‡</sup>				12	μs
V <sub>(SVSstart)</sub>	VLD ≠ 0, V <sub>CC</sub> /dt ≤ 3 V/s (see Figure 13)			1.55	1.7	V
		VLD = 1	70	120	155	mV
V <sub>hys(SVS_IT-)</sub>	V <sub>CC</sub> /dt ≤ 3 V/s (see Figure 13)	VLD = 2 14	V <sub>(SVS_IT-)</sub> x 0.001		V <sub>(SVS_IT-)</sub> x 0.016	
, , _ ,	$V_{CC}/dt \le 3$ V/s (see Figure 13), external voltage applied on A7	VLD = 15	4.4		x 0.016 20 2.05 2.23 2.35	mV
		VLD = 1	1.8	1.9	2.05	
		VLD = 2	1.94	2.1	2.23	1
		VLD = 3	2.05	2.2	2.35	1
		VLD = 4	2.14	2.3	2.46	<u>]</u>
		VLD = 5	2.24	2.4	2.58	
V <sub>(SVS_IT-)</sub>		VLD = 6	2.33	2.5	2.69	
	V <sub>CC</sub> /dt ≤ 3 V/s (see Figure 13)	VLD = 7	2.46	2.65	2.84	
V(O)(O) IT \	ACC/or ≥ 2 A/2 (see Lighte 12)	VLD = 8	2.58	2.8	150 2000 300 12 1.7 155 V(\$V\$_IT-) x 0.016 20 2.05 2.23 2.35 2.46 2.58 2.69 2.84 2.97 3.10 3.26 3.39 3.58† 3.73† 3.96†	V
v (SVS_II-)		VLD = 9	2.69	2.9		]
		VLD = 10	2.83	3.05	3.26	]
		VLD = 11	2.94	3.2	3.39	
		VLD = 12	3.11	3.35	3.58 <sup>†</sup>	]
		VLD = 13	3.24	3.5	3.73 <sup>†</sup>	]
		3.96 <sup>†</sup>	]			
	$V_{CC}/dt \le 3$ V/s (see Figure 13), external voltage applied on A7	VLD = 15	1.1	1.2	1.3	
I <sub>CC(SVS)</sub> (see Note 1)	VLD ≠ 0, V <sub>CC</sub> = 2.2 V/3 V			10	15	μА

<sup>†</sup> The recommended operating voltage range is limited to 3.6 V.

NOTE 1: The current consumption of the SVS module is not included in the  $I_{CC}$  current consumption data.



<sup>&</sup>lt;sup>‡</sup> t<sub>settle</sub> is the settling time that the comparator o/p needs to have a stable level after VLD is switched VLD ≠ 0 to a different VLD value somewhere between 2 and 15. The overdrive is assumed to be > 50 mV.



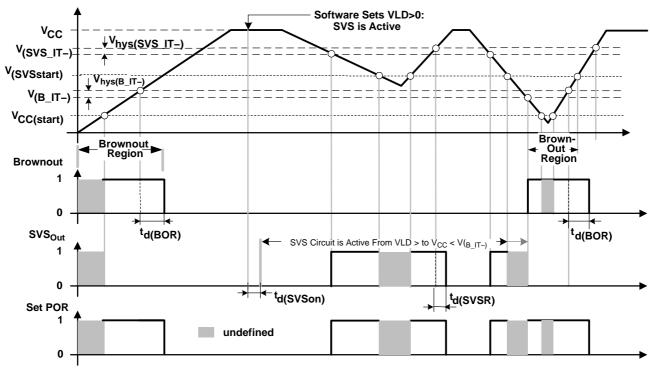


Figure 13. SVS Reset (SVSR) vs Supply Voltage

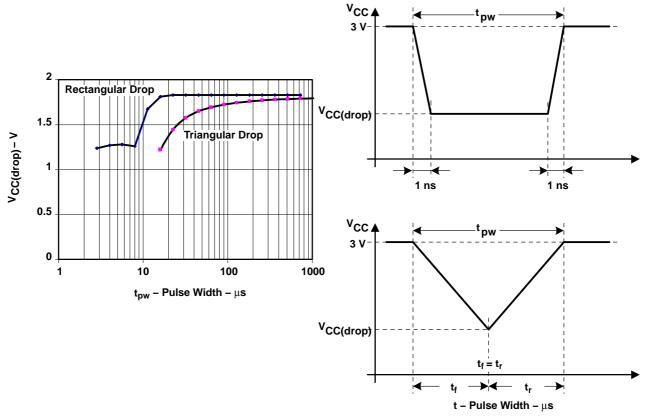


Figure 14. V<sub>CC(drop)</sub> With a Square Voltage Drop and a Triangle Voltage Drop to Generate an SVS Signal



## DCO

PARAMETER	TEST CONDITIONS	v <sub>cc</sub>	MIN	TYP	MAX	UNIT
f <sub>(DCOCLK)</sub>	N <sub>(DCO)</sub> =01Eh, FN_8=FN_4=FN_3=FN_2=0, D = 2; DCOPLUS= 0	2.2 V/3 V		1		MHz
,	EN A EN A EN A EN A PAGENTA A	2.2 V	0.3	0.65	1.25	
f <sub>(DCO=2)</sub>	FN_8=FN_4=FN_3=FN_2=0 ; DCOPLUS = 1	3 V	0.3	0.7	1.3	MHz
	EN O EN 4 EN O EN O O DOORING 4	2.2 V	2.5	5.6	10.5	N# 1-
f <sub>(DCO=27)</sub>	FN_8=FN_4=FN_3=FN_2=0; DCOPLUS = 1	3 V	2.7	6.1	11.3	MHz
	EN 9 EN 4 EN 2 9 EN 9 4 DOODLUG 4	2.2 V	0.7	1.3	2.3	N41 I-
f <sub>(DCO=2)</sub>	FN_8=FN_4=FN_3=0, FN_2=1; DCOPLUS = 1	3 V	0.8	1.5	2.5	MHz
	EN O EN A EN O O EN O A DOODING A	2.2 V	5.7	10.8	18	<b>M</b> 1-
f <sub>(DCO=27)</sub>	FN_8=FN_4=FN_3=0, FN_2=1; DCOPLUS = 1	3 V	6.5	12.1	20	MHz
,	EN O EN A O EN O A EN O DOORING A	2.2 V	1.2	2	3	
f <sub>(DCO=2)</sub>	FN_8=FN_4=0, FN_3= 1, FN_2=x; DCOPLUS = 1	3 V	1.3	2.2	3.5	MHz
	EN O EN 4 O EN O 4 EN O 11 DOORING 4	2.2 V	9	15.5	25	N# 1-
f <sub>(DCO=27)</sub>	FN_8=FN_4=0, FN_3= 1, FN_2=x; DCOPLUS = 1	3 V	10.3	17.9	28.5	MHz
,	FN_8=0, FN_4= 1, FN_3= FN_2=x; DCOPLUS = 1	2.2 V	1.8	2.8	4.2	
f <sub>(DCO=2)</sub>		3 V	2.1	3.4	5.2	MHz
	EN O O EN 4 4 EN O EN O DOODLIJO 4	2.2 V	13.5	21.5	33	NAL 1-
f <sub>(DCO=27)</sub>	FN_8=0, FN_4=1, FN_3= FN_2=x; DCOPLUS = 1	3 V	16	26.6	41	MHz
,	EN CA EN A EN C EN C POORUM	2.2 V	2.8	4.2	6.2	
f <sub>(DCO=2)</sub>	FN_8=1, FN_4=FN_3=FN_2=x; DCOPLUS = 1	3 V	4.2	6.3	9.2	MHz
,	EN OAFNA FNO FNO POORING	2.2 V	21	32	46	
f <sub>(DCO=27)</sub>	FN_8=1,FN_4=FN_3=FN_2=x; DCOPLUS = 1	3 V	30	46	70	MHz
	Step size between adjacent DCO taps:	1 < TAP ≤ 20	1.06		1.11	
S <sub>n</sub>	$S_n = f_{DCO(Tap n+1)} / f_{DCO(Tap n)}$ (see Figure 16 for taps 21 to 27)	TAP = 27	1.07		1.17	
5	Temperature drift, N <sub>(DCO)</sub> = 01Eh, FN_8=FN_4=FN_3=FN_2=0	2.2 V	-0.2	-0.3	-0.4	N 10 O
D <sub>t</sub>	D = 2; DCOPLUS = 0	3 V	-0.2	-0.3	-0.4	%/°C
D <sub>V</sub>	Drift with $V_{CC}$ variation, $N_{(DCO)} = 01Eh$ , $FN_8 = FN_4 = FN_3 = FN_2 = 0$ D = 2; DCOPLUS = 0		0	5	15	%/V

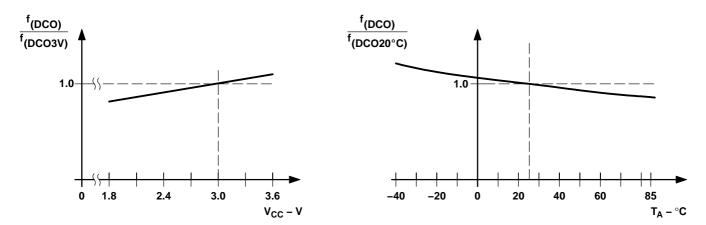


Figure 15. DCO Frequency vs Supply Voltage  $V_{\text{CC}}$  and vs Ambient Temperature



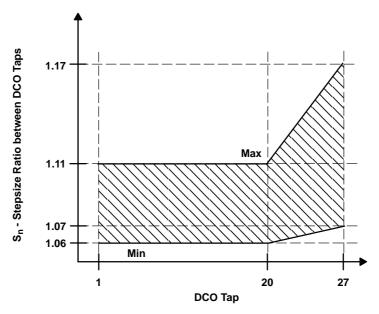


Figure 16. DCO Tap Step Size

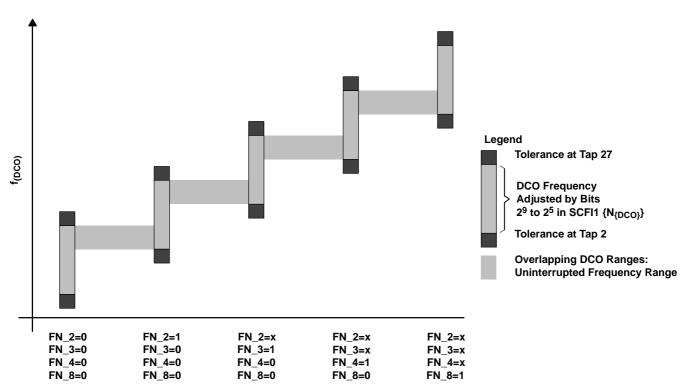


Figure 17. Five Overlapping DCO Ranges Controlled by FN\_x Bits



# electrical characteristics over recommended operating free-air temperature (unless otherwise noted)

# crystal oscillator, LFXT1 oscillator (see Notes 1 and 2)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
		OSCCAPx = 0h, V <sub>CC</sub> = 2.2 V / 3 V	0					
C <sub>XIN</sub>	Integrated input capacitance	OSCCAPx = 1h, V <sub>CC</sub> = 2.2 V / 3 V		10				
	(see Note 4)	OSCCAPx = 2h, V <sub>CC</sub> = 2.2 V / 3 V		14		pF		
		OSCCAPx = 3h, V <sub>CC</sub> = 2.2 V / 3 V		18				
		OSCCAPx = 0h, V <sub>CC</sub> = 2.2 V / 3 V	0					
	Integrated output capacitance	OSCCAPx = 1h, V <sub>CC</sub> = 2.2 V / 3 V		10				
C <sub>XOUT</sub>	(see Note 4)	OSCCAPx = 2h, V <sub>CC</sub> = 2.2 V / 3 V		14		pF		
		OSCCAPx = 3h, V <sub>CC</sub> = 2.2 V / 3 V		18				
V <sub>IL</sub>	Lawrence of MIN	V 00 V/0 V (see New 0)	V <sub>SS</sub>		0.2×V <sub>CC</sub>	.,		
V <sub>IH</sub>	Input levels at XIN	out levels at XIN $V_{CC} = 2.2 \text{ V/3 V (see Note 3)}$			V <sub>CC</sub>	V		

- NOTES: 1. The parasitic capacitance from the package and board may be estimated to be 2 pF. The effective load capacitor for the crystal is  $(C_{XIN} \times C_{XOUT}) / (C_{XIN} + C_{XOUT})$ . This is independent of XTS\_FLL.
  - 2. To improve EMI on the low-power LFXT1 oscillator, particularly in the LF mode (32 kHz), the following guidelines should be observed.
    - Keep the trace between the device and the crystal as short as possible.
    - Design a good ground plane around the oscillator pins.
    - Prevent crosstalk from other clock or data lines into oscillator pins XIN and XOUT.
    - Avoid running PCB traces underneath or adjacent to the XIN and XOUT pins.
    - Use assembly materials and praxis to avoid any parasitic load on the oscillator XIN and XOUT pins.
    - If conformal coating is used, ensure that it does not induce capacitive/resistive leakage between the oscillator pins.
    - Do not route the XOUT line to the JTAG header to support the serial programming adapter as shown in other documentation. This signal is no longer required for the serial programming adapter.
  - 3. Applies only when using an external logic-level clock source. XTS\_FLL must be set. Not applicable when using a crystal or resonator.
  - 4. External capacitance is recommended for precision real-time clock applications; OSCCAPx = 0h.

#### crystal oscillator, XT2 oscillator (see Note 1)

PARAMETER		TEST CONDITIONS	MIN	NOM MAX	UNIT
C <sub>XT2IN</sub>	Integrated input capacitance	V <sub>CC</sub> = 2.2 V/3 V		pF	
C <sub>XT2OUT</sub>	Integrated output capacitance	V <sub>CC</sub> = 2.2 V/3 V		pF	
V <sub>IL</sub>	Input levels at VTOIN	V = 2.2 V/2 V (and Note 2)	V <sub>SS</sub>	$0.2 \times V_{C}$	c V
V <sub>IH</sub>	Input levels at XT2IN	V <sub>CC</sub> = 2.2 V/3 V (see Note 2)	$0.8 \times V_{CC}$	$V_{CC}$	V

NOTES: 1. The oscillator needs capacitors at both terminals, with values specified by the crystal manufacturer.

2. Applies only when using an external logic-level clock source. Not applicable when using a crystal or resonator.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

## **USCI (UART mode)**

PARAMETER		TEST CONDITIONS	VCC	MIN	TYP	MAX	UNIT
f <sub>USCI</sub>	USCI input clock frequency	Internal: SMCLK, ACLK External: UCLK Duty Cycle = 50% ± 10%			f <sub>S</sub>	SYSTEM	MHz
f <sub>BITCLK</sub>	BITCLK clock frequency (equals Baudrate in MBaud)		2.2V /3 V			1	MHz
	UART receive deglitch time		2.2 V	50	150	600	
ττ	(see Note 1)		3 V	50	100	600	ns

NOTE 1: Pulses on the UART receive input (UCxRX) shorter than the UART receive deglitch time are suppressed. To ensure that pulses are correctly recognized their width should exceed the maximum specification of the deglitch time.

## USCI (SPI master mode) (see Figure 18 and Figure 19)

	PARAMETER	TEST CONDITIONS	VCC	MIN	TYP MAX	UNIT	
f <sub>USCI</sub>	USCI input clock frequency	SMCLK, ACLK Duty Cycle = 50% ± 10%			f <sub>SYSTEM</sub>	MHz	
	201111111111111111111111111111111111111		2.2 V	110			
t <sub>SU,MI</sub>	SOMI input data setup time	SOMI Input data setup time		3 V	75		ns
			2.2 V	0			
t <sub>HD,MI</sub>	SOMI input data hold time		3 V	0		ns	
	0040	UCLK edge to SIMO valid;	2.2 V		30		
t <sub>VALID,MO</sub>	SIMO output data valid time	C <sub>L</sub> = 20 pF	3 V		20	ns	

# USCI (SPI slave mode) (see Figure 20 and Figure 21)

	PARAMETER	TEST CONDITIONS	vcc	MIN	TYP	MAX	UNIT
t <sub>STE,LEAD</sub>	STE lead time STE low to clock		2.2 V/3 V		50		ns
t <sub>STE,LAG</sub>	STE lag time Last clock to STE high		2.2 V/3 V	10			ns
t <sub>STE,ACC</sub>	STE access time STE low to SOMI data out		2.2 V/3 V		50		ns
t <sub>STE,DIS</sub>	STE disable time STE high to SOMI high impedance		2.2 V/3 V		50		ns
	0000		2.2 V	20			
t <sub>SU,SI</sub>	SIMO input data setup time		3 V	15			ns
			2.2 V	10			
t <sub>HD,SI</sub>	SIMO input data hold time		3 V	10			ns
		UCLK edge to SOMI valid;	2.2 V		75	110	
t <sub>VALID</sub> ,SO	SOMI output data valid time	C <sub>L</sub> = 20 pF	3 V		50	75	ns

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

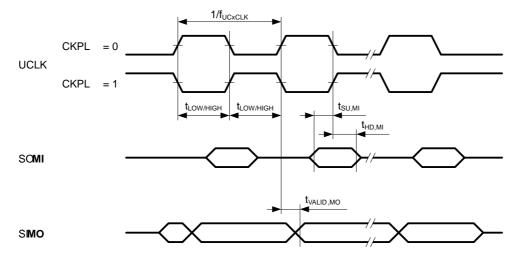


Figure 18. SPI Master Mode, CKPH = 0

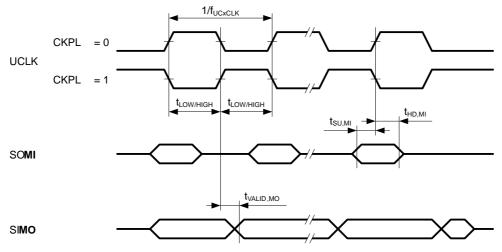


Figure 19. SPI Master Mode, CKPH = 1

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

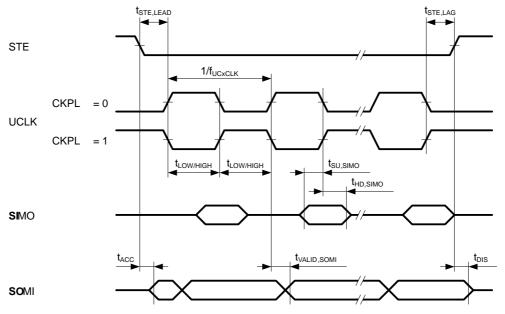


Figure 20. SPI Slave Mode, CKPH = 0

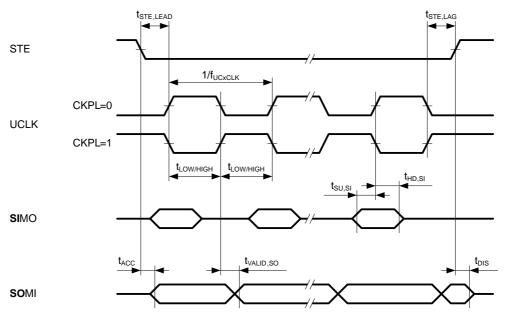


Figure 21. SPI Slave Mode, CKPH = 1

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

# USCI (I2C mode) (see Figure 22)

	PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	UNIT
fusci	USCI input clock frequency	Internal: SMCLK, ACLK External: UCLK Duty Cycle = 50% ± 10%			f <sub>S</sub> v	YSTEM	MHz
f <sub>SCL</sub>	SCL clock frequency		2.2 V/3 V	0		400	kHz
		f <sub>SCL</sub> ≤ 100kHz	2.2 V/3 V	4.0			
t <sub>HD,STA</sub>	Hold time (repeated) START	f <sub>SCL</sub> > 100kHz	2.2 V/3 V	0.6			μs
4	Oat and the forest and other	f <sub>SCL</sub> ≤ 100kHz	2.2 V/3 V	4.7			_
t <sub>SU,STA</sub>	Set-up time for a repeated START	f <sub>SCL</sub> > 100kHz	2.2 V/3 V	0.6			μS
t <sub>HD,DAT</sub>	Data hold time		2.2 V/3 V	0			ns
t <sub>SU,DAT</sub>	Data set-up time		2.2 V/3 V	250			ns
t <sub>SU,STO</sub>	Set-up time for STOP		2.2 V/3 V	4.0			μs
	Pulse width of spikes suppressed by		2.2 V	50	150	600	
t <sub>SP</sub>	input filter		3 V	50	100	600	ns

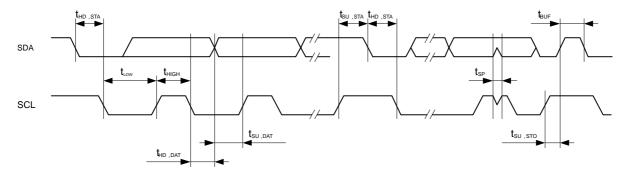


Figure 22. I2C Mode Timing

# **USART1** (see Note 1)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{(\tau)}$		V <sub>CC</sub> = 2.2 V, SYNC = 0, UART mode	200	430	800	5
	USART1 deglitch time	V <sub>CC</sub> = 3 V, SYNC = 0, UART mode	150	280	500	ns

NOTE 1: The signal applied to the USART1 receive signal/terminal (URXD1) should meet the timing requirements of  $t_{(\tau)}$  to ensure that the URXS flip-flop is set. The URXS flip-flop is set with negative pulses meeting the minimum-timing condition of  $t_{(\tau)}$ . The operating conditions to set the flag must be met independently from this timing constraint. The deglitch circuitry is active only on negative transitions on the URXD1 line.



# electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

#### 12-bit ADC, power supply and input range conditions (see Note 1)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
AV <sub>CC</sub>	Analog supply voltage					3.6	٧
V <sub>(P6.x/Ax)</sub>	Analog input voltage range (see Note 2)	All external Ax terminals. Analog inp selected in ADC12MCTLx register at $V_{(AVSS)} \le V_{Ax} \le V_{(AVCC)}$	0		V <sub>AVCC</sub>	٧	
	Operating supply current	f <sub>ADC12CLK</sub> = 5.0 MHz,	V <sub>CC</sub> = 2.2 V		0.65	1.3	4
ADC12	into AV <sub>CC</sub> terminal (see Note 3)	ADC12ON = 1, REFON = 0, SHT0=0, SHT1=0, ADC12DIV=0	V <sub>CC</sub> = 3 V		0.8	1.6	mA
	Operating supply current	f <sub>ADC12CLK</sub> = 5.0 MHz, ADC12ON = 0, REFON = 1, REF2_5V = 1	V <sub>CC</sub> = 3 V		0.5	0.8	mA
I <sub>REF+</sub>	into AV <sub>CC</sub> terminal (see Note 4)	f <sub>ADC12CLK</sub> = 5.0 MHz,	V <sub>CC</sub> = 2.2 V		0.5	0.8	
		ADC12ON = 0, REFON = 1, REF2_5V = 0	V <sub>CC</sub> = 3 V		0.5	0.8	mA
C <sub>I</sub>	Input capacitance	Only one terminal can be selected at one time, Ax	V <sub>CC</sub> = 2.2 V			40	pF
R <sub>I</sub>	Input MUX ON resistance	$0V \le V_{Ax} \le V_{AVCC}$	V <sub>CC</sub> = 3 V			2000	Ω

- NOTES: 1. The leakage current is defined in the leakage current table with Ax parameter.
  - 2. The analog input voltage range must be within the selected reference voltage range  $V_{R+}$  to  $V_{R-}$  for valid conversion results.
  - 3. The internal reference supply current is not included in current consumption parameter I<sub>ADC12</sub>.
  - 4. The internal reference current is supplied via terminal AV<sub>CC</sub>. Consumption is independent of the ADC12ON control bit, unless a conversion is active. The REFON bit enables to settle the built-in reference before starting an A/D conversion.

#### 12-bit ADC, external reference (see Note 1)

PA	RAMETER	TEST CONDITION	S	MIN	TYP MAX	UNIT
V <sub>eREF+</sub>	Positive external reference voltage input	V <sub>eREF+</sub> > V <sub>REF</sub> _/V <sub>eREF-</sub> , (see Note 2)			V <sub>AVCC</sub>	٧
V <sub>REF-</sub> /V <sub>eREF-</sub>	Negative external reference voltage input	V <sub>eREF+</sub> > V <sub>REF</sub> _/V <sub>eREF</sub> _, (see Note 3	/ <sub>eREF+</sub> > V <sub>REF</sub> _/V <sub>eREF</sub> _, (see Note 3)			V
(V <sub>eREF+</sub> - V <sub>REF-/</sub> V <sub>eREF-</sub> )	Differential external reference voltage input	V <sub>eREF+</sub> > V <sub>REF</sub> _/V <sub>eREF-</sub> , (see Note 4	V <sub>eREF+</sub> > V <sub>REF-</sub> /V <sub>eREF-</sub> , (see Note 4)			V
I <sub>VeREF+</sub>	Input leakage current	0V ≤V <sub>eREF+</sub> ≤ V <sub>AVCC</sub>	V <sub>CC</sub> = 2.2 V/3 V		±1	μА
I <sub>VREF-/VeREF-</sub>	Input leakage current	0V ≤ V <sub>eREF</sub> ≤ V <sub>AVCC</sub>	V <sub>CC</sub> = 2.2 V/3 V		±1	μΑ

- NOTES: 1. The external reference is used during conversion to charge and discharge the capacitance array. The input capacitance, C<sub>I</sub>, is also the dynamic load for an external reference during conversion. The dynamic impedance of the reference supply should follow the recommendations on analog-source impedance to allow the charge to settle for 12-bit accuracy.
  - 2. The accuracy limits the minimum positive external reference voltage. Lower reference voltage levels may be applied with reduced accuracy requirements.
  - The accuracy limits the maximum negative external reference voltage. Higher reference voltage levels may be applied with reduced accuracy requirements.
  - 4. The accuracy limits minimum external differential reference voltage. Lower differential reference voltage levels may be applied with reduced accuracy requirements.



#### 12-bit ADC, built-in reference

	PARAMETER	TEST CONDITIONS	5	MIN	NOM	MAX	UNIT
.,	Positive built-in reference	REF2_5V = 1 for 2.5 V, $I_{VREF+}$ max $\leq I_{VREF+} \leq I_{VREF+}$ min	V <sub>CC</sub> = 3 V	2.4	2.5	2.6	.,
V <sub>REF+</sub>	voltage output	REF2_5V = 0 for 1.5 V, $I_{VREF+}$ max $\leq I_{VREF+}$ $\leq I_{VREF+}$ min	V <sub>CC</sub> = 2.2 V/3 V	1.44	1.5	1.56	V
	AV <sub>CC</sub> minimum voltage,	REF2_5V = 0, $I_{VREF+}$ max $\leq I_{VREF+} \leq$	I <sub>VREF+</sub> min	2.2			
AV <sub>CC(min)</sub>	Positive built-in reference	REF2_5V = 1, $I_{VREF+}$ min $\geq I_{VREF+} \geq \cdot$	–0.5mA	2.8			V
	active	REF2_5V = 1, $I_{VREF+}$ min $\geq I_{VREF+} \geq -$	-1mA	2.9			
l	Load current out of V <sub>REF+</sub>		V <sub>CC</sub> = 2.2 V	0.01		-0.5	mA
I <sub>VREF+</sub>	terminal		$V_{CC} = 3 V$	0.01		-1	IIIA
	Load-current regulation V <sub>REF+</sub> terminal	I <sub>VREF+</sub> = 500 μA +/– 100 μA, Analog input voltage ~0.75 V;	$V_{CC} = 2.2 \text{ V}$			±2	LSB
		REF2_5V = 0	$V_{CC} = 3 V$			±2	LOD
I <sub>L(VREF)+</sub>		$I_{VREF+}$ = 500 μA ± 100 μA, Analog input voltage ~1.25 V, REF2_5V = 1	V <sub>CC</sub> = 3 V			±2	LSB
I <sub>DL(VREF) +</sub>	Load current regulation V <sub>REF+</sub> terminal	$\begin{split} I_{VREF+} = &100~\mu\text{A} \rightarrow 900~\mu\text{A}, \\ C_{VREF+} = &5~\mu\text{F}, \text{ ax } \sim &0.5~\text{x } V_{REF+}, \\ \text{Error of conversion result} \leq &1~\text{LSB} \end{split}$	V <sub>CC</sub> = 3 V			20	ns
C <sub>VREF+</sub>	Capacitance at pin V <sub>REF+</sub> (see Note 1)	REFON =1, 0 mA $\leq$ I <sub>VREF+</sub> $\leq$ I <sub>VREF+</sub> max	V <sub>CC</sub> = 2.2 V/3 V	5	10		μF
T <sub>REF+</sub>	Temperature coefficient of built-in reference	$I_{VREF+}$ is a constant in the range of 0 mA $\leq I_{VREF+} \leq$ 1 mA	V <sub>CC</sub> = 2.2 V/3 V			±100	ppm/°C
tREFON	Settle time of internal reference voltage (see Figure 23 and Note 2)	$I_{VREF+}$ = 0.5 mA, $C_{VREF+}$ = 10 $\mu$ F, $V_{REF+}$ = 1.5 V, $V_{AVCC}$ = 2.2 V				17	ms

- NOTES: 1. The internal buffer operational amplifier and the accuracy specifications require an external capacitor. All INL and DNL tests uses two capacitors between pins V<sub>REF+</sub> and AV<sub>SS</sub> and V<sub>REF-</sub>/V<sub>eREF-</sub> and AV<sub>SS</sub>: 10 μF tantalum and 100 nF ceramic.
  - 2. The condition is that the error in a conversion started after t<sub>REFON</sub> is less than ±0.5 LSB. The settling time depends on the external capacitive load.

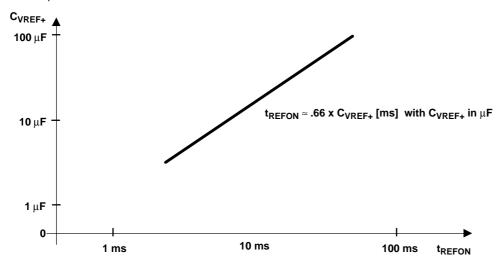


Figure 23. Typical Settling Time of Internal Reference t<sub>REFON</sub> vs External Capacitor on V<sub>REF</sub>+



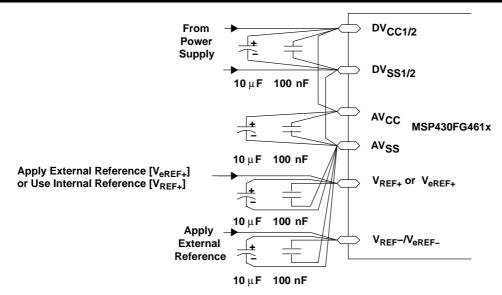


Figure 24. Supply Voltage and Reference Voltage Design  $V_{REF-}/V_{eREF-}$  External Supply

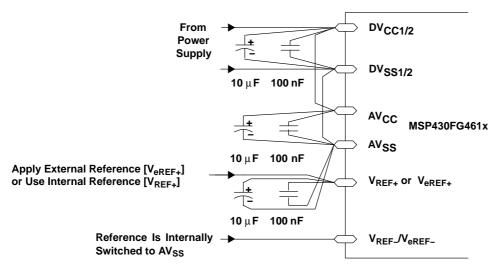


Figure 25. Supply Voltage and Reference Voltage Design V<sub>REF-</sub>/V<sub>eREF-</sub> = AV<sub>SS</sub>, Internally Connected

# electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

#### 12-bit ADC, timing parameters

P	PARAMETER	TEST CONDITION	IS	MIN	NOM	MAX	UNIT
f <sub>ADC12CLK</sub>		For specified performance of ADC12 linearity parameters	V <sub>CC</sub> = 2.2V/3 V	0.45	5	6.3	MHz
f <sub>ADC12OSC</sub>	Internal ADC12 oscillator	ADC12DIV=0, fADC12CLK=fADC12OSC	V <sub>CC</sub> = 2.2 V/ 3 V	3.7	5	6.3	MHz
		$C_{VREF+} \ge 5 \mu F$ , Internal oscillator, $f_{ADC12OSC} = 3.7 \text{ MHz}$ to 6.3 MHz	V <sub>CC</sub> = 2.2 V/ 3 V	2.06		3.51	μs
<sup>t</sup> CONVERT	Conversion time	External f <sub>ADC12CLK</sub> from ACLK, MCLK, or SMCLK, ADC12SSEL ≠ 0			13×ADC12DIV× 1/f <sub>ADC12CLK</sub>		μs
t <sub>ADC12ON</sub>	Turn on settling time of the ADC	(see Note 1)				100	ns
	Complie a time	$R_S = 400 \Omega, R_I = 1000 \Omega,$	V <sub>CC</sub> = 3 V	1220			
<sup>t</sup> Sample	Sampling time	$C_I = 30 \text{ pF}, \ \tau = [R_S + R_I] \times C_I,$ (see Note 2)	V <sub>CC</sub> = 2.2 V	1400			ns

NOTES: 1. The condition is that the error in a conversion started after t<sub>ADC12ON</sub> is less than ±0.5 LSB. The reference and input signal are already settled

## 12-bit ADC, linearity parameters

	PARAMETER	TEST CONDITIONS		MIN NOM	MAX	UNIT
_	Into and line with a sure	$1.4 \text{ V} \le (\text{V}_{\text{eREF+}} - \text{V}_{\text{REF-}}/\text{V}_{\text{eREF-}}) \text{ min } \le 1.6 \text{ V}$	V <sub>CC</sub> =		±2	5
EI	Integral linearity error	$1.6 \text{ V} < (\text{V}_{\text{eREF+}} - \text{V}_{\text{REF-}}/\text{V}_{\text{eREF-}}) \text{ min} \leq [\text{V}_{\text{AVCC}}]$	2.2 V/3 V		±1.7	LSB
E <sub>D</sub>	Differential linearity error	$ \begin{array}{l} (V_{eREF+} - V_{REF-}/V_{eREF-})_{min} \leq (V_{eREF+} - V_{REF-}/V_{eREF-}), \\ C_{VREF+} = 10~\mu F ~(tantalum) ~and ~100~nF ~(ceramic) \end{array} $	V <sub>CC</sub> = 2.2 V/3 V		±1	LSB
E <sub>O</sub>	Offset error	$\begin{split} &(V_{eREF+}-V_{REF-}/V_{eREF-})_{min} \leq (V_{eREF+}-V_{REF-}/V_{eREF-}), \\ &\text{Internal impedance of source } R_S < 100~\Omega, \\ &C_{VREF+} = 10~\mu F \text{ (tantalum) and } 100~nF \text{ (ceramic)} \end{split}$	V <sub>CC</sub> = 2.2 V/3 V	±2	±4	LSB
E <sub>G</sub>	Gain error	$ \begin{array}{l} (V_{\text{eREF+}} - V_{\text{REF-}} / V_{\text{eREF-}})_{\text{min}} \leq (V_{\text{eREF+}} - V_{\text{REF-}} / V_{\text{eREF-}}), \\ C_{\text{VREF+}} = 10~\mu\text{F (tantalum) and } 100~\text{nF (ceramic)} \end{array} $	V <sub>CC</sub> = 2.2 V/3 V	±1.1	±2	LSB
E <sub>T</sub>	Total unadjusted error	$ \begin{array}{l} (V_{\text{eREF+}} - V_{\text{REF-}} / V_{\text{eREF-}})_{\text{min}} \leq (V_{\text{eREF+}} - V_{\text{REF-}} / V_{\text{eREF-}}), \\ C_{\text{VREF+}} = 10~\mu\text{F (tantalum) and } 100~\text{nF (ceramic)} \end{array} $	V <sub>CC</sub> = 2.2 V/3 V	±2	±5	LSB

<sup>2.</sup> Approximately ten Tau  $(\tau)$  are needed to get an error of less than  $\pm 0.5$  LSB:  $t_{Sample} = ln(2^{n+1}) \times (R_S + R_I) \times C_I + 800$  ns where n = ADC resolution = 12,  $R_S$  = external source resistance.

#### 12-bit ADC, temperature sensor and built-in V<sub>MID</sub>

I	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	NOM	MAX	UNIT
	Operating supply current into	REFON = 0, INCH = 0Ah,	2.2 V		40	120	•
ISENSOR	AV <sub>CC</sub> terminal (see Note 1)	ADC12ON=NA, T <sub>A</sub> = 25°C	3 V		60	160	μΑ
V <sub>SENSOR</sub>	(see Note 2)	ADC12ON = 1, INCH = 0Ah, T <sub>A</sub> = 0°C	2.2 V/ 3 V		986		mV
TC <sub>SENSOR</sub>		ADC12ON = 1, INCH = 0Ah	2.2 V/ 3 V		3.55±3%		mV/°C
	Sample time required if	ADC12ON = 1, INCH = 0Ah,	2.2 V	30			
<sup>†</sup> SENSOR(sample)	channel 10 is selected (see Note 3)	Error of conversion result ≤ 1 LSB 3 V		30			μs
	Current into divider at	ADCASON A INCLL ORK	2.2 V			NA	
I <sub>VMID</sub>	channel 11 (see Note 4)	ADC12ON = 1, INCH = 0Bh	3 V			NA	μΑ
.,	AV dividends about all 44	ADC12ON = 1, INCH = 0Bh,	2.2 V		1.1	1.1±0.04	.,
$V_{MID}$	AV <sub>CC</sub> divider at channel 11	V <sub>MID</sub> is ~0.5 x V <sub>AVCC</sub>	3 V		1.5	1.50±0.04	V
tynup(seessele)	Sample time required if channel 11 is selected	ADC12ON = 1, INCH = 0Bh,	2.2 V	1400			ns
<sup>t</sup> ∨MID(sample)	(see Note 5)	Error of conversion result ≤ 1 LSB	3 V	1220			113

- NOTES: 1. The sensor current I<sub>SENSOR</sub> is consumed if (ADC12ON = 1 and REFON=1), or (ADC12ON=1 AND INCH=0Ah and sample signal is high). When REFON = 1, I<sub>SENSOR</sub> is already included in I<sub>REF+</sub>.
  - 2. The temperature sensor offset can be as much as ±20°C. A single-point calibration is recommended in order to minimize the offset error of the built-in temperature sensor.
  - 3. The typical equivalent impedance of the sensor is 51 kΩ. The sample time required includes the sensor-on time t<sub>SENSOR(on)</sub>
  - 4. No additional current is needed. The  $V_{\mbox{\scriptsize MID}}$  is used during sampling.
  - 5. The on-time t<sub>VMID(on)</sub> is included in the sampling time t<sub>VMID(sample)</sub>; no additional on time is needed.

#### 12-bit DAC, supply specifications

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
AV <sub>CC</sub>	Analog supply voltage	$AV_{CC} = DV_{CC},$ $AV_{SS} = DV_{SS} = 0 V$		2.20		3.60	V
		DAC12AMPx=2, DAC12IR=0, DAC12_xDAT=0800h			50	110	
	Supply current:	DAC12AMPx=2, DAC12IR=1, DAC12_xDAT=0800h , V <sub>eREF+</sub> =V <sub>REF+</sub> = AV <sub>CC</sub>			50	110	
I <sub>DD</sub>	Single DAC Channel (see Notes 1 and 2)	DAC12AMPx=5, DAC12IR=1, DAC12_xDAT=0800h, V <sub>eREF+</sub> =V <sub>REF+</sub> = AV <sub>CC</sub>	2.2 V/3 V		200	440	μΑ
		DAC12AMPx=7, DAC12IR=1, DAC12_xDAT=0800h, V <sub>eREF+</sub> =V <sub>REF+</sub> = AV <sub>CC</sub>			700	1500	
DCDD	Power-supply	DAC12_xDAT = 800h, $V_{REF}$ = 1.5 V, $\Delta AV_{CC}$ = 100mV	2.2 V		70		٩D
PSRR	rejection ratio (see Notes 3 and 4)	DAC12_xDAT = 800h, $V_{REF}$ = 1.5 V or 2.5 V, $\Delta AV_{CC}$ = 100mV	3 V		70		dB

NOTES: 1. No load at the output pin, DAC12\_0 or DAC12\_1, assuming that the control bits for the shared pins are set properly.

- 2. Current into reference terminals not included. If DAC12IR = 1 current flows through the input divider; see Reference Input specifications.
- $3. \quad \text{PSRR} = 20^* log\{\Delta \text{AV}_{\text{CC}}/\Delta \text{V}_{\text{DAC12\_xOUT}}\}.$
- 4. V<sub>REF</sub> is applied externally. The internal reference is not used.



#### 12-bit DAC, linearity specifications (see Figure 26)

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
	Resolution	(12-bit Monotonic)		12			bits
	Integral nonlinearity	V <sub>ref</sub> = 1.5 V, DAC12AMPx = 7, DAC12IR = 1	2.2 V		.00	100	- 00
INL	(see Note 1)	V <sub>ref</sub> = 2.5 V, DAC12AMPx = 7, DAC12IR = 1	3 V		±2.0	±8.0	LSB
DAII	Differential nonlinearity	V <sub>ref</sub> = 1.5 V, DAC12AMPx = 7, DAC12IR = 1	2.2 V		10.4	14.0	- CD
DNL	(see Note 1)	V <sub>ref</sub> = 2.5 V, DAC12AMPx = 7, DAC12IR = 1	3 V		±0.4	±1.0	LSB
	Offset voltage without calibration	V <sub>ref</sub> = 1.5 V, DAC12AMPx = 7, DAC12IR = 1	2.2 V			.04	
E <sub>O</sub>	(see Notes 1, 2) $ V_{ref} = 2.5 \text{ V}, $ $DAC12AMPx = 7, DAC12IR = 1 $ $ 3 \text{ V} $		±21	.,			
	Offset voltage with	V <sub>ref</sub> = 1.5 V, DAC12AMPx = 7, DAC12IR = 1	2.2 V			mV	
	calibration (see Notes 1, 2)	V <sub>ref</sub> = 2.5 V, DAC12AMPx = 7, DAC12IR = 1	3 V			±2.5	
d <sub>E(O)</sub> /d <sub>T</sub>	Offset error temperature coefficient (see Note 1)		2.2 V/3 V		±30		μV/°C
_	Coin amon (ann Nata 4)	V <sub>REF</sub> = 1.5 V	2.2 V			10.50	0/ FCD
E <sub>G</sub>	Gain error (see Note 1)	V <sub>REF</sub> = 2.5 V	3 V			±3.50	% FSR
d <sub>E(G)</sub> /d <sub>T</sub>	Gain temperature coefficient (see Note 1)		2.2 V/3 V		10		ppm of FSR/°C
	Torre for affect calls of	DAC12AMPx = 2				100	
t <sub>Offset_Cal</sub>	Time for offset calibration (see Note 3)	DAC12AMPx = 3,5	2.2 V/3 V			32	ms
	(300 14010 3)	DAC12AMPx = 4,6,7				6	

NOTES: 1. Parameters calculated from the best-fit curve from 0x0A to 0xFFF. The best-fit curve method is used to deliver coefficients "a" and "b" of the first order equation: y = a + b\*x. V<sub>DAC12\_xOUT</sub> = E<sub>O</sub> + (1 + E<sub>O</sub>) \* (V<sub>eREF+</sub>/4095) \* DAC12\_xDAT, DAC12IR = 1.

- 2. The offset calibration works on the output operational amplifier. Offset Calibration is triggered setting bit DAC12CALON
- 3. The offset calibration can be done if DAC12AMPx = {2, 3, 4, 5, 6, 7}. The output operational amplifier is switched off with DAC12AMPx = {0, 1}. It is recommended that the DAC12 module be configured prior to initiating calibration. Port activity during calibration may effect accuracy and is not recommended.

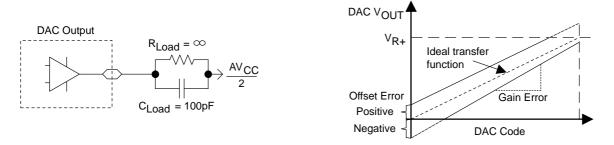
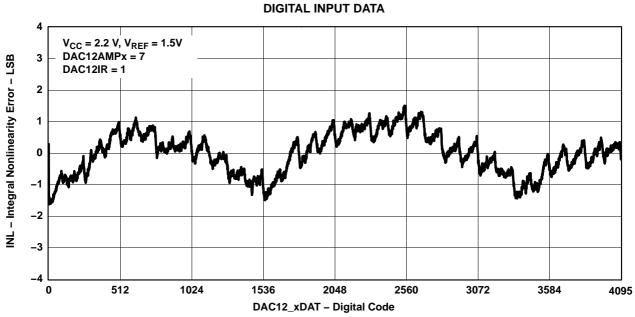


Figure 26. Linearity Test Load Conditions and Gain/Offset Definition

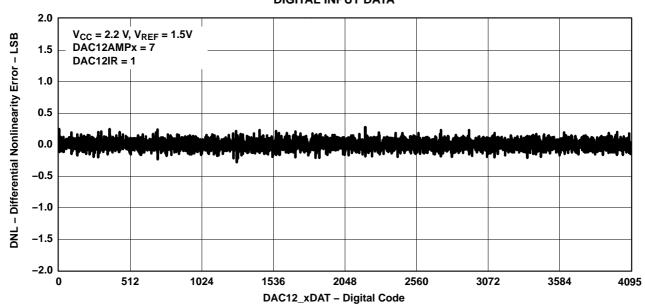


12-bit DAC, linearity specifications (continued)

TYPICAL INL ERROR
vs
DIGITAL INPUT DATA



# TYPICAL DNL ERROR vs DIGITAL INPUT DATA





# electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

## 12-bit DAC, output specifications

PAR	AMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
		No Load, Ve <sub>REF+</sub> = AV <sub>CC</sub> , DAC12_xDAT = 0h, DAC12IR = 1, DAC12AMPx = 7		0		0.005	
	Output voltage range	No Load, Ve <sub>REF+</sub> = AV <sub>CC</sub> , DAC12_xDAT = 0FFFh, DAC12IR = 1, DAC12AMPx = 7	0.07/07/	AV <sub>CC</sub> -0.05		AV <sub>CC</sub>	V
Vo	(see Note 1, Figure 29)	$R_{Load}$ = 3 k $\Omega$ , $Ve_{REF+}$ = AV $_{CC}$ , DAC12_xDAT = 0h, DAC12IR = 1, DAC12AMPx = 7	2.2 V/3 V	0		0.1	V
		$R_{Load}$ = 3 k $\Omega$ , $Ve_{REF+}$ = AV $_{CC}$ , DAC12_xDAT = 0FFFh, DAC12IR = 1, DAC12AMPx = 7		AV <sub>CC</sub> -0.13		AV <sub>CC</sub>	
C <sub>L(DAC12)</sub>	Max DAC12 load capacitance		2.2V/3V			100	pF
	Max DAC12		2.2V	-0.5		+0.5	A
I <sub>L(DAC12)</sub>	load current		3V	-1.0		+1.0	mA
		$\begin{aligned} R_{Load} &= 3 \text{ k}\Omega, \text{ V}_{O/P(DAC12)} < 0.3 \text{ V}, \\ DAC12AMPx &= 2, \text{ DAC12}\_x\text{DAT} &= 0 \text{h} \end{aligned}$			150	250	
R <sub>O/P(DAC12)</sub>	Output resistance (see Figure 29)	$R_{Load}$ = 3 k $\Omega$ , V <sub>O/P(DAC12)</sub> > AV <sub>CC</sub> -0.3 V DAC12_xDAT = 0FFFh	2.2 V/3 V		150	250	Ω
NOTE 1: Data		$R_{Load} = 3 k\Omega$ , $0.3V \le V_{O/P(DAC12)} \le AV_{CC} - 0.3V$			1	4	

NOTE 1: Data is valid after the offset calibration of the output amplifier.

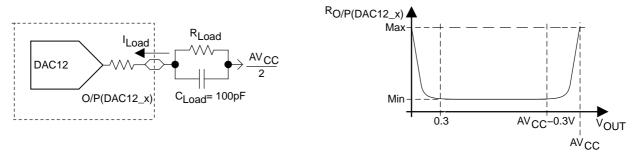


Figure 29. DAC12\_x Output Resistance Tests



#### 12-bit DAC, reference input specifications

PAR	RAMETER	AMETER TEST CONDITIONS V <sub>CC</sub> MIN T		TYP	MAX	UNIT	
	Reference input	DAC12IR=0 (see Notes 1 and 2)	0.07/07/		AV <sub>CC</sub> /3	AV <sub>CC</sub> +0.2	.,
Ve <sub>REF+</sub>	voltage range	DAC12IR=1 (see Notes 3 and 4)	2.2 V/3 V		AVcc	AVcc+0.2	V
		DAC12_0 IR=DAC12_1 IR =0		20			MΩ
		DAC12_0 IR=1, DAC12_1 IR = 0		40	40		
Ri <sub>(VREF+)</sub> ,	Reference input	DAC12_0 IR=0, DAC12_1 IR = 1	2.2 V/3 V	40	48	56	
Ri <sub>(VeREF+)</sub>	resistance	DAC12_0 IR=DAC12_1 IR =1,	2.2 V/3 V				kΩ
		DAC12_0 SREFx = DAC12_1 SREFx		20	24	28	
		(see Note 5)					

NOTES: 1. For a full-scale output, the reference input voltage can be as high as 1/3 of the maximum output voltage swing (AV<sub>CC</sub>).

- 2. The maximum voltage applied at reference input voltage terminal  $Ve_{REF+} = [AV_{CC} V_{E(O)}] / [3*(1 + E_G)]$ .
- 3. For a full-scale output, the reference input voltage can be as high as the maximum output voltage swing (AV<sub>CC</sub>).
- 4. The maximum voltage applied at reference input voltage terminal  $Ve_{REF+} = [AV_{CC} V_{E(O)}] / (1 + E_G)$ .
- 5. When DAC12IR = 1 and DAC12SREFx = 0 or 1 for both channels, the reference input resistive dividers for each DAC are in parallel reducing the reference input resistance.

# 12-bit DAC, dynamic specifications; V<sub>ref</sub> = V<sub>CC</sub>, DAC12IR = 1 (see Figure 30 and Figure 31)

PA	RAMETER	Ti	EST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT	
	DAC40	DAC12_xDAT = 800h,	$DAC12AMPx = 0 \rightarrow \{2, 3, 4\}$			60	120		
t <sub>ON</sub>	DAC12 on-time	$Error_{V(O)} < \pm 0.5 LSB$	$DAC12AMPx = 0 \to \{5, 6\}$	2.2 V/3 V		15	30	μs	
	OH-time	(see Note 1,Figure 30)	$DAC12AMPx = 0 \to 7$			6	12		
	0 - 111 11	DAGAGDAT	DAC12AMPx = 2			100	200		
t <sub>S(FS)</sub>	Settling time, full-scale	DAC12_xDAT = 80h→ F7Fh→ 80h	DAC12AMPx = 3,5	2.2 V/3 V		40	80	μs	
, ,	ruii-scale		DAC12AMPx = 4,6,7			15	30		
		DAC12_xDAT =	DAC12AMPx = 2			5			
t <sub>S(C-C)</sub>	Settling time, code to code	3F8h→ 408h→ 3F8h	DAC12AMPx = 3,5	2.2 V/3 V		2		μs	
, ,	code to code	$BF8h {\rightarrow} C08h {\rightarrow} BF8h$	DAC12AMPx = 4,6,7			1			
		DAC12_xDAT =	DAC12AMPx = 2		0.05	0.12			
SR	Slew rate	80h→ F7Fh→ 80h	DAC12AMPx = 3,5	2.2 V/3 V	0.35	0.7		V/μs	
		(see Note 2)	DAC12AMPx = 4,6,7		1.5	2.7			
		21012 217	DAC12AMPx = 2			600			
Glitch e	nergy, full-scale	DAC12_xDAT =	DAC12AMPx = 3,5	2.2 V/3 V		150		nV-s	
		80h→ F7Fh→ 80h	DAC12AMPx = 4,6,7			30		11.4.5	

NOTES: 1.  $R_{Load}$  and  $C_{Load}$  connected to  $AV_{SS}$  (not  $AV_{CC}/2$ ) in Figure 30.

2. Slew rate applies to output voltage steps >= 200mV.

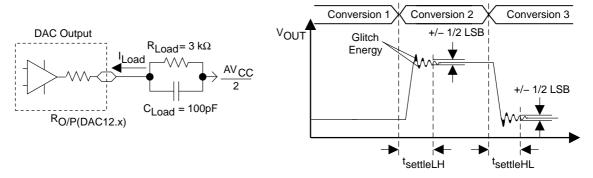


Figure 30. Settling Time and Glitch Energy Testing



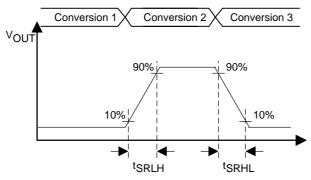


Figure 31. Slew Rate Testing

# 12-bit DAC, dynamic specifications continued (T<sub>A</sub> = 25°C unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
	3-dR handwidth	DAC12AMPx = {2, 3, 4}, DAC12SREFx = 2, DAC12IR = 1, DAC12_xDAT = 800h		40			
BW <sub>-3dB</sub>	3-dB bandwidth, V <sub>DC</sub> =1.5V, V <sub>AC</sub> =0.1V <sub>PP</sub>	DAC12AMPx = {5, 6}, DAC12SREFx = 2, DAC12IR = 1, DAC12_xDAT = 800h	2.2 V/3 V	180			kHz
(see Figu	(see Figure 32)	DAC12AMPx = 7, DAC12SREFx = 2, DAC12IR = 1, DAC12_xDAT = 800h		550			
		DAC12_0DAT = 800h, No Load, DAC12_1DAT = 80h<->F7Fh, $R_{Load}$ = $3k\Omega$ $f_{DAC12_1OUT}$ = 10kHz @ 50/50 duty cycle	0.03//03/		-80		.10
	o-channel crosstalk 1 and Figure 33)	DAC12_0DAT = $80h<->F7Fh$ , $R_{Load} = 3k\Omega$ , DAC12_1DAT = $800h$ , No Load, $f_{DAC12_0OUT} = 10kHz @ 50/50 duty cycle$	2.2 V/3 V		-80		dB

NOTE 1:  $R_{LOAD} = 3 \text{ k}\Omega$ ,  $C_{LOAD} = 100 \text{ pF}$ 

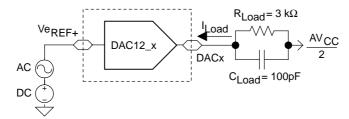


Figure 32. Test Conditions for 3-dB Bandwidth Specification

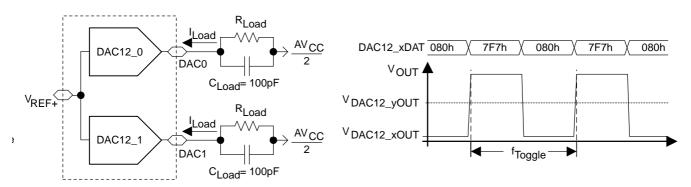


Figure 33. Crosstalk Test Conditions



# electrical characteristics over recommended operating free-air temperature (unless otherwise noted)

# operational amplifier OA, supply specifications

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
V <sub>CC</sub>	Supply voltage		_	2.2		3.6	V
		Fast Mode, OARRIP = 1 (rail-to-rail mode off)			180	290	
		Medium Mode, OARRIP = 1 (rail-to-rail mode off)			110	190	
	Supply current	Slow Mode, OARRIP = 1 (rail-to-rail mode off)	]		50	80	
I <sub>CC</sub>	(see Note 1)	Fast Mode, OARRIP = 0 (rail-to-rail mode on)	2.2 V/3 V		300	490	μΑ
		Medium Mode, OARRIP = 0 (rail-to-rail mode on)			190	350	
		Slow Mode, OARRIP = 0 (rail-to-rail mode on)			90	190	
PSRR	Power supply rejection ratio	Non-inverting	2.2 V/3 V		70		dB

NOTE 1: P6SEL.x = 1 for each corresponding pin when used in OA input or OA output mode.

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## operational amplifier OA, input/output specifications

	PARAMETER	TEST CONI	DITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
	V // 1/10	OARRIP = 1 (rail-to-	rail mode off)		-0.1		V <sub>CC</sub> -1.2	.,
$V_{I/P}$	Voltage supply, I/P	OARRIP = 0 (rail-to-	rail mode on)	-	-0.1		V <sub>CC</sub> +0.1	V
	Input leakage current, I/P	$T_A = -40 \text{ to } +55^{\circ}\text{C}$			-5	±0.5	5	
I <sub>lkg</sub>	(see Notes 1 and 2)	$T_A = +55 \text{ to } +85^{\circ}\text{C}$			-20	±5	20	nA
		Fast Mode				50		
		Medium Mode	f <sub>V(I/P)</sub> = 1 kHz			80		
		Slow Mode	` '			140		nV/√ <del>Hz</del>
V <sub>n</sub>	Voltage noise density, I/P	Fast Mode		1 - [		30		
		Medium Mode	f <sub>V(I/P)</sub> = 10 kHz			50		
		Slow Mode				65		
V <sub>IO</sub>	Offset voltage, I/P			2.2 V/3 V			±10	mV
	Offset temperature drift, I/P	see Note 3		2.2 V/3 V		±10		μV/°C
	Offset voltage drift with supply, I/P	$0.3V \le V_{IN} \le V_{CC} - 0.3$ $\Delta V_{CC} \le \pm 10\%, T_A = 2$		2.2 V/3 V			±1.5	mV/V
		Fast Mode, I <sub>SOURCE</sub> ≤ −500μA		2.2 V	V <sub>CC</sub> -0.2		V <sub>CC</sub>	
$V_{OH}$	High-level output voltage, O/P	Slow Mode,I <sub>SOURCE</sub>	≤ –150µA	3 V	V <sub>CC</sub> -0.1		V <sub>CC</sub>	V
		Fast Mode, I <sub>SOURCE</sub>	≤ +500μA	2.2 V	V <sub>SS</sub>		0.2	.,
$V_{OL}$	Low-level output voltage, O/P	Slow Mode,I <sub>SOURCE</sub>	≤ +150μA	3 V	V <sub>SS</sub>		0.1	V
		$R_{Load}$ = 3 k $\Omega$ , $C_{Load}$ = OARRIP = 0 (rail-to-IV <sub>O/P(OAx)</sub> < 0.2 V				150	250	
R <sub>O/P</sub> R	Output Resistance (see Figure 34 and Note 4)	OARRIP = 0 (rail-to-	$R_{Load} = 3 \text{ k}\Omega$ , $C_{Load} = 50 \text{pF}$ , OARRIP = 0  (rail-to-rail mode on), $V_{O/P(OAx)} > AV_{CC} - 0.2 \text{ V}$			150	250	Ω
		$R_{Load}$ = 3 k $\Omega$ , $C_{Load}$ = 50pF, OARRIP = 0 (rail-to-rail mode on), 0.2 V $\leq$ V <sub>O/P(OAx)</sub> $\leq$ AV <sub>CC</sub> - 0.2 V				0.1	4	
CMRR	Common-mode rejection ratio	Non-inverting		2.2 V/3 V		70		dB

NOTES: 1. ESD damage can degrade input current leakage.

- 2. The input bias current is overridden by the input leakage current.
- 3. Calculated using the box method.
- 4. Specification valid for voltage-follower OAx configuration.

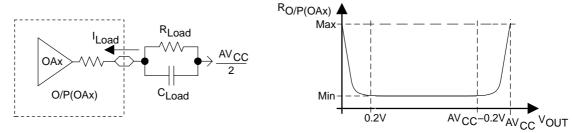
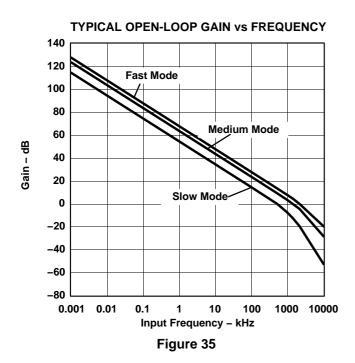
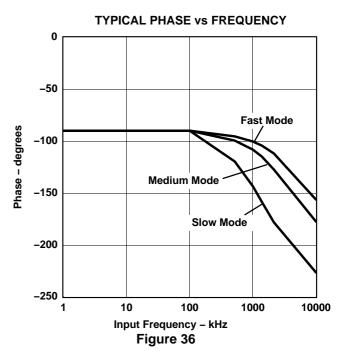


Figure 34. OAx Output Resistance Tests

## operational amplifier OA, dynamic specifications

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT	
		Fast Mode	_		1.2			
SR	Slew rate	Medium Mode	_		0.8		V/μs	
		Slow Mode	_		0.3			
	Open-loop voltage gain		_		100		dB	
φ <sub>m</sub>	Phase margin	C <sub>L</sub> = 50 pF	_		60		deg	
	Gain margin	C <sub>L</sub> = 50 pF	_		20		dB	
	Gain-bandwidth product	Non-inverting, Fast Mode, $R_L = 47k\Omega$ , $C_L = 50pF$			2.2			
GBW	(see Figure 35	Non-inverting, Medium Mode, $R_L = 300k\Omega$ , $C_L = 50pF$	2.2 V/3 V		1.4		MHz	
	and Figure 36)	Non–inverting, Slow Mode, $R_L = 300k\Omega$ , $C_L = 50pF$			0.5			
t <sub>en(on)</sub>	Enable time on	t <sub>on</sub> , non-inverting, Gain = 1	2.2 V/3 V		10	20	μs	
t <sub>en(off)</sub>	Enable time off	_	2.2 V/3 V			1	μs	





# electrical characteristics over recommended operating free-air temperature (unless otherwise noted)

# operational amplifier OA feedback network, noninverting amplifier mode (OAFCx = 4)

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
		OAFBRx = 0		0.996	1.00	1.002	
G		OAFBRx = 1		1.329	1.334	1.340	
		OAFBRx = 2 OAFBRx = 3		1.987	2.001	2.016	
	0.			2.64	2.667	2.70	
	Gain	OAFBRx = 4	2.2 V/ 3 V	3.93	4.00	4.06	
		OAFBRx = 5		5.22	5.33	5.43	
		OAFBRx = 6		7.76	7.97	8.18	
		OAFBRx = 7		15.0	15.8	16.6	
THD	Total harmonic distortion/	Allerine	2.2 V		-60		·ID
	nonlinearity	All gains	3 V		-70		dB
t <sub>Settle</sub>	Settling time (see Note 1)	All power modes	2.2 V/3 V		7	12	μs

NOTES: 1. The settling time specifies the time until an ADC result is stable. This includes the minimum required sampling time of the ADC. The settling time of the amplifier itself might be faster.

#### operational amplifier OA feedback network, inverting amplifier mode (OAFCx = 6) (see Note 1)

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
G		OAFBRx = 1		-0.371	-0.335	-0.298	
		OAFBRx = 2		-1.031	-1.002	-0.972	
		OAFBRx = 3		-1.727	-1.668	-1.609	
	Gain	OAFBRx = 4	2.2 V/ 3 V	-3.142	-3.00	-2.856	
	Gairi	OAFBRx = 5	2.2 V/ 3 V	-4.581	-4.33	-4.073	
		OAFBRx = 6		-7.529	-6.97	-6.379	
		OAFBRx = 7		-17.04 0	-14.8	-12.27 9	
THD	Total harmonic distortion/		2.2 V		-60		į
	nonlinearity	All gains	3 V		-70		dB
t <sub>Settle</sub>	Settling time (see Note 2)	All power modes	2.2 V/3 V		7	12	μs

NOTES: 1. This includes the 2 OA configuration "inverting amplifier with input buffer". Both OA needs to be set to the same power mode OAPMx.



<sup>2.</sup> The settling time specifies the time until an ADC result is stable. This includes the minimum required sampling time of the ADC. The settling time of the amplifier itself might be faster.

## flash memory (MSP430FG461x devices only)

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
V <sub>CC(PGM/</sub> ERASE)	Program and Erase supply voltage			2.7		3.6	٧
f <sub>FTG</sub>	Flash Timing Generator frequency			257		476	kHz
I <sub>PGM</sub>	Supply current from DV <sub>CC</sub> during program		2.7 V/ 3.6 V		3	5	mA
I <sub>ERASE</sub>	Supply current from DV <sub>CC</sub> during erase	See Note 3	2.7 V/ 3.6 V		3	7	mA
I <sub>GMERASE</sub>	Supply current from DV <sub>CC</sub> during global mass erase	See Note 4	2.7 V/ 3.6 V		6	14	mA
t <sub>CPT</sub>	Cumulative program time	See Note 1	2.7 V/ 3.6 V			10	ms
t <sub>CMErase</sub>	Cumulative mass erase time		2.7 V/ 3.6 V	20			ms
	Program/Erase endurance			10 <sup>4</sup>	10 <sup>5</sup>		cycles
t <sub>Retention</sub>	Data retention duration	$T_J = 25^{\circ}C$		100			years
t <sub>Word</sub>	Word or byte program time				30		
t <sub>Block, 0</sub>	Block program time for 1st byte or word				25		
t <sub>Block, 1-63</sub>	Block program time for each additional byte or word	]			18		
t <sub>Block</sub> , End	Block program end-sequence wait time	See Note 2			6		t <sub>FTG</sub>
t <sub>Mass Erase</sub>	Mass erase time				10593		
t <sub>Global Mass Erase</sub>	Global mass erase time				10593		
t <sub>Seg Erase</sub>	Segment erase time				4819	·	

- NOTES: 1. The cumulative program time must not be exceeded during a block-write operation. This parameter is only relevant if the block write feature is used.
  - 2. These values are hardwired into the Flash Controller's state machine ( $t_{FTG} = 1/f_{FTG}$ ).
  - 3. Lower 64-KB or upper 64-KB Flash memory erased.
  - 4. All Flash memory erased.

#### JTAG interface

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
,	TOK in a state of the state of	One Nete 4	2.2 V	0		5	MHz
TTCK	TCK input frequency	See Note 1	3 V	0		10	MHz
R <sub>Internal</sub>	Internal pull-up resistance on TMS, TCK, TDI/TCLK	See Note 2	2.2 V/ 3 V	25	60	90	kΩ

NOTES: 1. f<sub>TCK</sub> may be restricted to meet the timing requirements of the module selected.

2. TMS, TDI/TCLK, and TCK pull-up resistors are implemented in all versions.

## JTAG fuse (see Note 1)

	PARAMETER	TEST CONDITIONS	v <sub>cc</sub>	MIN	TYP	MAX	UNIT
V <sub>CC(FB)</sub>	Supply voltage during fuse-blow condition	T <sub>A</sub> = 25°C		2.5			V
$V_{FB}$	Voltage level on TDI/TCLK for fuse-blow: F versions			6		7	V
I <sub>FB</sub>	Supply current into TDI/TCLK during fuse blow					100	mA
t <sub>FB</sub>	Time to blow fuse					1	ms

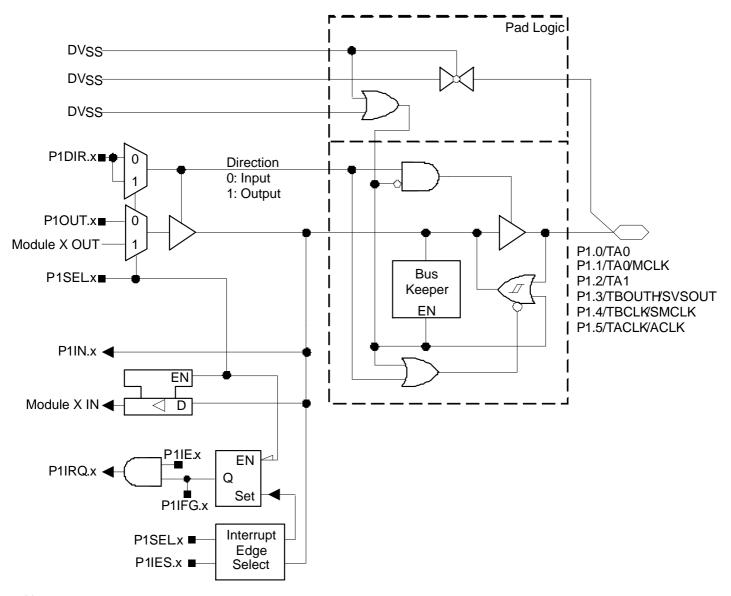
NOTE 1: Once the fuse is blown, no further access to the MSP430 JTAG/Test and emulation features is possible. The JTAG block is switched to bypass mode.



#### **APPLICATION INFORMATION**

## input/output schematics

Port P1, P1.0 to P1.5, input/output with Schmitt trigger



Note: x = 0,1,2,3,4,5



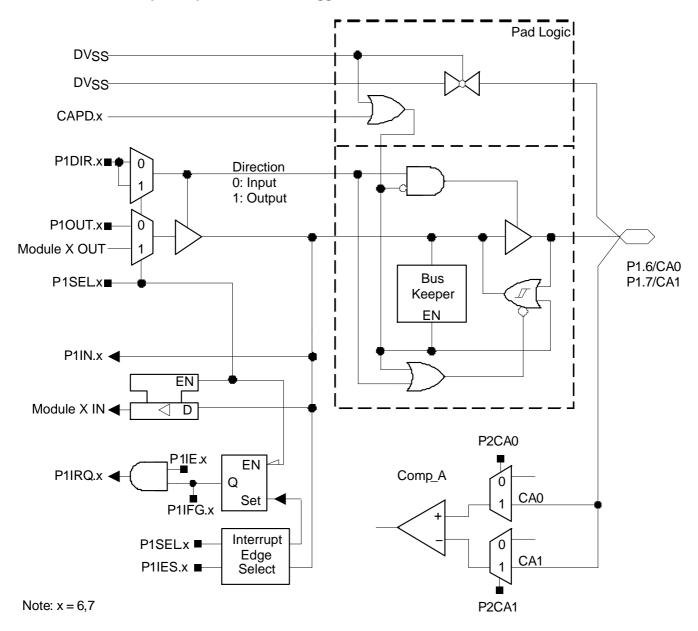
# MSP430xG461x MIXED SIGNAL MICROCONTROLLER

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# Port P1 (P1.0 to P1.5) pin functions

DIN NAME (D4 V)			CONTROL BIT	TS / SIGNALS
PIN NAME (P1.X)	X	FUNCTION	P1DIR.x	P1SEL.x
P1.0/TA0	0	P1.0 (I/O)	I: 0; O: 1	0
		Timer_A3.CCI0A	0	1
		Timer_A3.TA0	1	1
P1.1/TA0/MCLK	1	P1.1 (I/O)	I: 0; O: 1	0
		Timer_A3.CCI0B	0	1
		MCLK	1	1
P1.2/TA1	2	P1.2 (I/O)	I: 0; O: 1	0
		Timer_A3.CCI1A	0	1
		Timer_A3.TA1	1	1
P1.3/TBOUTH/SVSOUT	3	P1.3 (I/O)	I: 0; O: 1	0
		Timer_B7.TBOUTH	0	1
		SVSOUT	1	1
P1.4/TBCLK/SMCLK	4	P1.4 (I/O)	I: 0; O: 1	0
		Timer_B7.TBCLK	0	1
		SMCLK	1	1
P1.5/TACLK/ACLK	5	P1.5 (I/O)	I: 0; O: 1	0
		Timer_A3.TACLK	0	1
		ACLK	1	1

Port P1, P1.6, P1.7, input/output with Schmitt trigger



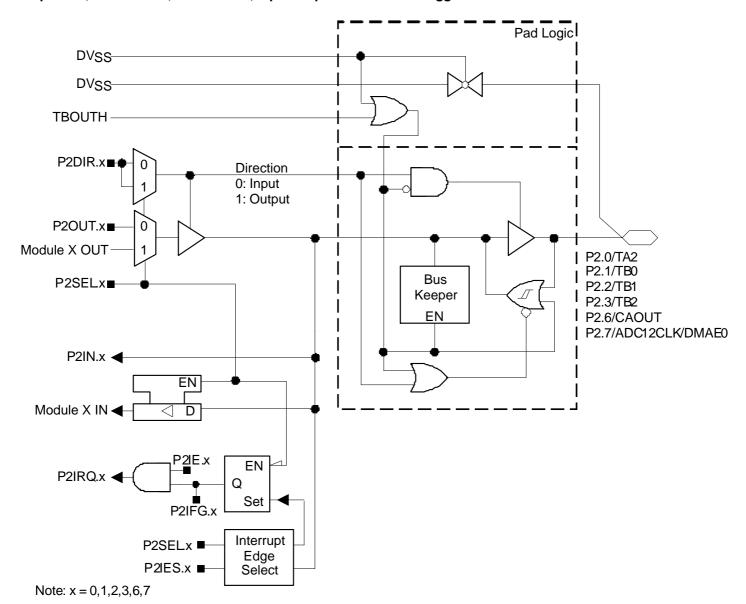
Port P1 (P1.6 and P1.7) pin functions

DINI NAME (D4 V)	x	FUNCTION	CONTROL BITS / SIGNALS				
PIN NAME (P1.X)			CAPD.x	P1DIR.x	P1SEL.x		
P1.6/CA0	6	P1.6 (I/O)	0	I: 0; O: 1	0		
		CA0	1	Х	Х		
P1.7/CA1	7	P1.7 (I/O)	0	I: 0; O: 1	0		
		CA1	1	Х	Х		

NOTE 1: X: Don't care



## port P2, P2.0 to P2.3, P2.6 to P2.7, input/output with Schmitt trigger



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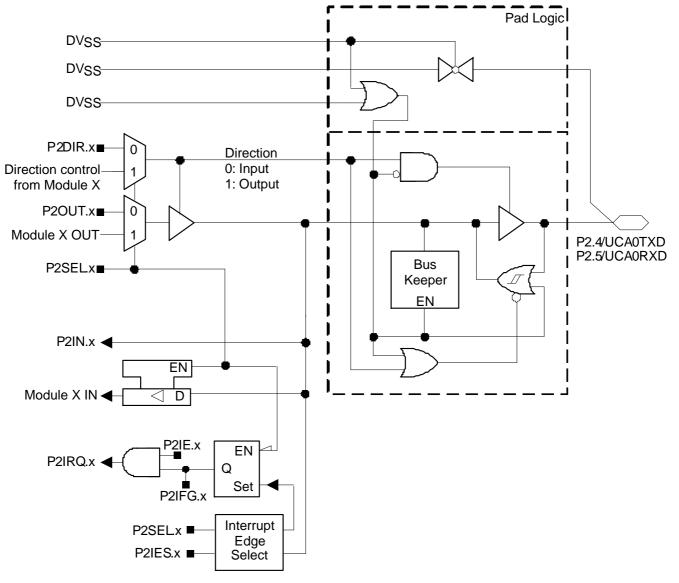
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# Port P2 (P2.0, P2.1, P2.2, P2.3, P2.6 and P2.7) pin functions

DINI NIAME (DO V)	,,	FUNCTION	CONTROL BIT	rs / Signals
PIN NAME (P2.X)	Х	FUNCTION	P2DIR.x	P2SEL.x
P2.0/TA2	0	P2.0 (I/O)	I: 0; O: 1	0
		Timer_A3.CCI2A	0	1
		Timer_A3.TA2	1	1
P2.1/TB0	1	P2.1 (I/O)	I: 0; O: 1	0
		Timer_B7.CCI0A and Timer_B7.CCI0B	0	1
		Timer_B7.TB0 (see Note 1)	1	1
P2.2/TB1	2	P2.2 (I/O)	I: 0; O: 1	0
		Timer_B7.CCI1A and Timer_B7.CCI1B	0	1
		Timer_B7.TB1 (see Note 1)	1	1
P2.3/TB3	3	P2.3 (I/O)	I: 0; O: 1	0
		Timer_B7.CCI2A and Timer_B7.CCI2B	0	1
		Timer_B7.TB3 (see Note 1)	1	1
P2.6/CAOUT	6	P2.6 (I/O)	I: 0; O: 1	0
		CAOUT	1	1
P2.7/ADC12CLK/DMAE0	7	P2.7 (I/O)	I: 0; O: 1	0
		ADC12CLK	1	1
		DMAE0	0	1

NOTE 1: Setting TBOUTH causes all Timer\_B outputs to be set to high impedance.

## port P2, P2.4 to P2.5, input/output with Schmitt trigger



Note: x = 4.5

## Port P2 (P2.4 and P2.5) pin functions

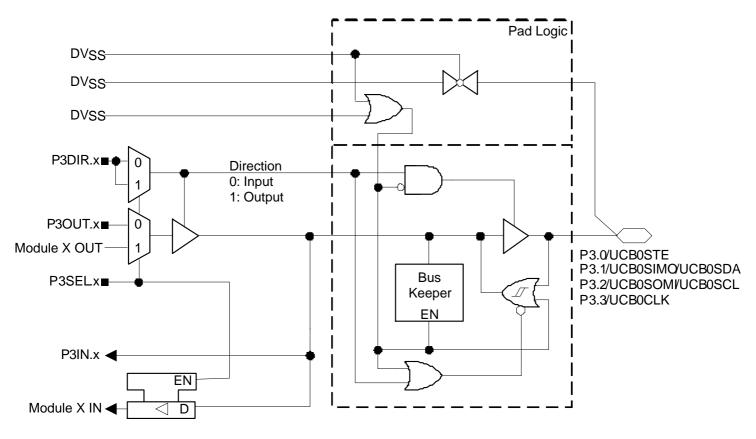
PIN NAME (P2.X)	x	FUNCTION	CONTROL BITS / SIGNALS		
PIN NAME (P2.X)		FUNCTION	P2DIR.x	P2SEL.x	
P2.4/UCA0TXD	4	P2.4 (I/O)	I: 0; O: 1	0	
		USCI_A0.UCA0TXD (see Note 1, 2)	Х	1	
P2.5/UCA0RXD	5	P2.5 (I/O)	I: 0; O: 1	0	
		USCI_A0.UCA0RXD (see Note 1, 2)	Х	1	

NOTES: 1. X: Don't care

2. When in USCI mode, P2.4 is set to output, P2.5 is set to input.



#### port P3, P3.0 to P3.3, input/output with Schmitt trigger



Note: x = 0,1,2,3

## Port P3 (P3.0 to P3.3) pin functions

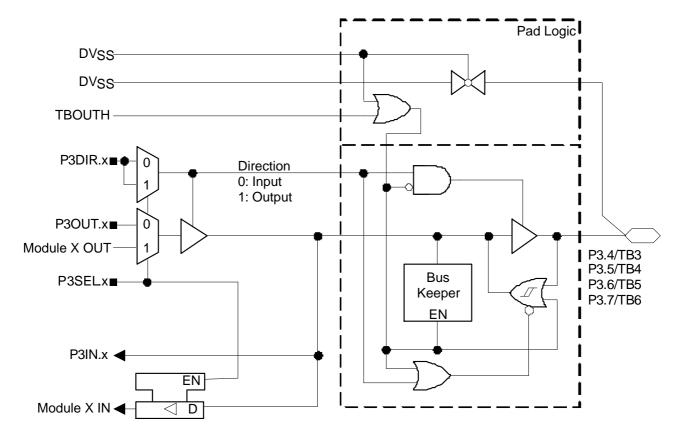
PIN NAME (P3.X)		FUNCTION	CONTROL BIT	S / SIGNALS
PIN NAME (P3.X)	X		P3DIR.x	P3SEL.x
P3.0/UCB0STE	0	P3.0 (I/O)	I: 0; O: 1	0
		UCB0STE (see Notes 1, 2)	Х	1
P3.1/UCB0SIMO/	1	P3.1 (I/O)	I: 0; O: 1	0
UCB0SDA		UCB0SIMO/UCB0SDA (see Notes 1, 2, 3)	Х	1
P3.2/UCB0SOMI/	2	P3.2 (I/O)	I: 0; O: 1	0
UCB0SCL		UCB0SOMI/UCB0SCL (see Notes 1, 2, 3)	Х	1
P3.3/UCB0CLK	3	P3.3 (I/O)	I: 0; O: 1	0
		UCB0CLK (see Notes 1, 2)	Х	1

NOTES: 1. X: Don't care

- 2. The pin direction is controlled by the USCI module.
- 3. In case the I2C functionality is selected the output drives only the logical 0 to  $V_{\mbox{\footnotesize SS}}$  level.



## port P3, P3.4 to P3.7, input/output with Schmitt trigger



Note: x = 4,5,6,7

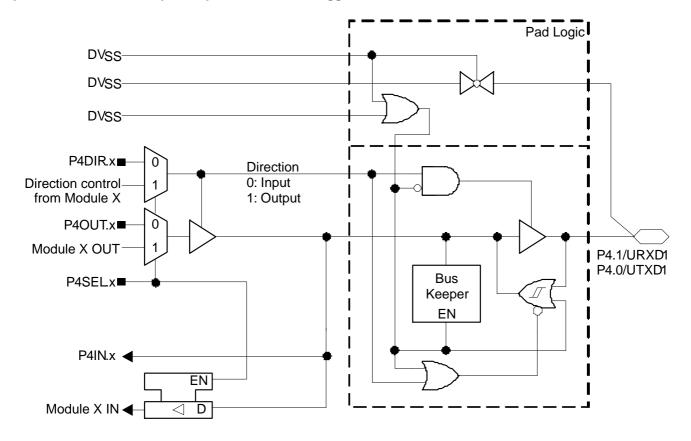
## Port P3 (P3.4 to P3.7) pin functions

PIN NAME (P3.X)	х	FUNCTION	CONTRO	CONTROL BITS / SIGNALS	
			P3DIR.)	P3SEL.x	
P3.4/TB3	4	P3.4 (I/O)	I: 0; O:	1 0	
		Timer_B7.CCl3A and Timer_B7.CCl3B	0	1	
		Timer_B7.TB3 (see Note 1)	1	1	
P3.5/TB4	5	P3.5 (I/O)	I: 0; O:	1 0	
		Timer_B7.CCl4A and Timer_B7.CCl4B	0	1	
		Timer_B7.TB4 (see Note 1)	1	1	
P3.6/TB5	6	P3.6 (I/O)	I: 0; O:	1 0	
		Timer_B7.CCl5A and Timer_B7.CCl5B	0	1	
		Timer_B7.TB5 (see Note 1)	1	1	
P3.7/TB6	7	P3.7 (I/O)	I: 0; O:	1 0	
		Timer_B7.CCl6A and Timer_B7.CCl6B	0	1	
		Timer_B7.TB6 (see Note 1)	1	1	

NOTE 1: Setting TBOUTH causes all Timer\_B outputs to be set to high impedance.



## port P4, P4.0 to P4.1, input/output with Schmitt trigger



Note: x = 0,1

# Port P4 (P4.0 to P4.1) pin functions

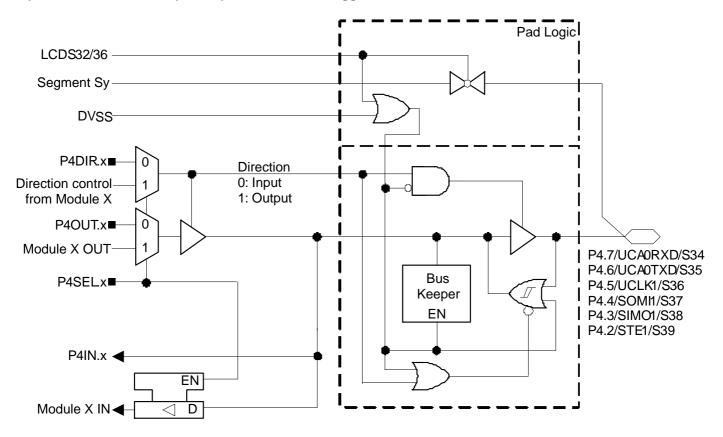
PIN NAME (P4.X)	x	FUNCTION	CONTROL BITS / SIGNALS	
			P4DIR.x	P4SEL.x
P4.0/UTXD1	0	P4.0 (I/O)	I: 0; O: 1	0
		USART1.UTXD1 (see Notes 1, 2)	Х	1
P4.1/URXD1	1	P4.1 (I/O)	I: 0; O: 1	0
		USART1.URXD1 (see Notes 1, 2)	Х	1

NOTES: 1. X: Don't care

2. When in USART1 mode, P4.0 is set to output, P4.1 is set to input.



#### port P4, P4.2 to P4.7, input/output with Schmitt trigger



Note: x = 2,3,4,5,6,7

y = 34,35,36,37,38,39

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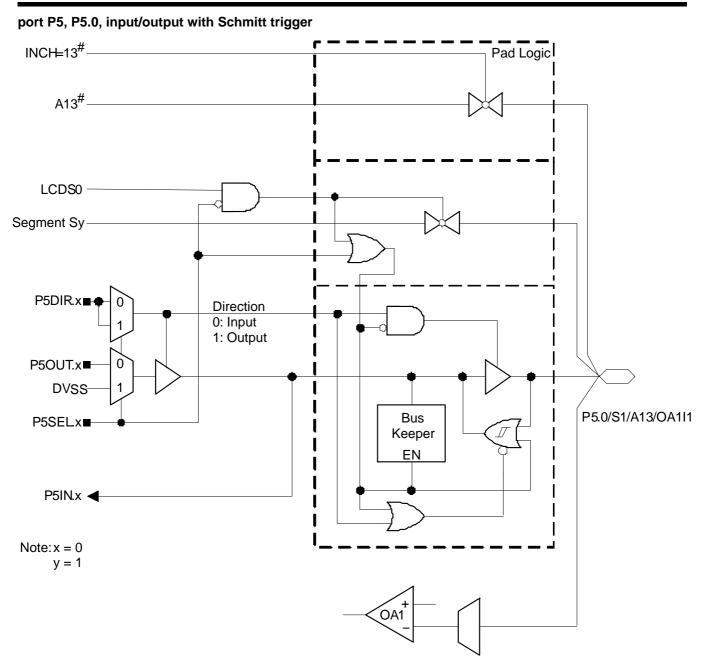
#### Port P4 (P4.2 to P4.5) pin functions

DIN NAME (DA V)		FUNCTION	CONT	ROL BITS / SIG	NALS
PIN NAME (P4.X)	X	FUNCTION	P4DIR.x	P4SEL.x	LCDS36
P4.2/STE1/S39	2	P4.2 (I/O)	l: 0; O: 1	0	0
		USART1.STE1	Х	1	0
		S39 (see Note 1)	Х	Х	1
P4.3/SIMO/S38	3	P4.3 (I/O)	l: 0; O: 1	0	0
		USART1.SIMO1 (see Notes 1, 2)	Х	1	0
		S38 (see Note 1)	Х	Х	1
P4.4/SOMI/S37	4	P4.4 (I/O)	l: 0; O: 1	0	0
		USART1.SOMI1 (see Notes 1, 2)	Х	1	0
		S37 (see Note 1)	Х	Х	1
P4.5/SOMI/S36	5	P4.5 (I/O)	l: 0; O: 1	0	0
		USART1.UCLK1 (see Notes 1, 2)	Х	1	0
		S36 (see Note 1)	Х	Х	1
P4.6/UCA0TXD/S35	6	P4.6 (I/O)	l: 0; O: 1	0	0
		USCI_A0.UCA0TXD (see Notes 1, 3)	Х	1	0
		S35 (see Note 1)	Х	Х	1
P4.7/UCA0RXD/S34	7	P4.7 (I/O)	l: 0; O: 1	0	0
		USCI_A0.UCA0RXD (see Notes 1, 3)	Х	1	0
		S34 (see Note 1)	Х	Х	1

NOTES: 1. X: Don't care

2. The pin direction is controlled by the USART1 module.

3. When in USCI mode, P4.6 is set to output, P4.7 is set to input.



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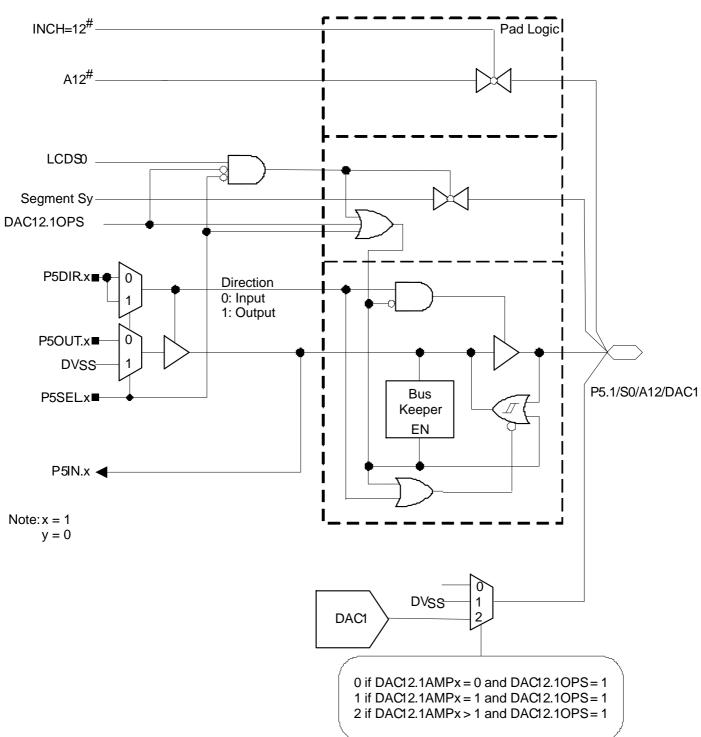
#### Port P5 (P5.0) pin functions

PIN NAME (P5.X)			CONTROL BITS / SIGNALS					
	Х	FUNCTION	P5DIR.x	P5SEL.x	INCHx	OAPx(OA1) OANx(OA1)	LCDS0	
P5.0/S1/A13/OA1I1	0	P5.0 (I/O) (see Note 1)	I: 0; O: 1	0	Х	Х	0	
		OAI11 (see Note 1)	0	Х	X	1	0	
		A13 (see Notes 1, 3)	Х	1	13	Х	Х	
		S1 enabled (see Note 1)	Х	0	X	Х	1	
		S1 disabled (see Note 1)	Х	1	Х	Х	1	

NOTES: 1. X: Don't care

- 2. N/A: Not available or not applicable.
- 3. Setting the P5SEL.x bit disables the output driver as well as the input Schmitt trigger to prevent parasitic cross currents when applying analog signals.

# port P5, P5.1, input/output with Schmitt trigger



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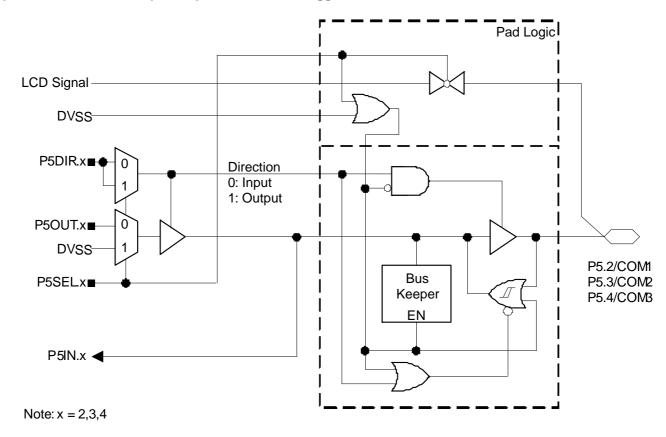
#### Port P5 (P5.1) pin functions

DINI NAME (DE V)		FUNCTION			CONTRO	OL BITS / SIGNA	LS	
PIN NAME (P5.X)	Х	FUNCTION	P5DIR.x	P5SEL.x	INCHx	DAC12.10PS	DAC12.1AMPx	LCDS0
P5.1/S0/A12/DAC1	1	P5.1 (I/O) (see Note 1)	I: 0; O: 1	0	Х	0	Х	0
		DAC1 high impedance (see Note 1)	Х	Х	Х	1	0	Х
		DVSS (see Note 1)	Х	Х	Х	1	1	Х
		DAC1 output (see Note 1)	Х	Х	Х	1	> 1	Х
		A12 (see Notes 1, 2)	Х	1	12	0	Х	0
		S0 enabled (see Note 1)	Х	0	Х	0	Х	1
		S0 disabled (see Note 1)	Х	1	Х	0	Х	1

NOTES: 1. X: Don't care

2. Setting the P5SEL.x bit disables the output driver as well as the input Schmitt trigger to prevent parasitic cross currents when applying analog signals.

#### port P5, P5.2 to P5.4, input/output with Schmitt trigger

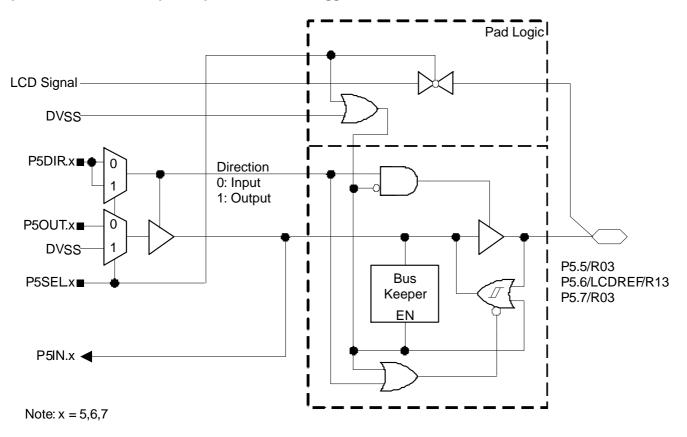


#### Port P5 (P5.2 to P5.4) pin functions

PIN NAME (P5.X)		FUNCTION -	CONTROL BITS / SIGNALS		
PIN NAME (PS.X)	X		P5DIR.x	P5SEL.x	
P5.2/COM1	2	P5.2 (I/O)	I: 0; O: 1	0	
		COM1 (see Note 1)	Х	1	
P5.3/COM2	3	P5.3 (I/O)	I: 0; O: 1	0	
		COM2 (see Note 1)	Х	1	
P5.4/COM3	4	P5.4 (I/O)	I: 0; O: 1	0	
		COM3 (see Note 1)	Х	1	

NOTE 1: X: Don't care

#### port P5, P5.5 to P5.7, input/output with Schmitt trigger



#### Port P5 (P5.5 to P5.7) pin functions

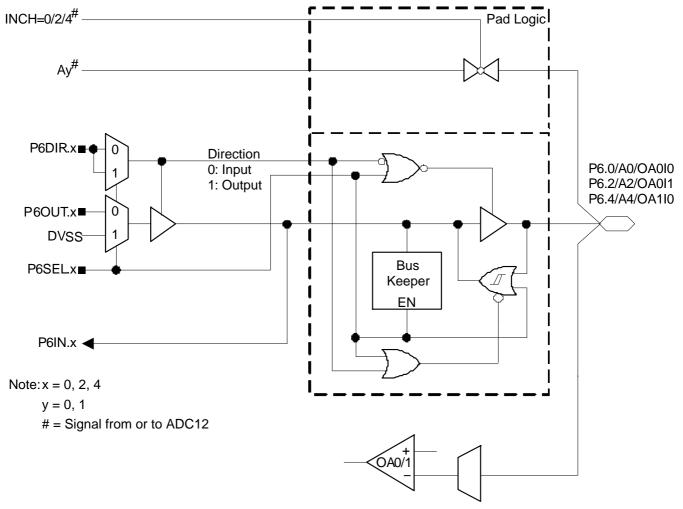
PIN NAME (P5.X)	V	FUNCTION	CONTROL BITS / SIGNALS		
PIN NAME (PS.A)	Х	FUNCTION	P5DIR.x	P5SEL.x	
P5.5/R03	5	P5.5 (I/O)	I: 0; O: 1	0	
		R03 (see Note 1)	Х	1	
P5.6/LCDREF/R13	6	P5.6 (I/O)	I: 0; O: 1	0	
		R13 or LCDREF (see Notes 1, 2)	Х	1	
P5.7/R03	7	P5.7 (I/O)	I: 0; O: 1	0	
		R03 (see Note 1)	X	1	

NOTES: 1. X: Don't care

2. External reference for the LCD\_A charge pump is applied when VLCDREFx = 01. Otherwise R13 is selected.



#### port P6, P6.0, P6.2, and P6.4, input/output with Schmitt trigger



#### Port P6 (P6.0, P6.2, and P6.4) pin functions

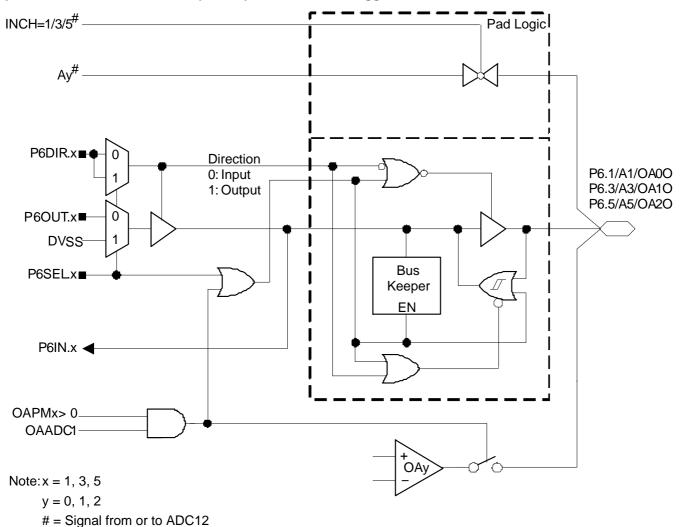
				CONTROL BITS / SIGNALS				
PIN NAME (P6.X)	X	FUNCTION	P6DIR.x	P6SEL.x	OAPx (OA0) OANx (OA0)	OAPx (OA1) OANx(OA1)	INCHx	
P6.0/A0/OA0I0	0	P6.0 (I/O) (see Note 1)	I: 0; O: 1	0	Х	Х	Х	
		OA0I0 (see Note 1)	0	Х	0	Х	Х	
		A0 (see Notes 1, 3)	Х	1	Х	Х	0	
P6.2/A2/OA0I1	2	P6.2 (I/O) (see Note 1)	I: 0; O: 1	0	Х	Х	Х	
		OA0I1 (see Note 1)	0	Х	1	Х	Х	
		A2 (see Notes 1, 3)	Х	1	Х	Х	2	
P6.4/A4/OA1I0	4	P6.4 (I/O) (see Note 1)	I: 0; O: 1	0	Х	Х	Х	
		OA1I0 (see Note 1)	0	Х	Х	0	Х	
		A4 (see Notes 1, 3)	Х	1	Х	Х	4	

NOTES: 1. X: Don't care

- 2. N/A: Not available or not applicable.
- 3. Setting the P6SEL.x bit disables the output driver as well as the input Schmitt trigger to prevent parasitic cross currents when applying analog signals.



#### port P6, P6.1, P6.3, and P6.5 input/output with Schmitt trigger





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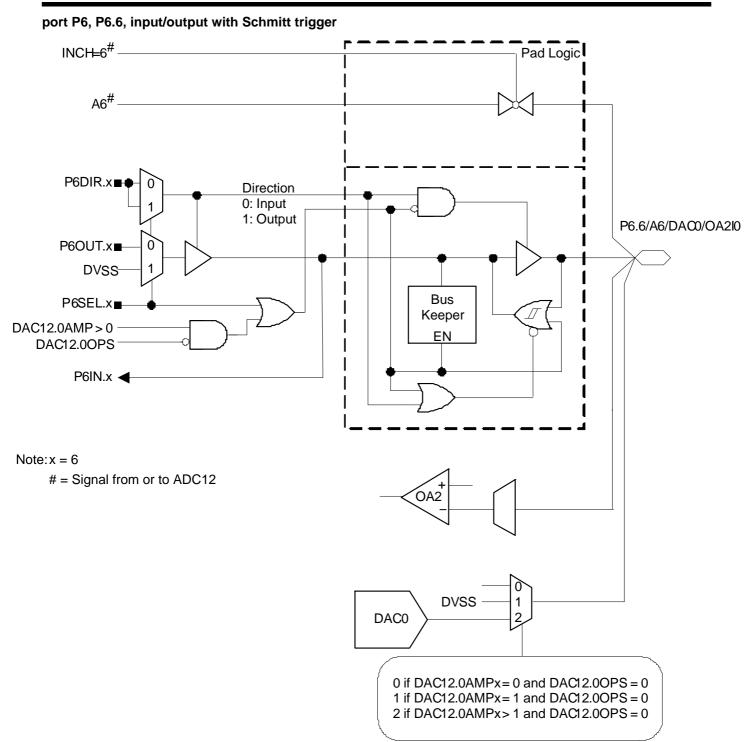
#### Port P6 (P6.1, P6.3, and P6.5) pin functions

PIN NAME (P6.X)	_	FUNCTION		CONT	ROL BITS / SIG	NALS	
FIN NAME (FO.A)	X	FUNCTION	P6DIR.x	P6SEL.x	OAADC1	OAPMx	INCHx
P6.1/A1/OA0O	1	P6.1 (I/O) (see Note 1)	I: 0; O: 1	0	Х	0	Х
		OA0O (see Notes 1, 4)	Х	Х	1	> 0	Х
		A1 (see Notes 1, 3)	Х	1	Х	0	1
P6.3/A3/OA1O	3	P6.3 (I/O) (see Note 1)	I: 0; O: 1	0	Х	0	Х
		OA1O (see Notes 1, 4)	Х	Х	1	> 0	Х
		A3 (see Notes 1, 3)	Х	1	Х	0	3
P6.5/A5/OA2O	5	P6.5 (I/O) (see Note 1)	I: 0; O: 1	0	Х	0	Х
		OA2O (see Notes 1, 4)	Х	Х	1	> 0	Х
		A5 (see Notes 1, 3)	Х	1	Х	0	5

NOTES: 1. X: Don't care

- 2. N/A: Not available or not applicable.
- 3. Setting the P6SEL.x bit disables the output driver as well as the input Schmitt trigger to prevent parasitic cross currents when applying analog signals.
- 4. Setting the OAADC1 bit or setting OAFCx = 00 will cause the operational amplifier to be present at the pin as well as internally connected to the corresponding ADC12 input.

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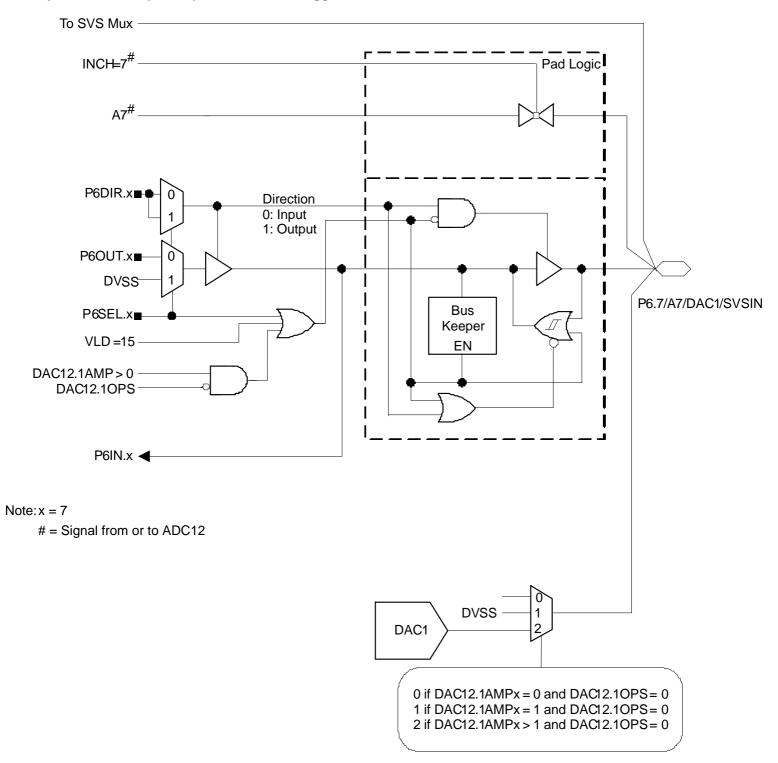
# Port P6 (P6.6) pin functions

		FUNCTION		CONTROL BITS / SIGNALS							
PIN NAME (P6.X)	Х		P6DIR.x	P6SEL.x	INCHx	DAC12.0OPS	DAC12.0AMPx	OAPx (OA2) OANx (OA2)			
P6.6/A6/DAC0/OA2I0	6	P6.6 (I/O) (see Note 1)	I: 0; O: 1	0	Х	1	Х	X			
		DAC0 high impedance (see Note 1)	Х	Х	Х	0	0	×			
					DVSS (see Note 1)	Х	Х	Х	0	1	X
		DAC0 output (see Note 1)	Х	Х	Х	0	>1	×			
		A6 (see Notes 1, 2)	Х	1	6	Х	Х	Х			
		OA2I0 (see Note 1)	0	Х	0	Х	Х	0			

NOTES: 1. X: Don't care

2. Setting the P6SEL.x bit disables the output driver as well as the input Schmitt trigger to prevent parasitic cross currents when applying analog signals.

#### port P6, P6.7, input/output with Schmitt trigger





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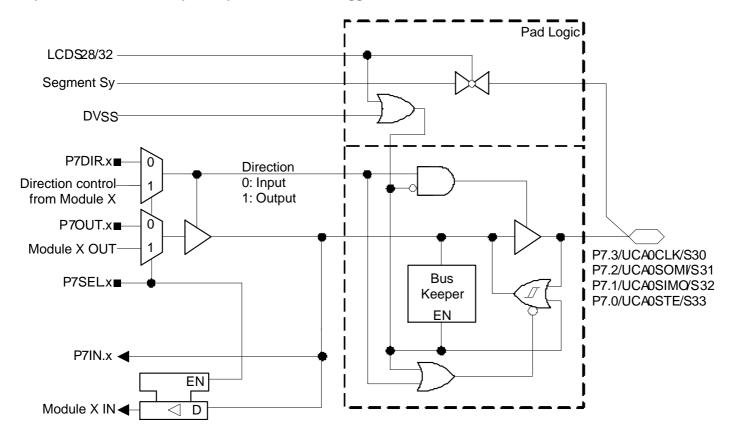
#### Port P6 (P6.7) pin functions

PIN NAME (P6.X)	V	FUNCTION		CONT	ROL BITS / S	IGNALS	
THE NAME (1 O.X)	Х		P6DIR.x	P6SEL.x	INCHx	DAC12.10PS	DAC12.1AMPx
P6.7/A7/DAC1/SVSIN	7	P6.7 (I/O) (see Note 1)	I: 0; O: 1	0	Х	1	X
		DAC1 high impedance (see Note 1)	Х	Х	Х	0	0
		DVSS (see Note 1)	Х	Х	Х	0	1
		DAC1 output (see Note 1)	Х	Х	Х	0	> 1
		A7 (see Notes 1, 2)	Х	1	7	Х	Х
		SVSIN (see Notes 1,3)	0	1	0	1	X

NOTES: 1. X: Don't care

- 2. Setting the P6SEL.x bit disables the output driver as well as the input Schmitt trigger to prevent parasitic cross currents when applying analog signals.
- 3. Setting VLDx = 15 will also cause the external SVSIN to be used. In this case, the P6SEL.x bit is a do not care.

#### port P7, P7.0 to P7.3, input/output with Schmitt trigger



Note: x = 0, 1, 2, 3y = 30, 31, 32, 33



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#### Port P7 (P7.0 to P7.1) pin functions

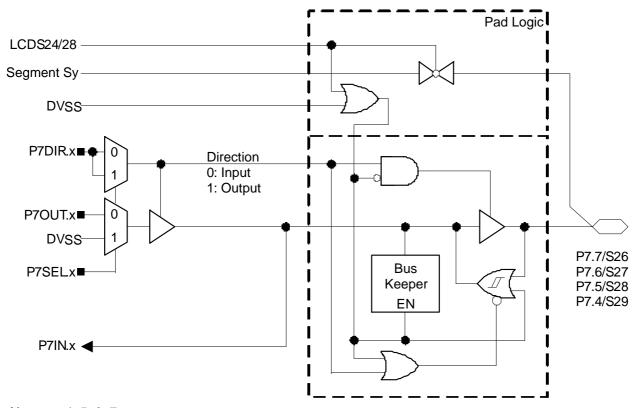
DIN NAME (D7 V)	\ ,	FUNCTION	CONT	ROL BITS / SIG	NALS
PIN NAME (P7.X)	Х	FUNCTION	P7DIR.x	P7SEL.x	LCDS32
P7.0/UCA0STE/S33	0	P7.0 (I/O)	I: 0; O: 1	0	0
		USCI_A0.UCA0STE (see Notes 1, 2)	Х	1	0
		S33 (see Note 1)	Х	Х	1
P7.1/UCA0SIMO/S32	1	P7.1 (I/O)	I: 0; O: 1	0	0
		USCI_A0.UCA0SIMO (see Notes 1, 2)	Х	1	0
		S32 (see Note 1)	Х	Х	1
P7.2/UCA0SOMI/S31	2	P7.2 (I/O)	I: 0; O: 1	0	0
		USCI_A0.UCA0SOMI (see Notes 1, 3)	Х	1	0
		S31 (see Note 1)	Х	Х	1
P7.3/UCA0CLK/S30	3	P7.3 (I/O)	I: 0; O: 1	0	0
		USCI_A0.UCA0CLK (see Notes 1, 3)	X	1	0
		S30 (see Note 1)	Х	Х	1

NOTES: 1. X: Don't care

2. The pin direction is controlled by the USCI module.

3. The pin direction is controlled by the USCI module.

#### port P7, P7.4 to P7.7, input/output with Schmitt trigger



Note: x = 4, 5, 6, 7y = 26, 27, 28, 29

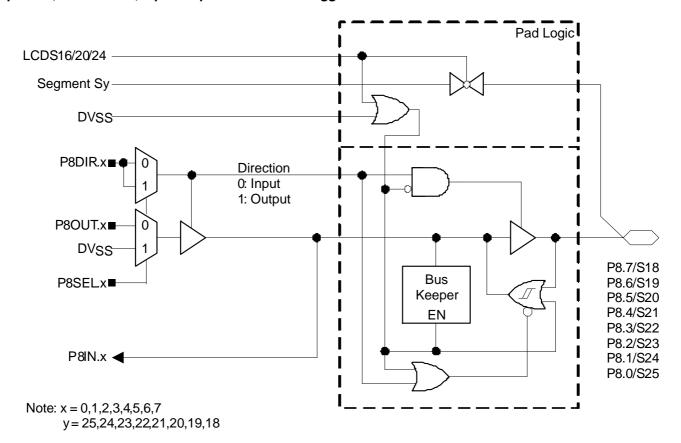
#### Port P7 (P7.4 to P7.5) pin functions

PIN NAME (P7.X)	\ ,	FUNCTION	CONT	CONTROL BITS / SIGNALS			
FIN NAME (F7.A)	X		P7DIR.x	P7SEL.x	LCDS28		
P7.4/S29	4	P7.4 (I/O)	I: 0; O: 1	0	0		
		S29 (see Note 1)	X	Х	1		
P7.5/S28	5	P7.5 (I/O)	I: 0; O: 1	0	0		
		S28 (see Note 1)	X	Х	1		
P7.6/S27	6	P7.6 (I/O)	I: 0; O: 1	0	0		
		S27 (see Note 1)	X	Х	1		
P7.7/S26	7	P7.7 (I/O)	I: 0; O: 1	0	0		
		S26 (see Note 1)	X	Χ	1		

NOTE 1: X: Don't care



#### port P8, P8.0 to P8.7, input/output with Schmitt trigger



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# Port P8 (P8.0 to P8.1) pin functions

DIN NAME (DO V)		FINATION	CONT	ROL BITS / SIG	NALS
PIN NAME (P8.X)	X	FUNCTION	P8DIR.x	P8SEL.x	LCDS16
P8.0/S18	0	P8.0 (I/O)	I: 0; O: 1	0	0
		S18 (see Note 1)	Х	Х	1
P8.1/S19 0	0	P8.0 (I/O)	I: 0; O: 1	0	0
		S19 (see Note 1)	X	Х	1
P8.2/S20	2	P8.2 (I/O)	I: 0; O: 1	0	0
		S20 (see Note 1)	Х	Х	1
P8.3/S21	3	P8.3 (I/O)	I: 0; O: 1	0	0
		S21 (see Note 1)	Х	Х	1
P8.4/S22	4	P8.4 (I/O)	I: 0; O: 1	0	0
		S22 (see Note 1)	X	Х	1
P8.5/S23	5	P8.5 (I/O)	I: 0; O: 1	0	0
		S23 (see Note 1)	Х	Х	1

NOTE 1: X: Don't care

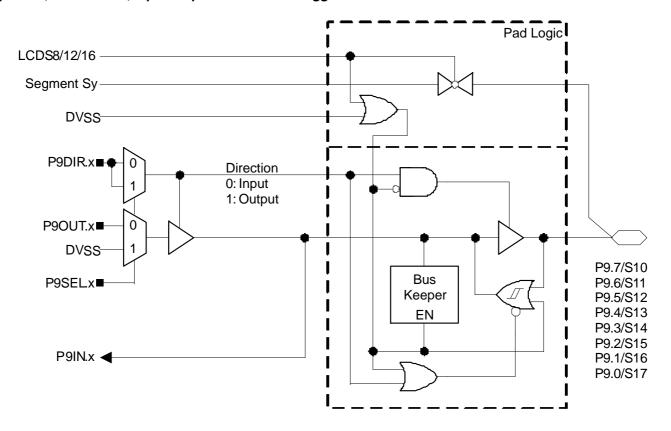
# Port P8 (P8.6 to P8.7) pin functions

PIN NAME (P8.X)		FUNCTION	CONTROL BITS / SIGNALS						
PIN NAIVIE (PO.A)	Х	FUNCTION	P8DIR.x	P8SEL.x	LCDS24				
P8.6/S24	6	P8.6 (I/O)	I: 0; O: 1	0	0				
		S24 (see Note 1)	Х	Х	1				
P8.7/S25	7	P8.7 (I/O)	I: 0; O: 1	0	0				
		S25 (see Note 1)	Х	Х	1				

NOTE 1: X: Don't care



#### port P9, P9.0 to P9.7, input/output with Schmitt trigger



Note: x = 0,1,2,3,4,5,6,7y = 17,16,15,14,13,12,11,10

# MSP430xG461x MIXED SIGNAL MICROCONTROLLER

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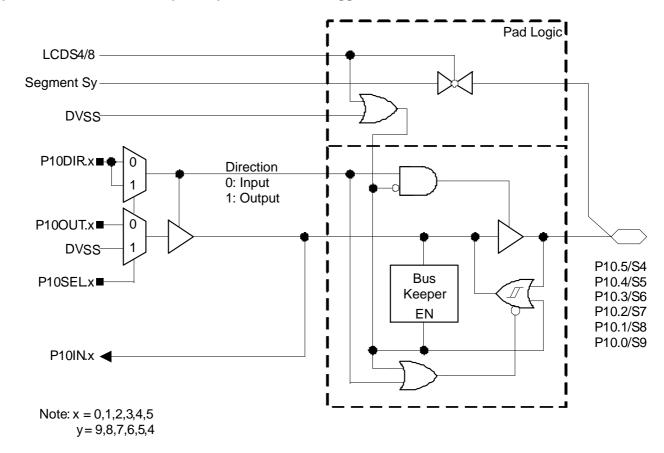
# Port P9 (P9.0 to P9.1) pin functions

DIN NAME (DO V)	\ ,	FINATION	CONT	ROL BITS / SIG	NALS
PIN NAME (P9.X)	X	FUNCTION	P9DIR.x	P9SEL.x	LCDS16
P9.0/S17	0	P9.0 (I/O)	I: 0; O: 1	0	0
		S17 (see Note 1)	Х	Х	1
P9.1/S16	1	P9.1 (I/O)	I: 0; O: 1	0	0
		S16 (see Note 1)	Х	Х	1
P9.2/S20	2	P9.2 (I/O)	I: 0; O: 1	0	0
		S15 (see Note 1)	Х	Х	1
P9.3/S21	3	P9.3 (I/O)	I: 0; O: 1	0	0
		S14 (see Note 1)	Х	Х	1
P9.4/S22	4	P9.4 (I/O)	I: 0; O: 1	0	0
		S13 (see Note 1)	Х	Х	1
P9.5/S23	5	P9.5 (I/O)	I: 0; O: 1	0	0
		S12 (see Note 1)	Х	Х	1
P9.6/S24	6	P9.6 (I/O)	I: 0; O: 1	0	0
		S11 (see Note 1)	Х	Х	1
P9.7/S25	7	P9.7 (I/O)	I: 0; O: 1	0	0
		S10 (see Note 1)	Х	Х	1

NOTE 1: X: Don't care



#### port P10, P10.0 to P10.5, input/output with Schmitt trigger



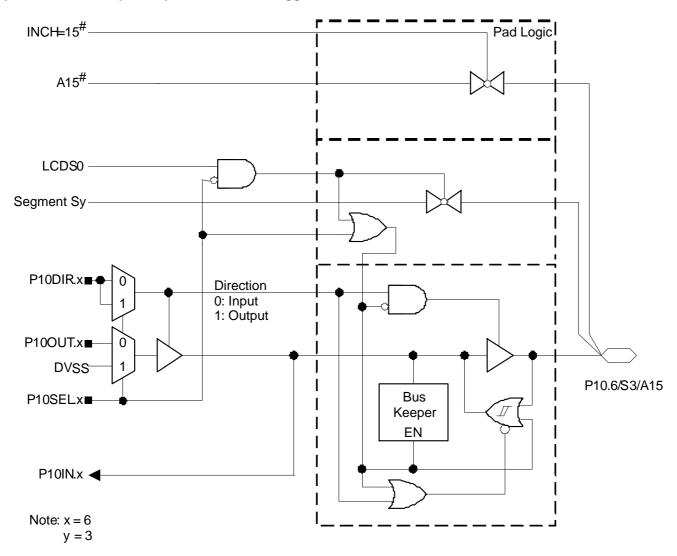
#### Port P10 (P10.0 to P10.1) pin functions

DINI NAME (D40 V)		TUNCTION.	CONT	ROL BITS / SIGI	NALS
PIN NAME (P10.X)	X	FUNCTION	P10DIR.x	P10SEL.x	LCDS8
P10.0/S8	0	P10.0 (I/O)	l: 0; O: 1	0	0
		S8 (see Note 1)	Х	Х	1
P10.1/S7	1	P10.1 (I/O)	l: 0; O: 1	0	0
		S7 (see Note 1)	Х	Х	1
P10.2/S7	2	P10.2 (I/O)	I: 0; O: 1	0	0
		S7 (see Note 1)	X	Х	1
P10.3/S6	3	P10.3 (I/O)	l: 0; O: 1	0	0
		S6 (see Note 1)	X	Х	1
P10.4/S5	4	P10.4 (I/O)	l: 0; O: 1	0	0
		S5 (see Note 1)	Х	Х	1
P10.5/S4	5	P10.5 (I/O)	l: 0; O: 1	0	0
		S4 (see Note 1)	Х	X	1

NOTE 1: X: Don't care



#### port P10, P10.6, input/output with Schmitt trigger



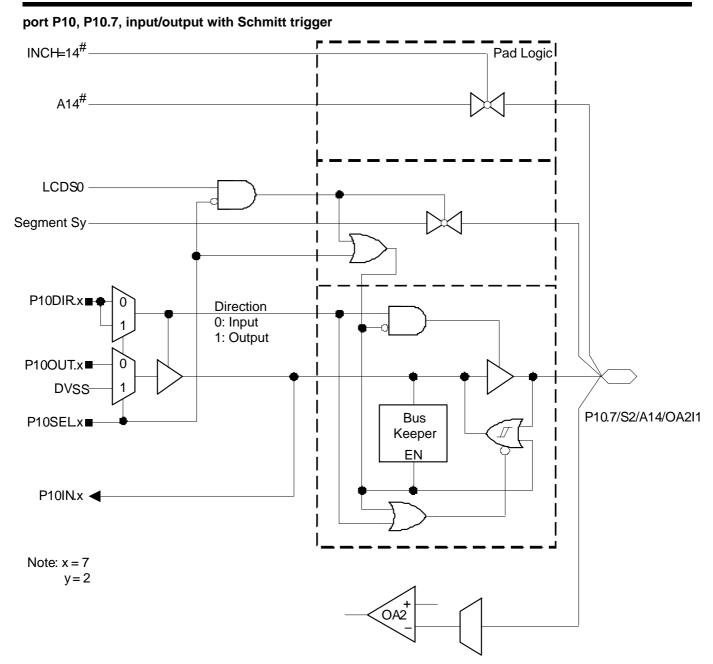
#### Port P10 (P10.6) pin functions

PIN NAME (P10.X)		FUNCTION	CONTROL BITS / SIGNALS							
PIN NAME (P10.A)	Х	FUNCTION	P10DIR.x	P10SEL.x	INCHx	LCDS0				
P10.6/S3/A15	6	P5.0 (I/O) (see Note 1)	I: 0; O: 1	0	X	0				
		A15 (see Notes 1, 3)	Х	1	15	0				
		S3 enabled (see Note 1)	Х	0	Х	1				
		S3 disabled (see Note 1)	Х	1	Х	1				

NOTES: 1. X: Don't care

- 2. N/A: Not available or not applicable.
- 3. Setting the P10SEL.x bit disables the output driver as well as the input Schmitt trigger to prevent parasitic cross currents when applying analog signals.





# MSP430xG461x MIXED SIGNAL MICROCONTROLLER

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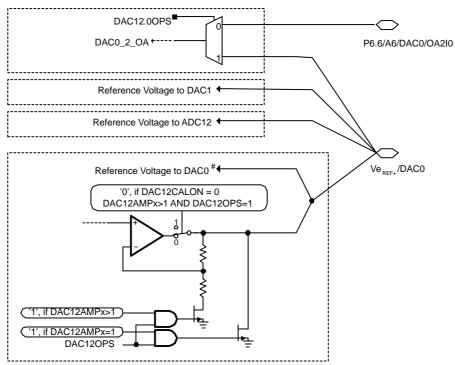
#### Port P10 (P10.7) pin functions

			CONTROL BITS / SIGNALS								
PIN NAME (P10.X)	Х	FUNCTION	P10DIR.x	P10SEL.x	INCHx	OAPx (OA1) OANx (OA1)	LCDS0				
P10.7/S2/A14/OA2I1	7	P10.7 (I/O) (see Note 1)	I: 0; O: 1	0	Х	Х	0				
		A14 (see Notes 1, 3)	Х	1	14	Х	0				
		OA2I1 (see Notes 1, 3)	0	Х	X	1	0				
		S2 enabled (see Note 1)	Х	0	X	Х	1				
		S2 disabled (see Note 1)	Х	1	Х	Х	1				

NOTES: 1. X: Don't care

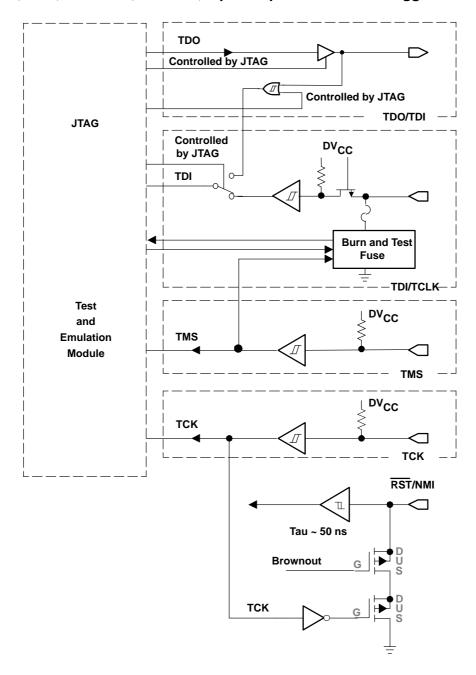
- 2. N/A: Not available or not applicable.
- 3. Setting the P10SEL.x bit disables the output driver as well as the input Schmitt trigger to prevent parasitic cross currents when applying analog signals.

# Ve<sub>REF+</sub>/DAC0



# If the reference of DAC0 is taken from pin Ve<sub>REF+</sub>/DACQ, unpredictable voltage levels will be on pin. In this situation, the DAC0 output is fed back to its own reference input.

#### JTAG pins TMS, TCK, TDI/TCLK, TDO/TDI, input/output with Schmitt trigger or output



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#### JTAG fuse check mode

MSP430 devices that have the fuse on the TDI/TCLK terminal have a fuse check mode that tests the continuity of the fuse the first time the JTAG port is accessed after a power-on reset (POR). When activated, a fuse check current (I<sub>(TF)</sub>) of 1 mA at 3 V can flow from the TDI/TCLK pin to ground if the fuse is not burned. Care must be taken to avoid accidentally activating the fuse check mode and increasing overall system power consumption.

Activation of the fuse check mode occurs with the first negative edge on the TMS pin after power up or if the TMS is being held low during power up. The second positive edge on the TMS pin deactivates the fuse check mode. After deactivation, the fuse check mode remains inactive until another POR occurs. After each POR the fuse check mode has the potential to be activated.

The fuse check current only flows when the fuse check mode is active and the TMS pin is in a low state (see Figure 37). Therefore, the additional current flow can be prevented by holding the TMS pin high (default condition). The JTAG pins are terminated internally and therefore do not require external termination.

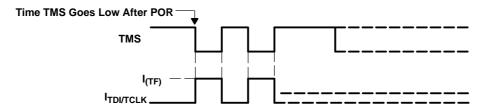


Figure 37. Fuse Check Mode Current

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## **Data Sheet Revision History**

Literature Number	Summary
SLAS508	Preliminary Product Preview datasheet release
SLAS508A	Production Data data sheet release
SLAS508B	Changed power consumption values in features (page 1)
SLAS508C	Changed t <sub>VALID,MO</sub> , t <sub>HD,SI</sub> , and t <sub>VALID,SO</sub> values (page 43)
SLAS508D	Changed I <sub>(AM)</sub> values for CG461x (page 29)
SLAS508E	Added ZQW package information Changed power consumption values for Standby and Off Modes in features (page 1) Corrected description of P7.3/UCA0CLK/S30 terminal (page 7) Clarified test conditions in recommended operating conditions table (page 30) Changed I <sub>(AM)</sub> values for CG461x and all TYP values for I <sub>(LPM3)</sub> in supply current into AV <sub>CC</sub> + DV <sub>CC</sub> table (page 31) Clarified test conditions in DCO table (page 42) Clarified test conditions in USART table (page 48) Clarified test conditions in operational amplifier OA, supply specifications table (page 59) Clarified test conditions in operational amplifier OA, input/output specifications table (page 60)
SLAS508F	Removed preview notice for MSP430CG461x in PZ package.
SLAS508G	Removed preview notice for all devices in ZQW package.
SLAS508H	Added "operational amplifier OA feedback network, noninverting amplifier mode (OAFCx = 4)" table and "operational amplifier OA feedback network, inverting amplifier mode (OAFCx = 6)" table (page 62)
SLAS508I	Changed limits on t <sub>d(SVSon)</sub> parameter (page 40)

NOTE: Page and figure numbers refer to the respective document revision.





1-Mar-2011

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
MSP430FG4616IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	
MSP430FG4616IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	
MSP430FG4616IZQW	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4616IZQWR	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	2500	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4616IZQWT	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4617IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	
MSP430FG4617IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	
MSP430FG4617IZQW	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4617IZQWR	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	2500	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4617IZQWT	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4618IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	
MSP430FG4618IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	
MSP430FG4618IZQW	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	





1-Mar-2011

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
MSP430FG4618IZQWR	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	2500	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4618IZQWT	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4619IPZ	ACTIVE	LQFP	PZ	100	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	
MSP430FG4619IPZR	ACTIVE	LQFP	PZ	100	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	
MSP430FG4619IZQW	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4619IZQWR	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	2500	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	
MSP430FG4619IZQWT	ACTIVE	BGA MICROSTAR JUNIOR	ZQW	113	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



#### **PACKAGE OPTION ADDENDUM**

1-Mar-2011

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# PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION



# TAPE DIMENSIONS KO P1 BO BO Cavity AO

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



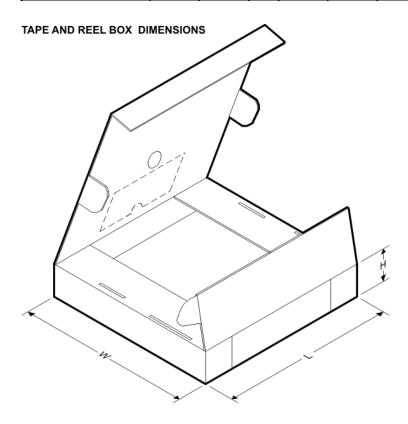
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430FG4616IZQWR	BGA MI CROSTA R JUNI OR	ZQW	113	2500	330.0	16.4	7.3	7.3	1.5	12.0	16.0	Q1
MSP430FG4616IZQWT	BGA MI CROSTA R JUNI OR	ZQW	113	250	330.0	16.4	7.3	7.3	1.5	12.0	16.0	Q1
MSP430FG4617IZQWR	BGA MI CROSTA R JUNI OR	ZQW	113	2500	330.0	16.4	7.3	7.3	1.5	12.0	16.0	Q1
MSP430FG4617IZQWT	BGA MI CROSTA R JUNI OR	ZQW	113	250	330.0	16.4	7.3	7.3	1.5	12.0	16.0	Q1
MSP430FG4618IZQWR	BGA MI CROSTA R JUNI OR	ZQW	113	2500	330.0	16.4	7.3	7.3	1.5	12.0	16.0	Q1
MSP430FG4618IZQWT	BGA MI CROSTA R JUNI	ZQW	113	250	330.0	16.4	7.3	7.3	1.5	12.0	16.0	Q1

# **PACKAGE MATERIALS INFORMATION**

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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	OR											
MSP430FG4619IZQWT	BGA MI CROSTA R JUNI OR	ZQW	113	250	330.0	16.4	7.3	7.3	1.5	12.0	16.0	Q1

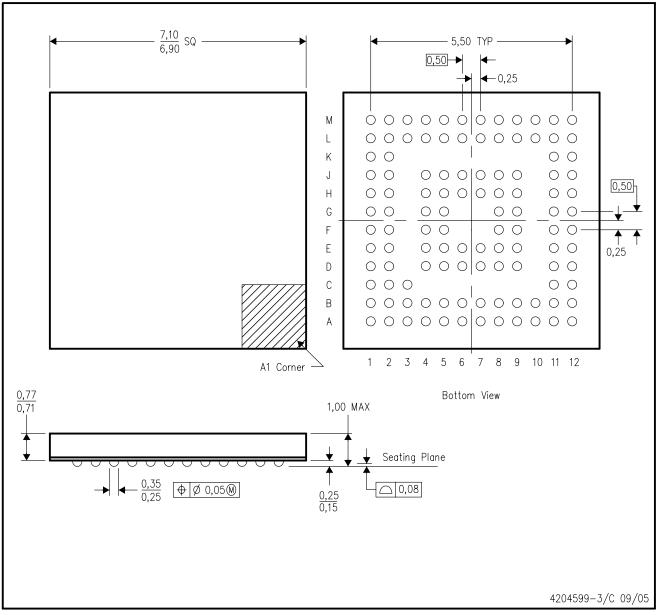


#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MSP430FG4616IZQWR	BGA MICROSTAR JUNIOR	ZQW	113	2500	333.2	345.9	28.6
MSP430FG4616IZQWT	BGA MICROSTAR JUNIOR	ZQW	113	250	333.2	345.9	28.6
MSP430FG4617IZQWR	BGA MICROSTAR JUNIOR	ZQW	113	2500	333.2	345.9	28.6
MSP430FG4617IZQWT	BGA MICROSTAR JUNIOR	ZQW	113	250	333.2	345.9	28.6
MSP430FG4618IZQWR	BGA MICROSTAR JUNIOR	ZQW	113	2500	333.2	345.9	28.6
MSP430FG4618IZQWT	BGA MICROSTAR JUNIOR	ZQW	113	250	333.2	345.9	28.6
MSP430FG4619IZQWT	BGA MICROSTAR JUNIOR	ZQW	113	250	333.2	345.9	28.6

# ZQW (S-PBGA-N113)

## PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225
- D. This is a lead-free solder ball design.



#### PZ (S-PQFP-G100)

#### PLASTIC QUAD FLATPACK

1



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Falls within JEDEC MS-026

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